NATIONAL INSTITUTE OF TECHNOLOGY DURGAPUR

DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

Revised Curriculum and Syllabi

Program Name Master of Technology in MICRO-ELECTRONICS & VLSI Effective from the Academic Year: 2021-2022



Recommended by DAC	: 12.08.2021
Recommended in PGAC	: 16.08.2021
Approved by the Senate	: 22.08.2021

CONTENTS

1. CURRICULUM FOR M. TECH. IN MICROELECTRONICS & VLSI	3
2. LIST OF COMMON POOL ELECTIVES	4 - 5
3. Assessment	6
4. PROGRAM OUTCOMES (POS) AND PROGRAM SPECIFIC OUTCOMES (PSOS)	7
5. DETAILED SYLLABUS	8-105
7A. CORE SUBJECTS	8 -17
7B. CORE LABORATORIES	18-20
7C. COMMON POOL ELECTIVES	21-105

Curriculum for M. Tech. in Microelectronics & VLSI

		SEMESTE	RI				
Sl. No	Code	Subject	L	Т	S	С	Н
1	EC1011	Semiconductor Device & Modeling	3	0	0	3	3
2	EC1012	Analog IC Design	3	1	0	4	4
3	EC1013	Digital IC Design	3	0	0	3	3
4	EC90XX	SPECIALIZATION ELECTIVE - I	3	1	0	4	4
5	EC90XX	SPECIALIZATION ELECTIVE - II	3	1	0	4	4
6	EC1061	Analog IC Design Lab	0	0	4	2	4
7	7 EC1062 Digital IC Design Lab		0	0	4	2	4
		TOTAL	15	3	8	22	26
		SEMESTE	RII				
Sl. No	Code	Subject	L	Т	S	С	Н
1	EC2011	VLSI Technology	3	0	0	3	3
2	EC2012	VLSI System Design	3	1	0	4	4
3	EC90XX	SPECIALIZATION ELECTIVE - III	3	1	0	4	4
4	EC90XX	SPECIALIZATION ELECTIVE - IV	3	1	0	4	4
5	EC90XX	SPECIALIZATION ELECTIVE - V	3	1	0	4	4
6	EC2061	VLSI System Design Lab	0	0	4	2	4
7	EC2062	Term Project/ Lab-Based Project	0	0	6	3	6
		TOTAL	15	4	10	24	29

	SEMESTER III						
Sl. No	No Code Subject		L	Т	S	С	H
1	XX90XX	AUDIT LECTURES / WORKSHOPS	0	0	0	0	2
2	EC3061	Project - I	0	0	24	12	24
3	EC3062	SEMINAR - NON-PROJECT / EVALUATION OF SUMMER TRAINING	0	0	4	2	4
		TOTAL	0	0	28	14	30

	SEMESTER IV						
Sl. No	Code	Subject	L	Т	S	С	Η
1	EC4061	Project - II	0	0	24	12	24
1	EC4062	PROJECT SEMINAR	0	0	4	2	4
		TOTAL	0	0	28	14	28

Note: (i) Project I & II may be done independently or completed in continuation,

(ii) Project I and/or II may be done in collaboration with Industry/other academic/R&D Organization

P a g e 3 | 105

1. List of Common Pool Electives

Sl. No.	SUBJECT CODE	SUBJECT	L-T-S	CREDIT
1.	EC9001	Digital Signal Processing using MATLAB [*]	3-0-2	4
2.	EC9002	Statistical Signal Processing	3-1-0	4
3.	EC9003	Applications of Image Processing using Python*	3-0-2	4
4.	EC9004	Automated Speech Signal Processing	3-1-0	4
5.	EC9005	Probability & Random Process	3-1-0	4
6.	EC9006	Error Correction Coding	3-1-0	4
7.	EC9007	Detection & Estimation Theory	3-1-0	4
8.	EC9008	Optical Communication & Networks	3-1-0	4
9.	EC9009	Cooperative Communication Networks	3-1-0	4
10.	EC9010	Network Information Theory and Coding	3-1-0	4
11.	EC9011	Digital Microwave Communication	3-1-0	4
12.	EC9012	Microwave Photonics	3-1-0	4
13.	EC9013	Radiating Systems for Next Gen Communication	3-1-0	4
14.	EC9014	Microwave and Millimeter-wave Measurements	3-1-0	4
15.	EC9015	Microwave Solid state Devices	3-1-0	4
16.	EC9016	Digital Satellite and Navigational Systems	3-1-0	4
17.	EC9017	Bimolecular Communication	3-1-0	4
18.	EC9018	Queuing Theory for Telecommunication	3-1-0	4
19.	EC9019	Quantum Communication and Computing	3-1-0	4
20.	EC9020	Cloud Computing	3-0-0	3
21.	EC9021	Machine Learning and Deep Learning using Python	3-1-0	4
22.	EC9022	Big Data Computing	3-1-0	4
23.	EC9023	Internet of Things (IoT)	3-1-0	4
24.	EC9024	Virtual Reality and Augmented Reality	3-1-0	4
25.	EC9025	Network Function Virtualization & Software Defined Networks	3-1-0	4
26.	EC9026	Game Theory for Telecom Management	3-1-0	4
27.	EC9027	Multiphysics Analysis and Modeling using COMSOL/ANSYS	3-1-0	4
28.	EC9028	Mixed Signal IC Design	3-1-0	4
29.	EC9029	Architectural Design of ICs	3-1-0	4
30.	EC9030	RF IC Design	3-1-0	4
31.	EC9031	SoC Design	3-1-0	4
32.	EC9032	FPGA based design*	3-0-2	4

Page 4 | 105

Sl. No.	SUBJECT CODE	SUBJECT	L-T-S	CREDIT
33.	EC9033	Embedded Systems	3-1-0	4
34.	EC9034	MEMS & Microsystems Technology	3-1-0	4
35.	EC9035	Nanoelectronics	3-1-0	4
36.	EC9036	ASIC Design using Verilog/VHDL*	3-0-2	4
37.	EC9037	Low Power Circuits and Systems	3-1-0	4
38.	EC9038	Testing and Verification of VLSI Circuits	3-1-0	4
39.	EC9039	Advanced Computer Architecture	3-1-0	4
40.	EC9040	DSP Architectures in VLSI	3-1-0	4
41.	EC9041	Power Management IC Design	3-1-0	4
42.	EC9042	Cyber Physical Electronic System Design	3-1-0	4
43.	EC9043	Smart Material based Devices	3-1-0	4
Note:	Other than the	above-mentioned courses, maximum two courses (one from eacl		0

core and elective offered by other PG programs of the-Institute can be opted as an ELECTIVE subject with the necessary prior approval from the Department.

*The Lecture, Tutorial and Sessional distribution of EC9001, EC9003, EC9032, and EC9036 are 3, 0 and 2, respectively.

2. Assessment:

The assessment method followed from the academic year 2019-2020 is briefly mentioned as follows.

A. Theory Courses (15 + 25 + 60)

In the subjects, total 100 marks consist of the following three components.

(i) Continuous Assessment 1 (CA1): (15 marks)

This is realized with class tests, quizzes, home assignments, surprise tests or a combination of these components. If more than two class tests are conducted, average marks are considered.

(ii) Continuous Assessment 2 (CA2): (25 marks, 2 hours)

Mid-term assessment (CA2) covers half of the syllabus. The exam is conducted at the middle of the semester following the academic calendar. The evaluation is done within a fortnight and the answer scripts are shown to the students so that they can understand their shortcomings in learning the subject.

(iii) End-term Examination: (60 marks, 3 hours)

End-term examination covers the full syllabus. The exam is centrally conducted at the end of the semester. After the evaluation, the answer scripts are shown to the students. Model answers are also provided.

** It is to be mentioned here that in the previous two academic years - 2017-2018 and 2018-2019, the assessment methods and distributions of the three components corresponding to the total 100 marks are as given below.

- a) Continuous Assessment (CA): 20 marks This is based on quizzes, home assignments, class test and surprise tests.
- b) Mid-Semester Assessment (MA): 30 marks A mid-semester examination is conducted tentatively within 7-8 weeks after beginning of teaching in each semester.
- c) End-Semester Examination: 50 marks The examination is conducted at the end of teaching session of the semester.

Based on the feedback taken from the concerned stakeholders of the Institute as well as academic, industry and R&D personnel, PG curriculum has been revised in the academic year 2019-2020.

B. Laboratory Courses (40 + 40 + 20)

For the evaluation of Laboratory Courses, total 100 marks has following three components

- (i) Continuous Assessment (CA): 40 marks The students are evaluated based on their performance on day to day basis in conducting the experiments and obtaining the experimental results in the Laboratory. Attendance, general attentiveness/ sincerity /behavior of student and occasional instant quizzes are considered in this component.
- (ii) **End-Semester Assessment (EA): 40 marks** The end-semester evaluation consists of two subcomponents. 20 marks for the performance of the students in conducting the experiment or program assigned during the end-semester examination and 20marks for viva-voce examination.
- (iii) Laboratory Reports: 20 marks– 20 marks is awarded based on the representation of the experimental results, writing ability of the associated theory, analysis of the obtained results and observation/concluding remarks drawn corresponding to each experiment performed in the laboratory throughout the semester including the end-semester examination.

3. Program Outcomes (POs) and Program Specific Outcomes (PSOs)

A. Program Outcomes (Pos):

NBA has defined the following three POs for the PG programs:

- **PO 1:** An ability to independently carry out research /investigation and development work to solve practical problems.
- PO 2: An ability to write and present a substantial technical report/document.
- **PO 3:** Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

B. Program Specific Outcomes (PSOs):

In addition to the three POs, three program specific outcomes (PSOs) have been defined by the Department as follows -

PSO 1 (PO 4): Identify, formulate and solve engineering problems in the field of Microelectronics and VLSI

PSO 2 (PO 5): Apply knowledge, proper methodology and modern tools to analyze and solve the problems in the domain of Microelectronics and VLSI.

PSO 3 (PO 6): Acquire professional and intellectual integrity and ethics of research and recognize the need to engage in learning with a high level of enthusiasm and commitment to contribute to the community for sustainable development of society

Course Articulation Matrices: Connection between the courses and the POs and PSOs

The correlation levels are 1, 2 or 3, denoting: 1: Slight (Low) 2: Moderate (Medium) 3: Substantial (High).

4. Detailed Syllabus: A. Core Subjects

	Departme	nt of Electronics &	Communic	ation Engine	eering		
a		Program Core		Total conta	ct hours : 42		
Course	Title of the course	(PCR) /	Lecture	Tutorial	Practical	Total	Credit
Code		Electives (PEL)	(L)	(T)	(P)	Hours	
	Semiconductor						
EC1011	Device & Modeling	PCR	3	0	0	3	3
Pre-requis	ites/Co-requisites:		Course A	ssessment m	ethods: (Cont	inuous Ass	essment
[PHC331,]	ECC302]		(CA:15%), Mid-Term	Assessment (MA:25%)	and
			End-Tern	n Assessmen	t (EA:60%)):		
			Continuo	us Assessme	nt (CA): Quiz	zes/Class	
				gnments/Att			
Course	After successful	l completion of the c	ourse, the st	udent will be	able to:		
Outcomes		introduce the physics		ductor mater	rials for under	standing t	he device
	mod	leling of semiconduc	ctor devices.				
	• CO 2: To	understand the transp	port of charg	ge carriers fo	or the operatio	n of semic	conductor
		ices.					
		apply suitable appro		-	s to derive the	e physical	model of
		iconductor devices s	•				
		analyze electrostation			-voltage chara	acteristics	of MOS
 devices under a variety of conditions. CO 5: To evaluate qualitative understanding of the physics of emerging MOS 							
						ig MOS de	vices and
		version of this under	-	-			
	• CO 6: To	develop the fundam	nental under	standing of	device mode	ling and r	numerical
		ulation					
Topics		miconductor Electr					
Covered		Materials, Band Mo					
		Drift Velocity, Mo	bility and S	cattering, Dr	ift & Diffusio	on Current	, Device:
	Hall-Effect.		a	10.11	() IT 0	T 01	
		etal-Semiconductor					T 1
		uctor junctions, Cu Junction, Linearly					
	• 1	ak down mechanism			•	Ceverse-Di	aseu p-n
		eld-Effect Transisto				Model II	0· T -
				215) and its	I ofuel I-v		, 1 -
	r.	, Flat Band Voltage	. Oxide and	Interface (Charge, High a	and Low F	requency
	C-V Characterist	ics, Basic MOSFET	behavior, Tl	nreshold Vol	tage Model, 1	st Order I-	V Model.
		ort Channel Effects					
		echnology nodes and					o scaling
		ects: velocity satura					
	bias effect, thresh	hold adjustment, mol	bility degrad	ation, subthr	eshold current	t, hot carrie	er effects,
	velocity oversho	ot, high field effects	in scaled MC	OSFETs, sub	strate current a	and effects	in scaled
	MOSFETS.						
		onconventional MO			_		
		te, high mobility N	MOSFETS,	SOI, Multi-	gate MOSFE	Ts, FinFE	ET, GAA
	MOSFETs.						
		troduction to BSIM				1 1 1 1 1	
	•	models, BSIM fami	• •				v Model,
	Introduction to the	ne TCAD Simulation	Tool, Exam	ples of TCA	D Simulation	s.	

P a g e 8 | 105

	Total Contact Hours: (L=42, T=0)= 42
Tort Doolra	Text Books:
Text Books,	
and/or	1. Yuan Taur and Tak H. Ning, "Fundamentals of Modern VLSI Devices" 2 nd Edition,
Reference	Cambridge University Press, 2013.
Material	2. Theodore I. Kamins Richard S. Muller, "Device Electronics for Integrated circuits", 3 rd
	Edition Wiley, 2007.
	3. Dragica Vasileska, Stephen M. Goodnick, and Gerhard Klimeck, "Computational
	<i>Electronics: Semiclassical and Quantum Device Modeling and Simulation</i> ", CRC Press,
	2010.
	4. A B. Bhattacharyya, "Compact MOSFET Models for VLSI Design", Wiley-IEEE, 2009.
	Reference Books:
	1. S. M. Sze and Kwok K. Ng., "Physics of Semiconductor Devices", 3rd Edition, John
	Wiley & Sons, 2002.
	2. Robert F. Pierret, "Semiconductor Device Fundamentals", Pearson Education, 2006.
	3. Donald A. Neamen, "Semiconductor Physics and Devices", 3rd Edition, Mc-Graw Hill,
	2003.
	4. Jasprit Singh, "Semiconductor Devices- Basic Principles", John Wiley and Sons Inc.,
	2001.
	2001.

EC1011: Semiconductor Device & Modeling [Mapping between course outcomes (COs) and Program Outcomes (POs)]

CO	Statement	Program Outcomes						
СО	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3	
CO1	To introduce the physics of semiconductor materials for understanding the device modeling of semiconductor devices.	1	1	3	2	1	1	
CO2	To understand the transport of charge carriers for the operation of semiconductor devices.	2	1	3	2	1	1	
CO3	To apply suitable approximations and techniques to derive the physical model of semiconductor devices such as P-N junctions.	2	2	3	2	3	1	
CO4	To analyse electrostatic variables and current- voltage characteristics of MOS devices under a variety of conditions.	2	2	3	3	2	1	
CO5	To evaluate qualitative understanding of the physics of emerging MOS devices and conversion of this understanding into modeling.	2	2	3	3	3	2	
CO6	To develop the fundamental understanding of device modeling and numerical simulation	3	3	3	3	3	2	
	Average	2.00	1.83	3.00	2.50	2.17	1.33	

	· · · · · · · · · · · · · · · · · · ·	-	Electronics & C	Communication]				
Course	Title of	Program Core		Total contac	et hours : 56			
Code	the course	(PCR) / Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit	
EC1012	Analog IC Design	PCR	3	1	0	4	4	
Pre-requisites/Co-requisites:		ites:			Continuous Assess			
[<u>ECC301,</u>	<u>ECC302, ECC</u>	<u> [602/EC1011]</u>			nd End-Term Asse Quizzes/Class tests			
Commo	A ft on au o oo	actul completion of				"11551giintento	, i ittoilidailio	
Course Outcomes		essful completion of Define various para				analog IC desi	σn	
outcomes		Describe the operation				-	5	
	• CO 3:	Solve any given cir		-				
	• CO 4:	Evaluate various pe	erformance metri	ics such as gain/B	W/Power dissipati	on/Input & ou	itput range.	
		Analyze feedback						
		Design a Single sta	• •		er to meet the give	n specification	ns.	
Topics Covered	Module I.	MOS Device Ph nsiderations, Overv			I/V Characteristi	os Short Cha	nnol Effort	
Covered		e Signal MOS Devi		cennology, MOS		cs, Short Cha		
	Basic Conce Amplifier pa Module IV. Simple, Case Module V. Single Ende Differential Module VI. General Con Differential Module VII General Con	Current Mirror code, Wilson and L Differential Amp d and double ender Pair with MOS load Frequency Resp nsiderations, Comr	ce Stage, Source [L - 3; T - 2] arge Swing curre blifiers $[L - 7; T$ d. Differential O ds, current mirror bonse of Amplif non Source Stag plifiers $[L - 7; 7]$ Stage Op Amps,	Follower, Comm ent mirrors; Const - 2] peration, Basic I load. fiers [L – 6; T - 1 ge, Source Follow T - 2] Two Stage Op	tant g_m, Band gap Differential Pair, C I] wer, Common Ga Amps, Common	o references. Common- Moo te Stage, Cas – Mode Feedb	de Respons scode Stag ack(CMFB	
	Module VIII. Feedback [L – 5; T - 2] Feedback-Types, Nyquist plot, Stability- Frequency compensation techniques, Miller compensation, pole splitting, Gain Margin, Phase Margin.							
	spitting, Oa	in Margin, Phase M	largin.					

P a g e 10 | 105

Text	Text Books:
Books,	1. Behzad Razavi, "Design of Analog CMOS Integrated Circuits", McGraw-Hill, 2 nd Edition 2017.
and/or	2. Adel Sedra, Kenneth C. Smith, Tony Chan Carusone, Vincent Gaudet, "Microelectronic Circuits",
Reference	Oxford, 8th Ed. 2020
Material	3. Franco Maloberti, "Understanding Microelectronics: A Top-Down Approach", Wiley 2011.
	Reference Books:
	1. Paul R. Gray, Paul J. Hurst, Stephen H. Lewis, and Robert G. Meyer, "Analysis and Design of Analog Integrated Circuits", John Wiley & Sons, Inc., 5th Edition 2015.
	2. Roubik Gregorian, Gabor C. Temes, "Analog MOS Integrated Circuits for Signal Processing", Wiley 1986.

	EC1012: Analog IC Design [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]									
СО	Statement		T	Program	n Outcom	es				
0	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3			
CO1	Define various parameters/terms associated with MOS transistors and Analog IC design.	2	1	2	3	1	1			
CO2	Describe the operation of a MOS transistor /Amplifier/other fundamental blocks.	2	3	1	3	2	2			
CO3	Solve any given circuit using appropriate Large/Small Signal model equations.	3	2	1	2	2	1			
CO4	Evaluate various performance metrics such as gain/BW/Power dissipation/Input & output range etc.	3	1	1	3	2	1			
CO5	Analyze feedback circuit and determine its poles, zeros, gain margin & phase margin.	3	1	1	2	1	2			
CO6	Design a Single stage Amplifier/Differential Amplifier to meet the given specifications.	2	1	3	3	1	1			
	Average	2.50	1.50	1.50	2.67	1.50	1.33			

1	-	nt of Electronics &							
Course	TT: (1 6 (1	Program Core	Total contact hours : 42						
Code			Tutorial (T)	Practical (P)	Total Hours	Cred			
EC1013	Digital IC Design	PCR	3	0	0	3	3		
Pre-requisites/Co-requisites: Digital Circuits and Systems[ECC401/EC1011] Course After successful completion of the course), Mid-Term <u>Assessment</u> us Assessment <u>gnments/Atte</u> udent will be	nt (CA): Quiz endance able to:	MA:25%)			
Outcomes	 CO 2: Und CO 3: Ider CO 4: Ana CO 5: Des 	 CO 2: Understand the characteristics of CMOS inverter. CO 3: Identify the basic steps of ASIC Design Flow and fabrication process. CO 4: Analyze the static and dynamic characteristics of CMOS circuits. CO 5: Design and implementation of combinational and sequential circuits. 							
Topics Covered	Overview of V modularity, and Recent TrendsModule II.M CMOS inverte inverter design of interconnect CMOS inverterModule III.Co CMOS logic circ circuits, CMOS logic circuits, a Behavior of bi- CMOS D-latchModule IV.R	Module I. Overview of VLSI Design $[L - 2; T - 0]$ Overview of VLSI design methodologies, design hierarchy, concepts of regularity, modularity, and locality, VLSI design styles, design quality, packaging technology, Recent Trends in VLSI Design & its research issues in industry, MOS Transistor.							
 Basics of IC; an overview of VLSI design flow, and layout design rulidea to RTL; functional verification: simulation and formal verification linting, CDC, RDC, and X-propagation; Synthesis: technology optimization, post-synthesis: LEC, GLS; static timing analysis; constructions; testing: insertion, ATPG, BIST; chip planning and phy physical design; partitioning, floor planning, power planning, placem post route LEC, post routing GLS, DFM, ECO, DRC, physical and sealring, dummy filling, SPICE simulation, DRC and antenna clean, or Module V. Semiconductor Memories [L – 4; T - 0] Memory hierarchy and types, SRAM, DRAM structure, and implementation. 									

Page 12 | 105

	Total Contact Hours: (L=42, T=0)= 42
Text Books, and/or Reference Material	 Text Books: N. H. E. Weste and C. Harris, "Principles of CMOS VLSI Design: A System Perspective", 3rd Edition, Pearson Education 2007. Sung-Mo Kang, Yusuf Leblebici, Chulwoo Kim, "CMOS Digital Integrated Circuits", 4th edition, McGraw-Hill, 2018. Luciano Lavagno, Igor L. Markov, Grant E. Martin, Louis K. Scheffer, "Electronic Design Automation for Integrated Circuits", Handbook, Second Edition, - 2016, - CRC Press. Michael Smith, Addison-Wesley, "Application-Specific Integrated Circuits," Professional; 1 edition, June 20, 1997.
	 Reference Books: Jan M. Rabaey, Anantha Chandrakasan, Borivoje Nikolic, "Digital Integrated Circuits: A Design Perspective," 2nd Edition, Pearson Education, 2009. J. Bhaskar, "Verilog HDL synthesis: a practical primer," August 1998. Giovanni De Micheli, "Synthesis and Optimization of Digital Circuits," McGraw-Hill, 1994. J. Bhasker, Rakes Chadha, "Static Timing Analysis For Nanometer Designs: A Practical Approach," Springer, 2009. J. D. Plummer, M. Deal, and P. B. Griffin, "Silicon VLSI Technology: Fundamentals, Practice, and Modeling," Pearson, Springer; 2009.

	EC1013: Digital IC Design [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]									
СО	Statement			Program	n Outcom	es				
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3			
CO1	Acquire idea about the digital IC design techniques.	1	1	2	2	3	2			
CO2	Understand the characteristics of CMOS inverter	1	1	2	2	3	1			
CO3	Identify the basic steps of ASIC Design Flow and fabrication process.	1	1	2	3	3	3			
CO4	Analyze the static and dynamic characteristics of CMOS circuits	2	1	2	3	3	1			
CO5	Design and implementation of combinational and sequential circuits	1	1	2	3	3	2			
CO6	Evaluate the performance of CMOS circuits	1	1	2	3	3	1			
	Average	1.17	1	2	2.67	3	1.67			

Page 13 | 105

		Program Core							
Course Code	Course	(PCR)/		Tutorial (T)	Practical (P)	Total Hours	Credi		
EC2011	VLSI Technology	PCR	(L) 3	0	0	3	3		
	/ Co-requisites: r Device and Model	ing [EC1011] etion of the course, t	(CA:15% End-Tern Continuo tests/Assig), Mid-Term n Assessmen us Assessme gnments/Atte	nt (CA): Quiz endance	(MA:25%)			
Outcomes	• CO 2: Ider • CO 3: Illus • CO 4: App	er htify the fundamental strate the different me	miconductor crystal properties and growth process of Silicon als of IC fabrication nethods involved in VLSI fabrication process ed methods involved in IC fabrication						
Topics Covered	Module I. In History of IC's; Line (FEOL), Ba Module II. Ele Crystal Structure Need of Clean R Module III. Or Dry and Wet Oxi Oxide Charges, I	troduction $[L - 2; T]$ Operation & Models ick End of Line (BEC ectronic Materials a s, Defects in Crystals oom, RCA cleaning of kidation $[L - 5; T - 0]$ dation, Kinetics of O Device Isolation, LO	• 0] for Devices DL) and Clean R s, Si, Poly Si of Si. D] xidation, Ox COS, STI, O	of Interest: oom Enviro , Si Crystal (idation Rate	CMOS and M nment [L – 3 Growth, Defin Constants, De	3; T - 0] nition of cle	an roon		
	 Module IV. Lithography [L – 5; T - 0] Overview of Lithography, Radiation Sources, Masks, Photoresist, Components of Photoresist Optical Aligners, Resolution, Depth of Focus, Advanced Lithography: E-beam Lithography, X-ray Lithography, Ion Beam Lithography. Module V. Diffusion and Ion Implantation [L – 7; T - 0] Pre-Deposition and Drive-in Diffusion Modeling, Dose, 2-Step Diffusions, Successive Diffusion Lateral Diffusion, Series Resistance, Junction Depth, Irvin's Curves, Diffusion System. Problems in Thermal Diffusion, Advantages of Ion Implantation, Applications in ICs, Ion Implantation System, Mask, Energy Loss Mechanisms, Depth Profile, Range & Straggle, Lateral Straggle, Dose, Junction Depth, Ion Implantation Damage, Post Implantation Annealing, Ion Channeling Multi Energy Implantation. 								
	Module VI. Thin Film Deposition $[L - 6; T - 0]$ Physical Vapor Deposition: Thermal evaporation, Resistive Evaporation, Electron beam evaporation, Laser ablation, Sputtering. Chemical Vapor Deposition: Advantages and disadvantages of Chemical Vapor deposition (CVD) techniques over PVD techniques, reaction types, Boundaries and Flow, Different kinds of CVD techniques: APCVD, LPCVD, Metallorganic CVD (MOCVD), Plasma Enhanced CVD etc. Module VII. Etching $[L - 2; T - 0]$								

P a g e 14 | 105

	Module VIII. Metallization/Interconnects [L – 5; T - 0]							
	Overview of Interconnects, Contacts, Metal gate/Poly Gate, Metallization, Problems in							
	Aluminum Metal contacts, Al spike, Electromigration, MetalSilicides, Cu metal lines, Multi-							
	Level Metallization, Planarization, Inter Metal Dielectric.							
	Module IX. Process Integration $[L - 7; T - 0]$							
	NMOS, CMOS process, SOI process, 3D IC Process, Packaging.							
	Total Contact Hours: (L=42, T=0)= 42							
Text Books,	Text Books:							
and/or	1. S. M. Sze, "VLSI Technology", 2nd Edition, McGraw Hill, 2003.							
Reference	2. S. K. Gandhi, "Silicon Process Technology", 2nd Edition, Wiley India, 2009.							
Material								
	Reference Books:							
	1. J. Plummer, M. Deal and P. Griffin, "Silicon VLSI Technology", 1st Edition, Pearson							
	Education, 2009.							
	2. S. M. Sze and May, "Fundamentals of Semiconductor Fabrication", 2nd Edition, Wiley,							
	2004.							

EC2011: VLSI Technology [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]									
СО	Statement	Program Outcomes PO1 PO2 PO3 PSO1 PSO2 PSO3							
CO1	Outline the basics of semiconductor crystal properties and growth process of Si wafer.	1	1	3	2	1	1		
CO2	Identify the fundamentals of IC fabrication.	1	1	3	3	2	1		
CO3	Illustrate the different methods involved in VLSI fabrication process	2	2	3	2	3	1		
CO4	Appreciate the advanced methods involved in IC fabrication.	2	2	3	3	3	1		
CO5	Build the knowledge of process integration- NMOS, CMOS.	3	3	3	3	3	1		
	Average	1.8	1.8	3	2.6	2.4	1		

	Departme	nt of Electronics &	Communic	ation Engine	eering				
	Title of the	Title of the Program Core Total contact hours : 56							
Course Code	course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit		
EC2012	VLSI System Design	PCR	3	1	0	4	4		
EC2012 Pre-requisites/ Digital IC Desi Analog IC Desi Course Outcomes Topics Covered	Design Co-requisites: gn[EC1013] gn [EC1012] After the compl CO 1: Und CO 2: Lear CO 3: Und CO 4: Iden CO 4: Iden CO 5: Desi diffe CO 6: Eval Module I. VLSI System des research issues ir concepts. Deep St Module II. Block specification process and opera annotation & simu Module III. Basic tenets of sy skew & latency, A Design a constrain	PCR etion of the course, t lerstand the full custor rn about static timing lerstand the design for atify and interpret the ign and analyse the p erent specifications. luate and design of n Overview of VLSI sign methodologies, n industry: System c ub-micron Technolog Full Custom Flow on, schematic design ting corners, layout v ulation, simulation re Constraints and St ynchronous static tim Asynchronous and sy nts for a design in SD analysis; timing repor	Course A (CA:15% End-Term Continuou tests/Assig he student w om and semic analysis and or testability design towa erformance (System Desi VLSI design ase studies. gies: Some D ($L - 6; T - 1$ n entry, netli vith DRC/ L edone with p atic Timing ing: setup & nchronous c C format: desi	ssessment ma), Mid-Term <u>a</u> Assessment <u>gnments/Atte</u> ill be able to custom desig d design cons flows. ards realizing (speed, power ign [L – 2; T a flow, Recent Design auto Design Issues] st generation VS clean, para arasitic infor Analysis [I & hold timin locks, crossin sign objects,	ethods: (Cont Assessment (t (EA:60%)) nt (CA): Quiz endance n flow. straints. (T - 0] nt Trends in Y mation of VI (T - 0] nt Trends in Y mation of VI (T - 0] n and simulat rasitic extracti mation, Conc (L - 8; T - 3] g, multipath a ng clock doma- timing constra	MA:25%) zes/Class cuits and c	essment and lesign for gn & its ss: basic ation for C, back ELL. hs, clock k gating;		
	Module IV.Semiconductor Memories $[L - 8; T - 2]$ Memory hierarchy and types; SRAM Cell optimization and design metrics, memory read and write path; DRAM array design and related constraints, DRAM interface- address decoding, pipelining, data interface, charge pumps; non-volatile memory cell-basic principle and operation, reliability considerations of NVM; Case study- high speed memory, low voltage memory.Module V.Design for Testability $[L - 8; T - 2]$ Introduction to DFT, DFT directory structure, DFT rule checker, debugging and fixing DFT violations, scan Mapping, Scan mapping, scan chain connection, using pre-compiled cores, adding testability logic, ATPG, DFT flows.Module VI.Flow for Designing Full SoC $[L - 5; T - 3]$ Block specification, schematic design entry, netlist generation and simulation, simulation for process and operating corners, layout with DRC/ LVS clean, parasitic extraction for R & C, back annotation & simulation, simulation redone with parasitic information, concepts of PCELL.Module VI.Physical Design $[L - 5; T - 3]$								

Total Contact Hours: (L=42, T=14)= 56
Text Books:
1. N. H. E. Weste and C. Harris, "Principles of CMOS VLSI Design: A System Perspective",
3rd Edition, Pearson Education 2007.
2. Jan M. Rabaey, Anantha Chandrakasan, Borivoje Nikolic, "Digital Integrated Circuits: A
Design Perspective", Second Edition, Pearson Education, 2016.
Reference Books:
1. Michael L. Bushnell, Vishwani D. Agrawal, "Essentials of Electronic Testing for Digital,
Memory and Mixed-Signal VLSI Circuits", Kluwer Academic Publishers 2002.
 Sung-Mo Kang, Yusuf Leblebici, "CMOS Digital Integrated Circuits", 3rd edition, Tata McGraw-Hill, 2003.
]

	EC2012: VLSI System Design [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]									
00	St. 4			Program	n Outcom	es				
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3			
CO1	Understand the full custom and semicustom design flow.	1	1	2	2	3	2			
CO2	Learn about static timing analysis and design constraints.	1	1	2	2	3	1			
CO3	Understand the design for testability flows.	1	1	2	3	3	3			
CO4	Identify and interpret the design towards realizing VLSI design.	2	1	2	3	3	1			
CO5	Design and analyse the performance (speed, power) of VLSI circuits and design for different specifications.	1	2	2	3	3	3			
CO6	Evaluate and design of memory cell.	2	1	2	3	3	3			
	Average	1.33	1.17	2	2.67	3	2.67			

B. C	lore]	Lat	oorat	tories
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Course Code Title of the course Program Core (PCR) / Electives (PEL) Total Number of contact hours Credit Ec1061 Analog IC Design Lab Core (Lab) 0 0 4 4 2 Pre-requisites/Co-requisites: Basic knowledge of Linux and Devices / Circuits [ECS352] Course Assessment methods: (Continuous Assessment (CA), Mid-semester assessment (MA) and end assessment (EA)): Course After going through the course, student will be able to Outcomes • CO1: Operate CAD tools (Cadence/Mentor) to simulate Analog blocks in Modern CMOS process. • CO2: Determine the characteristics of active/ & passive devices for modeling and analysis. • CO2: Determine the characteristics of active/ & passive devices for modeling and analysis. • CO2: Determine the characteristics of active/ depassive devices for modeling and analysis. • CO4: Optimize a differential amplifier to meet the target specification. • CO5: Appreciate various performance metrics like CMRR, ICMR, PSRR, SR, Power Dissipation Delay, and Noise Margin with respect to design variables. • CO6: Examine the effect of process variation using Monte Carlo simulation Topics Covered/ Syllabus 0. Determination of NMOS and PMOS device parameter (V _{T0} , k', λ, γ, SS) 3. Simulation of CMOS Inverter and measure its delay, Noise margin, power 5. Design of a voltage reference and simple, Cascode current mirror 6. Design & simulation of Common Source Amplifier 7. Design of a voltage ref		Departmer	nt of Electronics and	Communica	tion Engine	ering				
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Image: Construct of the system of	Code		(PCR) / Electives	Lecture	Tutorial	Practical	Total			
EC1061 Analog IC Design Lab Core (Lab) Image: Core (Lab) Pre-requisites/Co-requisites: Basic knowledge of Linux and Devices / Circuits [ECS352] Course Assessment methods: (Continuous Assessment (CA), Mid-semester assessment (MA) and end assessment (EA)): Course Outcomes After going through the course, student will be able to • • CO1: Operate CAD tools (Cadence/Mentor) to simulate Analog blocks in Modern CMOS process. • CO2: Determine the characteristics of active/ & passive devices for modeling and analysis. • CO3: Design an inverter (and other basic gates) based on the given specifications. • CO4: Optimize a differential amplifier to meet the target specification • CO5: Appreciate various performance metrics like CMRR, ICMR, PSRR, SR, Power Dissipation Delay, and Noise Margin with respect to design variables. • • Co6: Examine the effect of process variation using Monte Carlo simulation Topics Co6: Examine the Step of NMOS and PMOS characteristics 2. Determination of NMOS and PMOS Resistive Load Inverter. 4. Simulation of CMOS Inverter and measure its delay, Noise margin, power 5. Design of a voltage reference and simple, Cascode current mirror 6. Design of a voltage reference and simple, Cascode current mirror 7. Simulation of Ring Oscillator. <th></th> <th></th> <th>(PEL)</th> <th>(L)</th> <th>(T)</th> <th></th> <th>Hours</th> <th></th>			(PEL)	(L)	(T)		Hours			
Lab Course Basic knowledge of Linux and Devices / Circuits [ECS352] Course Assessment methods: (Continuous Assessment (CA), Mid-semester assessment (MA) and end assessment (EA)): Assignments, Quiz/ test, and End Semester Examination Course Outcomes After going through the course, student will be able to • CO1: Operate CAD tools (Cadence/Mentor) to simulate Analog blocks in Modern CMOS process. • CO2: Determine the characteristics of active/ & passive devices for modeling and analysis. • CO3: Design an inverter (and other basic gates) based on the given specifications. • CO4: Optimize a differential amplifier to meet the target specification • CO6: Examine the effect of process variation using Monte Carlo simulation Topics Co6: Examine the effect of process variation using Monte Carlo simulation Topics 1. Determination of NMOS and PMOS characteristics 2. Determination of NMOS and PMOS device parameter (V _{T0} , k', λ, γ, SS) 3. Simulation of CMOS Inverter and measure its delay, Noise margin, power 5. Design of a voltage reference and simple, Cascode current mirror 6. Design & simulation of Common Source Amplifier 7. Simulation of Ring Oscillator. 8. Monte Carlo Simulation and process variation				0	0	4	4	2		
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 Simulation of Ring Oscillator. Monte Carlo Simulation and process variation 						t mirror				
8. Monte Carlo Simulation and process variation										
	Text/					ts". McGraw-	Hill			
Reference 2. Cadence Tutorials :				0.100 11108						
Materials https://nano.wiki.ifi.uio.no/Cadence-Tutorial-English-cadence 6.1.6				-Tutorial-En	glish-cadenc	e 6.1.6				

	EC1061: Analog IC Design Lab [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]										
СО	Statement	Program Outcomes									
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3				
CO1	Operate CAD tools (Cadence/Mentor) to simulate Analog blocks in Modern CMOS process.	3	1	2	2	2	1				
CO2	Determine the characteristics of active/ & passive devices for modeling and analysis.	1	1	3	3	3	1				
CO3	Design an inverter (and other basic gates) based on the given specifications.	2	2	3	3	3	1				
CO4	Optimize a Differential amplifier to meet the target specification	3	1	2	2	2	1				
CO5	Appreciate various performance metrics like CMRR, ICMR, PSRR, SR, Power Dissipation, Delay, and Noise Margin with respect to design variables.	1	1	3	3	3	1				
CO6	Examine the effect of process variation using Monte Carlo simulation	3	1	2	2	2	2				
	Average	2	1.2	2.6	2.6	2.6	1				

P a g e 18 | 105

	Departme	nt of Electronics and	Communica	tion Engine	ering				
Course	Title of the course	Program Core	Total Nun	nber of conta	ct hours		Credit		
Code		(PCR) / Electives	Lecture	Tutorial	Practical	Total			
		(PEL)	(L)	(T)	(P) [#]	Hours			
EC1062	Digital IC Design	Core (Lab)	0	0	4	4	2		
	Lab								
	ites/Co-requisites:	Course Assessment					id-Term		
	ronics (ECC01),		Assessment (MA:25%) and End-Term Assessment (EA:60%))						
	ctor Devices and	Continuous Assess	ment (CA): Q	Quizzes/Class	s tests/Assigni	ments/Atter	ndance		
	EC1011), Digital								
	Systems (ECC402),								
-	Digital IC Design (EC1012)								
Course	-	8							
Outcomes									
	-	-		-		ircuits.			
		and implementation of			intial circuits				
		-	e of CMOS digital circuits.						
		CO6: Draw the Layout of CMOS Circuits							
Topics	List of experimen								
Covered		d plot the static (VTC)							
		d plot the dynamic cha				_			
	e e	d simulation of CMOS	, , , , , , , , , , , , , , , , , , , ,	,	, 0		2.2.2		
		nd implementation of C logic (PTL).	MOS transm	ission gate a	ind logic circu	nts using pa	488		
		two-phase non-overlap							
	6. Design ar	d implementation of d	ynamic and d	lomino logic	circuits.				
		nd simulation of FFs (D			pass transistor	s.			
	e e	6T SRAM Cell and me							
	9. Draw the	Layout of CMOS i) In	verter ii) Tra	nsmission ga	ite				
	Note: The simula	tions will be carried o	ut using CM	IOS 180 nm	and 65 nm p	rocess. For	r all the		
		ents need to measure							
		various loads. Results							
Text Books				-	-				
and/or	1. Eric Brunva	nd, "Digital VLSI Chip	o Design with	n Cadence ar	nd Synopsys C	AD Tools"	, 2nd		
Reference		rson Education 2009.							
Material		aey, Anantha Chandrak				ated Circu	its: A		
	Design Pers	spective", Pearson Educ	cation, 2nd E	dition, 2016	•				

	EC1062: Digital IC Design Lab [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]										
СО	Statement	Program Outcomes									
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3				
CO1	Design a CMOS inverter to meet the given specifications.	3	1	2	2	2	1				
CO2	Explain the CAD tool flow for Physical design of digital circuits.	1	1	3	3	3	1				
CO3	Analyze the impact of device sizes in the implementation of CMOS circuits.	2	2	3	3	3	1				
CO4	Design and implementation of combinational and sequential circuits	2	2	3	3	3	1				
CO5	Evaluate the performance of CMOS digital circuits.	2	2	3	3	3	1				
CO6	Draw the Layout of CMOS Circuits	2	2	3	3	3	1				
	Average	2	1.6	2.8	2.8	2.8	1				

P a g e 19 | 105

	Departmen	t of Electronics and	Communica	tion Engine	ering					
Course	Title of the course	Program Core	Total Nur	nber of conta	act hours		Credit			
Code		(PCR) / Elective	Lecture	Tutorial	Practical	Total				
		(PEL)	(L)	(T)	(P)	Hours				
EC2061	VLSI System	Core (Lab)	0	0	4	4	2			
	Design Lab									
Pre-requisit EC1061, EC	es/Co-requisites: 1062,	Course Assessment Assessment (MA:2 Continuous Assess	5%) and End	-Term Asses	ssment (EA:60)%))				
Course Outcomes	 CO2: Illustrate CO3: Design (CO4: Design a 	 CO2: Illustrate gm/ID plots and its use in Analog Circuit Design CO3: Design Opamps to meet any given specification. CO4: Design and implementation of various components of a processor. CO5: Evaluate the performance of VLSI Designs. 								
Topics		List of experiments :								
Covered/		n of gm/ID plots for va	arious Chann	el lengths.						
Syllabus	2. Design an	d optimize a two stage	Opamp.	-						
	Ū.	Band-gap reference C								
		8 bit Flash ADC and 1								
		d implementation of A								
		d implementation of S			7					
		d implementation of M d implementation of C				hy 2 modu	lac			
		d implementation of R			mai and sint-	oy-2 mouu	105.			
		d implementation of S			tend Modules					
Reference Materials	 B. Razavi, "De Allan Hastings N. H. E. West 	esign of Analog CMOS , "The Art of Analog I e and C. Harris, "Prir on Education 2007.	Integrated C Layout", Pren	<i>Circuits</i> ", Mo tice Hall, Se	cGraw-Hill Ec cond Edition,	lucation, 20 2005.				

	EC2061: VLSI System Design Lab [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]										
СО	Statement		1	Program	n Outcom	es					
0	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3				
CO1	Employ CAD tools to carry out Mixed Signal Design using bottom up approach	1	1	2	3	3	1				
CO2	Illustrate gm/ID plots and its use in Analog Circuit Design	2	2	2	3	3	1				
CO3	Design Opamps to meet any given specification	2	2	2	3	3	1				
CO4	Design and implementation of various components of a processor	3	2	3	3	3	1				
CO5	Evaluate the performance of VLSI Designs.	3	3	3	3	3	2				
	Average	2.2	2	2.4	3	3	1.2				

C. Common Pool Electives

	Department of	f Electronics and	Communica	tion Engine	ering						
		Program	Total	contact hour	rs: 70 (L-42 +	P-28)					
Course Code	Title of the course	Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit				
EC9001*	Digital Signal Processing using MATLAB*	Electives (PEL)	3	0	2	5	4				
Pre-requis		Course Assessment methods: (Continuous Assessment (CA), Mid-									
	1 Systems (ECC303)	semester assess									
Mathemati	<u>cs – II (MAC02)</u>	Assignments, C Semester Exam		st, Mid-seme	ster Examinati	ion and En	d				
Course Objectiv	Ye Systems in Frequency I Analog Filter Design; I	oduction to DSP; I and Non Recursiv Domain; Simple Di Digital Filter Struct	Digital Syster e; Discrete F gital Filters; ture, Synthes	Fourier Trans Digital Proce is and Desig	form; Z Trans essing of Conti n of Adaptive	form; Disc nuous Tim Filters.	rete Time				
	On successful complete CO1# Analyse a given know the property of a					rm to					
Course Outcome	problem, construct sim	CO2# Process signals to make them more useful; and how to design a signal processor for a given problem, construct simple IIR and FIR filter.CO3# Design and Analysis of various types of Analog Butterworth and Chebyshev Filters									
	CO4# Design methods CO5# Perform Frequer FIR and IIR Filter Stru CO6# Describe the ope	ncy transformation cture.	s in Analog a	-	omains. Realiz	zation of D	igital				
Topics Covered/ Syllabus	Module I. $(L-1)$ Introduction: reasons bof the course. [CO#1]		-	nals, brief his	storical develo	pment, org	anization				
	difference equations, f	Module II. $(L-2)$ Theory of discrete time linear system sequences, linear time invariant systems, causality, stability, difference equations, frequency response, discrete Fourier series, relation between continuous and discrete systems, Inverse Systems, Stability. [CO#1]									
	Z –transform: definiti from the system functi the singularity location	Module III. $(L - 2; P - 1)$ Z –transform: definition, properties of Z transform, system function, digital filter implementation from the system function, region of convergence in the Z plane, determining filter coefficients from the singularity locations, geometric evolution of Z transform in the Z plane, relationship between Fourier transform and Z transform, inverse Z transform. [CO#1]									
	Module IV. $(L - 3; P)$ Transform technique: transform, properties o in time and decimation	Fourier transform, f DFT, circular cor	volution, co	mputations f							

P a g e 21 | 105

Module V. (L - 5; P - 2)

Digital filter structures: system describing equations, filter categories, All Pass Filters, Comb Filters, direct form I and II structures, cascade and parallel communication of second order systems, Polyphase representation of filters, linear phase FIR filter structures, Compensatory Transfer Functions, frequency sampling structure for the FIR filter. Test for Stability using All Pass Functions. [CO#1, 2]

Module VI. (L - 5; P - 2)

IIR filter design techniques: Analog Filter Design, Analog Butterworth lowpass filter design techniques, Analog Chebyshev LPF, Design methods to convert analog filters into digital filters, frequency transformation for converting lowpass filters into other types, all-pass filters for phase response compensation. **[CO#2, 3]**

Module VII. (L - 5; P - 2)

Digital Filter Structures: IIR Realizations, All Pass Realizations, FIR and IIR Lattice Synthesis, IIR Design by Bilinear Transformation, Digital to Digital Frequency Transformation. **[CO#2, 3,4]**

Module VIII. (L-5; P-1)

FIR filter design techniques: Windowing method for designing FIR filters, DFT method for approximating the desired unit sample response, combining DFT and window method for designing FIR filter, frequency sampling method for designing FIR filter [CO#2, 3]

Module IX. (L - 5; P - 2)

FFT- Derivation of the Radix-2 FFT: Describe the purpose of the Fast Fourier Transform (FFT) and explain its relationship with DFT, Outline the Fast Fourier Transform (FFT) in mathematical form using twiddle factors, Explain the properties of twiddle factors, Describe how the N-point sequence can be decomposed into N/2-point sequences and how the Discrete Fourier Transform (DFT) can be calculated, Explain the relationship between N-point DFT with N/2-point DFT of even and odd values of the signal, Outline the benefits of the radix method for FFT and its computational savings. **[CO#1,2]**

Module X. (L - 3; P - 1)

Adaptive Filters - Prediction and System Identification: Describe the characteristics of adaptive systems, Explain the functionality and operation of a closed-loop configuration involving adaptive filters, Explain the functionality and operation of a prediction configuration and system identification configuration involving adaptive filters, Outline applications for the system identification configuration with adaptive filters. **[CO#5]**

Module XI. (L - 3; P - 1)

Adaptive Filters - Equalization and Noise Cancellation: Explain the operation of the equalization configuration and the noise cancellation configuration involving adaptive filters, Outline applications for the equalization and noise cancellation configurations with adaptive filters, Explain how noise cancellation works through adaptive filters. **[CO#4,5]**

Module XII. (L - 3; P - 1)

Adaptive Filters - Adaptive FIR filter and the LMS algorithm: Outline the operations of a basic adaptive Finite Impulse Filter (FIR) filter system in mathematical form, Explain the cost function of an adaptive Finite Impulse Filter (FIR) filter system, Outline the concept and purpose of the Steepest Descent and the Least Means Squares (LMS) algorithm, Discuss the pros and cons of using the LMS algorithm for adaptive FIR filtering. **[CO#2, 3, 4, 5]**

 Text Books, and/or
 Text Books:

 Reference
 [1] Alan V. Oppenheim, Ronald W. Schafer, and John R. Buck, "Discrete-Time Signal Processing", Second Edition, Pearson Education India.

 [2] John G. Proakis, Dimitris G. Manolakis, and D Sharma, "Digital Signal Processing: Principles", Algorithms and Applications, 3rd Edition, Pearson Education India.

Page 22 | 105

[3]	Richard G. Lyons, "Understanding Digital Signal Processing", Prentice Hall, 1996. ISBN: 0201634678.
	Sanjit K. Mitra, "Digital Signal Processing: A Computer - Based Approach", McGraw- Hill Higher Education
	Tarun Kumar Rawat, " <i>Digital Signal Processing</i> ", Oxford University Press, ISBN: 9780198081937
	Donald S. Reay, "Digital Signal Processing Using the ARM Cortex M4 Paperback".
	e Books/materials:
[1]	S. W. Smith, "The Scientist and Engineer's and Guide to Digital Signal Processing", California Technical Publishing, 1997. ISBN: 0-9660176-3.
[2]	Vinay K. Ingle, John G. Proakis, "Digital Signal Processing using MATLAB," Brooks/Cole-Thomson Learning
[3]	https://nptel.ac.in/courses/117/102/117102060/
[4]	Digital Signal Processing using Arm Cortex-M based Microcontrollers: Theory and Practice https://www.arm.com/resources/education/textbooks/dsptextbook

EC9001: *Digital Signal Processing using MATLAB (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

			F	Program	Outcom	es	
СО	Statement		PO 2	PO3	PSO 1	PSO 2	PSO 3
CO 1	Analyse a given signal or system using tools such as Fourier transform and z-transform to know the property of a signal or system.	3	2	1	3	2	1
CO 2	Process signals to make them more useful; and how to design a signal processor for a given problem, construct simple IIR and FIR filter.	1	2	1	1	1	1
CO 3	Design and Analysis of various types of Analog Butterworth and Chebyshev filters.	3	3	3	3	2	2
CO 4	Design methods to convert analog filters into digital filters.	3	3	3	2	2	2
CO 5	Perform Frequency transformations in Analog and Digital domains. Realization of Digital FIR and IIR Filter Structure.	3	3	2	3	3	3
	Average		2.6	2	2.4	2	1.8

CO2: To familiariz problems.	Assignments, Quiz	Lecture (L) 3 nt methods: (sessment (M. z/class test, N	Tutorial (T) 1 Continuous A A) and end as	ssessment (EA	Total Hours 4 CA), Mid-se (A)):				
Statistical Signal Processing tes: EC1001 CO1: Understandin CO2: To familiariz problems.	(PEL) PEL Course Assessmen ass Assignments, Quiz	(L) 3 nt methods: (sessment (MA z/class test, N	(T) 1 Continuous A A) and end as Mid-semester	(P) 0 Assessment (C seessment (EA Examination	Hours 4 CA), Mid-so (()):	4 emester			
Processing tes: EC1001 CO1: Understandin CO2: To familiariz problems.	Course Assessmer ass Assignments, Quiz	nt methods: (sessment (Mz z/class test, N	Continuous A A) and end as Mid-semester	Assessment (C ssessment (EA Examination	CA), Mid-se A)):	emester			
CO1: Understandin CO2: To familiariz problems.	ass Assignments, Quiz ng statistical models ir	sessment (MA z/class test, N	A) and end as Mid-semester	ssessment (EA	A)):				
CO1: Understandin CO2: To familiariz problems.	Assignments, Quiz	z/class test, N	Aid-semester	Examination					
CO1: Understandin CO2: To familiariz problems.	ng statistical models in				and End S				
CO2: To familiariz problems.	-	n the analysi		1		emester			
CO3: Design and d	Course Outcomes CO1: Understanding statistical models in the analysis of signals using Stochastic processes CO2: To familiarize students with application of hypothesis testing to signal and event of problems. CO3: Design and development of optimum filters using classical and adaptive algorithms.								
The filtering problet to develop linear ad Module 2. Stocha Partial characteriza Matrix, Stochastic m Yule-Walker eqns. transmission of statt Module 3. Weinen The statement of Li	m, Linear Optimum Filaptive filters, Adaptive filters, Adaptive stic Processes and Metion of a discrete-time nodels, Wold decomposed of the complex Gaussian ionary process through r Filters: $(L - 3, T - 1)$ near Optimum Filterin	lters, Adapti e Beamformi odels ($L - 6$, e stochastic psition, Asym Process, H n a linear filte	ing (4L) , T – 2) process, Mean ptotic station Power Spect er, Power spe	an Ergodic T harity of an aut ral Density fectrum estimat	heorem, Co toregressive and its p tion.	orrelation e process roperties			
Module 4. Linear Forward Linear Pre of prediction-error Factorization, Lattic Module 5. Method	Module 4. Linear Prediction: $(L - 5, T - 2)$ Forward Linear Prediction, Backward Linear Prediction (3L), Levinson-Durbin Algorithm, Properties of prediction-error filters, Autoregressive modelling of a stationary random process, Cholesky Factorization, Lattice Predictors, All-pole, All-pass Lattice Filter Module 5. Method of Steepest Descent: $(L - 3, T - 1)$								
 Module 6. Least-I Structure and oper comparison between the LMS algorithm function approach f Module 7. Methoo Statement of Least Normal Equations a Least Squares estir 	Mean-Square (LMS) Adaptive Filters: $(L - 5, T - 2)$ ration of LMS algorithm, LMS Adaptation algorithm, Statistical LMS theor en LMS algorithm and steepest descent algorithm, directionality of convergence of for non-white inputs, Robustness of the LMS Filter, bounds on step size, transf for deterministic inputs, Normalized LMS Adaptive filters bd of Least Squares: $(L - 5, T - 2)$ t Squares Estimation problem. Data windowing, Minimum sum of error square and Linear Least Squares Filters, Time-Averaged correlation matrix, Properties of mates, Singular Value Decomposition (SVD), Pseudo-inverse, Interpretation								
	The filtering proble to develop linear ad Module 2. Stocha Partial characteriza Matrix, Stochastic r Yule-Walker eqns transmission of stat Module 3. Weiner The statement of Li Wiener-Hopf equat Module 4. Linear Forward Linear Pre of prediction-error Factorization, Lattic Module 5. Metho Basic idea of steepe Module 6. Least-I Structure and oper comparison betwee the LMS algorithm function approach f Module 7. Metho Statement of Least Normal Equations a Least Squares estin singular values and	 The filtering problem, Linear Optimum Fito develop linear adaptive filters, Adaptive Module 2. Stochastic Processes and M Partial characterization of a discrete-time Matrix, Stochastic models, Wold decomport Yule-Walker eqns., complex Gaussian transmission of stationary process through Module 3. Weiner Filters: (L – 3, T – 1) The statement of Linear Optimum Filterine Wiener-Hopf equations (3L) Module 4. Linear Prediction: (L – 5, T Forward Linear Prediction, Backward Line of prediction-error filters, Autoregressive Factorization, Lattice Predictors, All-pole Module 5. Method of Steepest Descent Basic idea of steepest descent algorithm, S Structure and operation of LMS algorith comparison between LMS algorithm and the LMS algorithm for non-white inputs, function approach for deterministic inputs Module 7. Method of Least Squares: (I Statement of Least Squares estimates, Singular Value singular values and singular vectors, Mini 	to develop linear adaptive filters, Adaptive Beamformi Module 2. Stochastic Processes and Models (L – 6, Partial characterization of a discrete-time stochastic Matrix, Stochastic models, Wold decomposition, Asym Yule-Walker eqns., complex Gaussian Process, H transmission of stationary process through a linear filte Module 3. Weiner Filters: (L – 3, T – 1) The statement of Linear Optimum Filtering, Principle of Wiener-Hopf equations (3L) Module 4. Linear Prediction: (L – 5, T – 2) Forward Linear Prediction, Backward Linear Prediction of prediction-error filters, Autoregressive modelling Factorization, Lattice Predictors, All-pole, All-pass La Module 5. Method of Steepest Descent: (L – 3, T – Basic idea of steepest descent algorithm, Steepest descent the LMS algorithm for non-white inputs, Robustness of function approach for deterministic inputs, Normalized Module 7. Method of Least Squares: (L – 5, T – 2) Statement of Least Squares Estimation problem. Data Normal Equations and Linear Least Squares Filters, T. Least Squares estimates, Singular Value Decomposi singular values and singular vectors, Minimum-Norm	The filtering problem, Linear Optimum Filters, Adaptive Filters, Li to develop linear adaptive filters, Adaptive Beamforming (4L) Module 2. Stochastic Processes and Models (L – 6, T – 2) Partial characterization of a discrete-time stochastic process, Me Matrix, Stochastic models, Wold decomposition, Asymptotic station Yule-Walker eqns., complex Gaussian Process, Power Spect transmission of stationary process through a linear filter, Power spec Module 3. Weiner Filters: (L – 3, T – 1) The statement of Linear Optimum Filtering, Principle of Orthogona Wiener-Hopf equations (3L) Module 4. Linear Prediction: (L – 5, T – 2) Forward Linear Prediction, Backward Linear Prediction (3L), Levir of prediction-error filters, Autoregressive modelling of a statio Factorization, Lattice Predictors, All-pole, All-pass Lattice Filter Module 5. Method of Steepest Descent: (L – 3, T – 1) Basic idea of steepest descent algorithm, Steepest descent applied to Module 6. Least-Mean-Square (LMS) Adaptive Filters: (L – 5 Structure and operation of LMS algorithm, LMS Adaptation al comparison between LMS algorithm and steepest descent algorithm the LMS algorithm for non-white inputs, Robustness of the LMS F function approach for deterministic inputs, Normalized LMS Adapt Module 7. Method of Least Squares: (L – 5, T – 2) Statement of Least Squares Estimation problem. Data windowing Normal Equations and Linear Least Squares Filters, Time-Average Least Squares estimates, Singular Value Decomposition (SVD), singular values and singular vectors, Minimum-Norm solution to the	The filtering problem, Linear Optimum Filters, Adaptive Filters, Linear Filter Str to develop linear adaptive filters, Adaptive Beamforming (4L) Module 2. Stochastic Processes and Models (L – 6, T – 2) Partial characterization of a discrete-time stochastic process, Mean Ergodic T Matrix, Stochastic models, Wold decomposition, Asymptotic stationarity of an aur Yule-Walker eqns., complex Gaussian Process, Power Spectral Density transmission of stationary process through a linear filter, Power spectrum estimat Module 3. Weiner Filters: (L – 3, T – 1) The statement of Linear Optimum Filtering, Principle of Orthogonality, minimur Wiener-Hopf equations (3L) Module 4. Linear Prediction: (L – 5, T – 2) Forward Linear Prediction, Backward Linear Prediction (3L), Levinson-Durbin A of prediction-error filters, Autoregressive modelling of a stationary random Factorization, Lattice Predictors, All-pole, All-pass Lattice Filter Module 5. Method of Steepest Descent: (L – 3, T – 1) Basic idea of steepest descent algorithm, Steepest descent applied to Wiener filter Module 6. Least-Mean-Square (LMS) Adaptive Filters: (L – 5, T – 2) Structure and operation of LMS algorithm and steepest descent algorithm, directionalit the LMS algorithm for non-white inputs, Robustness of the LMS Filter, bounds of function approach for deterministic inputs, Normalized LMS Adaptive filters Module 7. Method of Least Squares: (L – 5, T – 2) Statement of Least Squares Estimation problem. Data windowing, Minimum st Normal Equations and Linear Least Squares Filters, Time-Averaged correlation Least Squares estimates, Singular Value Decomposition (SVD), Pseudo-inver	The filtering problem, Linear Optimum Filters, Adaptive Filters, Linear Filter Structures, Aption develop linear adaptive filters, Adaptive Beamforming (4L) Module 2. Stochastic Processes and Models (L – 6, T – 2) Partial characterization of a discrete-time stochastic process, Mean Ergodic Theorem, Co Matrix, Stochastic models, Wold decomposition, Asymptotic stationarity of an autoregressive Yule-Walker eqns., complex Gaussian Process, Power Spectral Density and its p transmission of stationary process through a linear filter, Power spectrum estimation. Module 3. Weiner Filters: (L – 3, T – 1) The statement of Linear Optimum Filtering, Principle of Orthogonality, minimum mean-sque Wiener-Hopf equations (3L) Module 4. Linear Prediction: (L – 5, T – 2) Forward Linear Prediction, Backward Linear Prediction (3L), Levinson-Durbin Algorithm, F of prediction-error filters, Autoregressive modelling of a stationary random process, F Factorization, Lattice Predictors, All-pole, All-pass Lattice Filter Module 5. Method of Steepest Descent: (L – 3, T – 1) Basic idea of steepest descent algorithm, Steepest descent applied to Wiener filter, stability, I Module 6. Least-Mean-Square (LMS) Adaptive Filters: (L – 5, T – 2) Structure and operation of LMS algorithm, LMS Adaptation algorithm, Statistical LMS: comparison between LMS algorithm and steepest descent algorithm, directionality of convec the LMS algorithm for non-white inputs, Robustness of the LMS Filters Module 7. Method of Least Squares: (L – 5, T – 2) Statement of Least Squares Estimation problem. Data windowing, Minimum sum of error Normal Equations and Linear Least Squares Filters, Time-Averaged correlation matrix, Pro Least Squares estimates, Singular Value Decomposition (SVD), Pseudo-inverse, Interpre singular values and singular vectors, Minimum-Norm solution to the Linear Least Squares p			

Page 24 | 105

	Matrix Inversion Lemma, Exponentially weighted RLS algorithm, selection of the regularizing parameter, Update recursion for the Sum of Weighted Error Squares, Example of a single weight adaptive noise canceller, convergence analysis of the RLS algorithm, Robustness of RLS Filters
	Module 9. Kalman Filters : $(L - 5, T - 2)$ Recursive MMSE for scalar random variables, Statement of the Kalman Filtering problem, The Innovations process, Estimation of the state using Innovations process, Filtering, Initial Conditions, Kalman Filter as the unifying basis for RLS Filters, Kalman Filter variants, the Extended Kalman Filter
	Total Contact Hours: (L=41, T=15)= 56
Text Books,	Text Books:
and/or	1.Fundamentals of Statistical Signal Processing: Estimation Theory - Steven M. Kay
reference material	2. Adaptive Filter Theory - Simon Haykin (Fourth Edition)
	Reference Books:
	3. Statistical Digital Signal Processing and Modeling - Monson H. Hayes
	4. Probability, Random Variables and Stochastic Processes - Athanasios Papoulis and S. Unnikrishna
	Pillai
	5. An Introduction to Statistical Signal processing, Gray and Davisson, Cambridge University Press

EC9002: Statistical Signal Processing [Mapping between course outcomes (COs) and program outcomes (POs)]

		Program Outcomes							
СО	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Understanding statistical models in the analysis of signals using Stochastic processes	3	2	3	3	1	2		
CO 2	To familiarize students with application of hypothesis testing to signal and event detection problems.	3	2	3	3	1	2		
CO 3	Design and development of optimum filters using classical and adaptive algorithms.	3	2	3	3	1	3		
Average		3	2	3	3	1	2.33		

	Departmen	t of Electronics	and Communicat	tion Enginee	ering		
Course	Title of the course	Program	Total Number	of contact h	ours: 70 (L-42	2 + P-28)	Credit
Code		Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	
EC9003	Applications of Image Processing using Python	PEL	3	0	2	5	4
Pre-requisit	Image Processing using Python es: Systems (ECC303), al Processing (ECC603) • CO1: Under • CO2: Anal • CO3: Under	PEL Course Assess assessment (M Assignments, Examination erstand image en yze digital image erstand the applit ty to interpret di Image Fundan ge acquisition; S ns; Convolution ng; Image sharpe of image degra iodic noise redu- tering; Constrain oression and En by coding; Lossy i-resolution Im ansform, Wavel Image decompose phological Proc rations- Dilatio ture extraction; Thresholding; notion in segme s in Images and Principal compon- istogram of orie es of Python [P nment; Python I ta analysis-Num ting started witt n different mod matrix represent es. g Matplotlib an g Matplotlib; Ur	sment methods: (C <u>IA</u>) and end assess Quiz/class test, M hancement and ress es through multiress cation of morpholo gital image recogn nentals, Image En ampling; Quantiza and Correlation; <i>H</i> ening and smoother dation; Noise mod iction by frequency ted least squares fill coding of Image [coding of Image [compression; Loss age Processing [IL et function, Waveles sition and compress essing and Segmen n and erosion; O <i>Segmentation-</i> De Region based seg- ntation. their Application nent analysis, Decise nted gradient. -2] IDE; Python syntax py; Introduction to h Images using Of es; Displaying an ation of images; O nd Colormaps [P- - iderstanding different	continuous A ment (EA)): id-semester I toration tech gical process ition techniq hancement tion; Resolu <i>Enhancement</i> tion; Resolu <i>Enhancement</i> tion; Resolu <i>Enhancement</i> tion; Resolu <i>Enhancement</i> tion; Resolu <i>Enhancement</i> tering; Imag [L-6] sless compre c-6] et series, Dis sion using di ntation [L-1 pening and etection of co gmentation; as [L-4] sion tree and etection of co gmentation; as [L-4] sion tree and <i>x</i> , variables, openCV Pyth image; Writ Creating an 6]	ssessment (CA Examination a niques. niques. sing and segm ues. and Restoration tion; Relations t- Gray level i ons (spatial and tion in the pre- tering; Estimate e interpolation ssion; Quality crete wavelet for screte wave	A), Mid-ser nd End Ser entation in ion [L-15] ship betwee ntensity tra- diffequence sence of ne- ting the de- n and resam preserving transform a transform a	nester nester images. en pixels; ansforms; based); bise only gradation pling. adaptive nd multi- ransform; king and hological invariant thon data ent path; s shapes;
	Image plotting using	g Matplotlib; Ur tiple images thro mental Operat fying pixel valu	derstanding differe ough Matplotlib. ions on Images us es; Accessing imag	ent color may ing OpenCV ge properties	Python [P-4]	[] e Region of	Interest;

	Module X: Practical Exercises using OpenCV Python [P-12]Face, Eyes, and Smile detection from Image / Webcam; Object tracking by color; BGR palette with trackbars; Different blurring/smoothing and sharpening algorithms applying filters; Edge detection algorithms.Total Contact Hours: (L=42, P=28) = 70
Textbooks, and/or reference material	 Text Books: Digital Image Processing: R C Gonzalez and R E Woods; Pearson Education. Guide to Signals and Patterns in Image Processing- Foundations, Methods and Applications: Apurba Das; Springer. Digital Image Processing and Computer Vision: Sonka, Hlavac and Boyle; Cengage Learning (India Edition).
	 Reference Books: 1. Digital Image Processing: K R Castleman; Pearson Education. 2. Digital Image Processing: S Sridhar; Oxford Higher Education.

EC9003 Applications of Image Processing using Python

[Mapping the Course Outcomes (COs) to the Programme Outcomes (POs) and Programme Specific Outcomes

(ľ	S	U	S)	

		Program Outcomes						
СО	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3	
CO 1	Understand image enhancement and restoration techniques.	3	2	3	3	2	2	
CO 2	Analyze digital images through multi-resolution techniques.	3	1	2	3	1	2	
CO 3	Understand the application of morphological processing and segmentation in images.	3	2	2	3	1	2	
CO 4	Ability to interpret digital image recognition techniques.	3	2	1	3	2	2	
	Average		1.75	2	3	1.5	2	

POs:

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems

PO 2: An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSOs:

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

		f Electronics and C								
Course	Title of the course	Program Core	Total	Number of	contact hour	rs: 56	Credi			
Code		(PCR) /	Lecture	Tutorial	Practical	Total	1			
		Electives (PEL)	(L)	(T)	(P)	Hours				
EC9004	Automated Speech Signal Processing	PEL	3	1	0	4	4			
Pre-requisite	Ŭ Ŭ	Course Assessme	ent methods:	(Continuous	s Assessment	(CA). Mid-	-semeste			
1		assessment (MA)				(-))				
2. Digital Sig 3. Probability	d Systems (ECC303) mal Processing (ECC603) Theory for Engineering ECO541)/any equivalent	Assignments, Qu Examination	iiz/class test,	Mid-semest	er Examinatio	on and End	Semeste			
Course	CO1: Summariz	e the various techn	iques involv	red in collec	ting the featu	res from th	ne sneed			
Outcomes	signal in both time CO2: Understan CO 3: Compare	e and frequency dor ad the basic algorith the various techniqu nple system for spece	nain. ms of speecl les involved	n analysis co in speech an	mmon to man d speaker dete	y application.	ons.			
Topics		on to Digital Speed	ch Processin	g [L-5]						
Covered	Module I: Introduction to Digital Speech Processing [L-5] Acoustic theory of speech production; auditory perception and intelligibility; psychoacoustics; digital models for speech signals.									
	rate; speech Vs silence parallel processing app difference function; pite Module III: Linear P Solution of LPC equa recursive solution for th the LPC analysis equati formant analysis using	proach; short time ch period estimation rediction Analysis ations- Cholesky d he autocorrelation e ons; applications of	autocorrelation using the autocorrelation (L-8; T-4) [L-8; T-4] [lecomposition equations; co	tion function utocorrelatio n solution t mparison be	n; short time n function. for covariance tween the met	average n e method, thods of so	Durbir lutions			
	Introduction; homomo computational consider homomorphic vocoder techniques such as spec	Module IV: Homomorphic Speech Processing [L-8; T-4] Introduction; homomorphic systems for convolution-properties of the complex cepstrum computational considerations, the complex cepstrum of speech, pitch detection, formant estimation homomorphic vocoder; speech enhancement- nature of interfering sounds, speech enhancement techniques such as spectral subtraction, enhancement by resynthesis, Comb filter, Weiner filter, and multi microphone approach.								
	Basic pattern recogniti speech patterns; isolate using templates and d recognition, Viterbi alg techniques, features that sequence recognition; s	Module V:Automatic Speech and Speaker Recognition[L-10; T-5]Basic pattern recognition approaches; parametric representation of speech; evaluating similarity of speech patterns; isolated digit recognition system; continuous digit recognition system; recognition using templates and dynamic time warping; Hidden Markov Model for speech- HMM for speech recognition, Viterbi algorithm, training and testing using HMMS; speaker recognition- recognition techniques, features that distinguish speakers, deterministic sequence recognition for ASR; statistical sequence recognition; speaker recognition systems like speaker verification and identification systems; some aspects of computer music synthesis; music signal analysis; music retrieval.								
				Total Co	ontact Hours	: (L=42, T=	=14) = 5			

reference	2. S. D. Apte, Speech and Audio Processing, Wiley India Edition. 2019.
material	3. Thomas F. Quatieri, Discrete-Time Speech Signal Processing: Principles and Practice, Prentice
	Hall, 2008.
	Reference books:
	1. G. Ben, N. Morgan, D. Ellis, Speech and Audio Signal Processing: processing and perception
	of speech and music, John Wiley and Sons, 2011.
	2. B. Jacob, M. M. Sondhi, Y. Huang, Handbook of Speech Processing, Springer, 2007.

EC9004 Automated Speech Signal Processing

[Mapping the Course Outcomes (COs) to the Programme Outcomes (POs) and Programme Specific Outcomes (PSOs)]

			l	Program	Outcome	s	
СО	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3
CO 1	Summarize the various techniques involved in collecting the features from the speech signal in both time and frequency domain	3	3	3	3	2	2
CO 2	Understand the basic algorithms of speech analysis common to many applications.	3	1	2	2	1	2
CO 3	Compare the various techniques involved in speech and speaker detection.	3	2	3	3	3	3
CO 4 Design a simple system for speech processing including its implementation into application programs		3	2	3	2	3	3
	Average		2	2.75	2.5	2.25	2.5

POs:

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems

PO 2: An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSOs:

- PSO 1: Understanding mathematical modelling of communication systems and networks
- PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena
- PSO 3: Equip with modern computational and hardware tools for designing communication systems

	Departmen	nt of Electronics	and Commu	inication Ei	ngineering					
		Program		Total cont	act hours: 56					
Course Code	Title of the course	Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit			
EC9005	Probability and Random Processes	PEL	3	1	0	4	4			
Pre-requis None	ites:	Course Assess Assignments, C Examination					t (EA))			
Course Outcome s	 CO1: Characterize probability models and function of random variables. CO2: Evaluate and apply moments & characteristic functions and understand the concept of inequalities and probabilistic limits. CO3: Recognize, interpret and apply a variety of deterministic and nondeterministic random processes that occur in engineering. CO4: Calculate the autocorrelation and spectral density of a random process and recognize the relation between them. 									
Topics Covered	Module I. (L-3; T-2) Introduction: Basic of Pr Module II. (L-6; T-2) Random Variables: Defin CDF and PDF of Contin variables, The normal a Conditional probability of Module III. (L-3; T-1) Function of one random Module IV. (L-5; T-2) Mean, Variance, Momen inequality, Moment gene Module V. (L-5; T-1) Two random variables, Jacobi Module V. (L-6; T-2) Stationary random proces Autocorrelation function Module VI. (L-5; T-1) Linear systems with rand band process, Cauchy Sc Module VII. (L-5; T-1) Markov Processes, Mar Markov process, Poissso Properties of Gaussian pro-	obability theory, I nition, Continuous nuous random va approximation an lensity function variable; Transfor ts, Characteristics rating function, C Joint density and unction of two ra an and transforma asses, Second order , Cross correlation lom inputs, ACF a hwartz Inequality kov chain, CTM an- Kolmogorov	s random var riables, Disc d the Poisso mation of ra functions of thernoff's bo l distribution ndom variab ation of rando stationary, V n function, C and PSD of t C, DTMC, Bin roperties of	riables, Exan crete random on approxim ndom variab random variab random variab random variables of central om variables WSS process ovariance, F he response, biscrete tim rth- Death pro Gaussian pro	aples of contin a variables, PM hation of bino bles iables, Markov ants, Kurtosis, Marginal stati limit theorem, ses, SSS proces SD Wiener–Khin he Markov pro cocess cesses, Examp	uous random AF of discre mial randon y inequality, 0 Skewness. stics, Indepe , Two function sses, Ergodic tchine theore ocess, contin oles, Gaussia	te random n variable, Chebyshev endence of ons of two processes, em Narrow uous time n process,			

Text	Text Books:
Books,	
and/or reference	[1] A. Popoulis, U. Pillai, <i>Probability, random variables and stochastic processes</i> , Tata McGraw- Hill Inc., 4 th Ed., New Delhi, 2017
material	[2] P. Peebles, <i>Probability, random variables and random signal priniciples</i> , McGraw-Hill Inc., 4 th Ed., New York, USA, 2001
	 [3] C. W. Therrien, M. Tummala, Probability and random processes for electrical and computer engineers, 2nd Ed., CRC press, printed in India, 2012
	Reference books:
	 George R. Cooper, C. D. McGillem, Probabilistic methods of signal analysis and system analysis, Oxford University Press, 3rd Ed., New Delhi, 2007
	 [2] Alberto Leon-Garcia, Probability and random processes for electrical engineering, Pearson Education Inc., 2nd Ed., 2007

EC9005: Probability and Random Processes (Elective) [(Mapping between course outcomes (COs) and program outcomes (POs)]

CO	Statement	Program Outcomes						
СО	Statement		PO 2	PO 3	PSO 1	PSO 2	PSO 3	
CO 1	Characterize probability models and function of random variables.	1	2	1	3	1	1	
CO 2	Evaluate and apply moments & characteristic functions and understand the concept of inequalities and probabilistic limits.	2	1	2	3	1	1	
CO 3	Recognize, interpret and apply a variety of deterministic and nondeterministic random processes that occur in engineering.	2	1	2	3	2	1	
CO 4	Calculate the autocorrelation and spectral density of a random process and recognize the relation between them.	1	2	1	3	1	2	
	Average	1.5	1.5	1.5	3.0	1.3	1.3	

	Departmen	t of Electronics and C	Communicat	tion Enginee	ering			
Course		Program Core		-	ct hours: 57			
Course Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit	
EC9006	Error Correction Coding	PEL	3	1	0	4	4	
	tes: and random variables; <u>munication (ECC501)</u> • CO1: Acquir • CO2: Unders • CO3: Learn	Course Assessment assessment (MA) an Assignments, Quiz/ Examination e idea about different to stand generator matrix LDPC, BCH, RS and T	d end assess class test, Mi types of erro , encoding a Furbo codes.	ment (EA)): id-semester I r control cod nd decoding	Examination an ing techniques	nd End Ser		
Topics Covered	CO5: Differe Module I. (L – Introduction to Line Module II. (L –	e and mitigate errors in ntiate between differe 8; T- 2) ear Algebra: Group, Ri 9; T- 3) k Codes: Generator an	nt coding str	ector Space.	Dual Codes, I	Decoding,	General	
	Module III. (L – Cyclic Codes: Alge Module IV. (L – BCH Codes: Prop	braic description, Enc	oding and De	ecoding of C	yclic codes.			
	Reed Solomon (RS Module VI. (L –) Codes: Definition, D			ntation, Viterb	i decoding	, Error	
	Module VII. (L – LDPC Codes: Defin Graph, Decoding, I	nition, Construction, R	egular and in	rregular LDP	C, Belief Prop	pagation, T	anner	
	Module VIII. (L – 3; T- 1) Turbo Codes: Definition, Construction methods, Decoding Total Contact Hours: (L=43, T=							
Text Books and/or reference material	[1] Shu Lin a <i>applicatio</i>	nd Daniel.J.Costello Ja ns: 2 nd Ed., Pearson I eira and P. G. Farrel, i, 2006	ndia, New D	elhi, 2010.			ey India,	
		Moon, <i>Error Correct</i> India, New Delhi, 200		Mathemati	cal Methods	and Algor	ithm, 1 st	

P a g e 32 | 105

СО	Statement	Program Outcomes							
	Statement	PO1	PO2	PO3	PSO 1	PSO 2	PSO 3		
CO 1	Acquire idea about different types of error control coding techniques.	3	1	1	3	2	1		
CO 2	Understand generator matrix, encoding and decoding of different codes.	2	2	2	3	1	2		
CO 3	Learn LDPC, BCH, RS and Turbo codes.	2	2	1	3	1	2		
CO 4	Analyze and mitigate errors in channels.	3	1	3	3	1	1		
CO 5	Differentiate between different coding strategies.	1	1	2	3	2	2		
	Average		1.4	1.8	3.0	1.4	1.6		

EC9006: Error Correction Coding (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

	Departme	nt of Electronics and	Communica	tion Engine	ering					
Course	Title of the course	Program Core	Total con	Credit						
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours				
	Detection and Estimation Theory	PEL	3	1	0	4	4			
Pre-requisites:		Course Assessment methods: (Continuous Assessment (CA), Mid-semester								
<u>EC1001</u> ,		assessment (MA) and end assessment (EA)):								
<u>Analog Communication</u> (ECC401)		Assignments, Quiz/class test, Mid-semester Examination and End Semester Examination								
Digital Communication		Lammaton								
(ECC501)										
Course		ze students with Class		al Inference	Techniques an	nd their ap	plications			
Outcomes		cation and Signal proc		haam						
		ze students with Signa required mathematica		•	nnlementation	of statisti	cal signal			
	processing a	-	1 SKIIIS 101 G	congin and in	iprementation	of statisti	cai signai			
Topics		andom Signal and R	andom Proc	ess Basics (]	L – 4; T - 1)					
Covered	Important probability distribution functions: Gaussian, Chi-square, Rayleigh, Rician, Student's t, F,									
		iate and Multivariate				rrelation p	oroperties,			
	Stationarity, Ergodi	icity, Gaussian Process	y, Gaussian Process, Power Spectral Density							
	hypothesis testing; performance. Neyr detector, Minimax (Module III. Detect Matched Filter Det testing; Module IV. Detect Estimator Correlato Module V. Detect Composite Hypothe Module VI. Mini Introduction to sig estimators, MVUE noise.	 Module IV. Detection of Random Signal (L - 5; T - 1) Estimator Correlator, Energy Detector; Module V. Detection of Signal with unknown parameters (L - 5; T - 2) Composite Hypothesis Testing : Bayesian Approach and GLRT, Sinusoidal detection; Module VI. Minimum Variance Unbiased Estimation (L - 6; T - 2) Introduction to signal Estimation, Minimum variance unbiased estimator (MVUE), Unbiased estimators, MVUE Criterion, Cramer Rao Lower bound(CRLB); General CRLB for signals in white 								
	Module VII. Random parameter Estimation: $(L - 6; T - 2)$ Bayesian Formulation, Minimum mean square error (MMSE) and MAP estimation, Linear MMSE estimation, Wiener and optimum MMSE Filtering; Module VIII. Non-Random Parameter Estimation: $(L - 6; T - 2)$ Least squares estimation, Best linear unbiased estimation (BLUE), Geometric interpretations, Maximum likelihood Estimation, Efficiency and consistency of estimators and asymptotic properties									
Tarré D 1 .	Torrt De al-			Total	Contact Hour	rs: (L=56,	T=0)= 56			
Text Books, and/or reference material	 Text Books: [1] Fundamentals of Statistical Signal Processing, (Vol 1 & Vol 2), S.M. Kay, Pearson [2] Detection, Estimation, and Modulation Theory, Part-1, VanTrees, Jhon Wiley Reference Books: 									
	•	etection and Estimation luction to Signal detec					erlag			

Page 34 | 105

EC9007: Detection and Estimation Theory (Elective)

[Mapping between course outcomes (COs) and program outcomes (POs)]

		Program Outcomes						
CO	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3	
CO 1	To familiarize students with Classical Statistical Inference Techniques and their applications to Communication and Signal processing	3	3	3	3	1	2	
CO 2	To familiarize students with Signal Detection Theory	3	3	3	3	1	2	
CO 3	To develop required mathematical skills for design and implementation of statistical signal processing algorithm	3	3	3	3	1	3	
Average		3	3	3	3	1	2.33	

	Depa	rtment of Electronic &	& Commu	nication Eng	gineering					
Course	Title of the course	Program Core	6							
Code		(PCR) / Electives (PEL)	Lectur e (L)	Tutorial (T)	Practical (P)	Total Hours	Credit			
EC9008	Optical Communication & Networks	PEL	3	1	0	4	4			
Pre-requisites:		Course Assessment methods: (Continuous Assessment (CA), Mid-semester								
I.ElectronicDevicesandCircuits (ECC302 & ECC504)2.Electromagnetic theory andTransmission Lines (ECC 403)3.AnalogCommunication(ECC401),DigitalCommunication (ECC501)		assessment (MA) and end assessment (EA)): Assignments, Quiz/class test, Mid-semester Examination and End Semester Examination								
Course Outcomes	 CO2: The back technology. CO3: The same same same same same same same sam	 CO1: Students will be able to learn the intricacies of design constraints at optical frequency. CO2: The basic training for understanding circuits and system level implementation in lightwav technology. CO3: The students can design components and choose appropriate sources and receivers for a optical network. CO4: Understanding the usage of OTDR in monitoring an optical communication system. 								
Topics	Module I.									
Covered		Overview of general communication, advantages of optical communication; Shannon noiseless coding theorem and Shannon noisy coding theorem.								
	Module II.	Optical Fiber: $[L - 8; T - 2]$								
	optics represent	Classification of Fibers, Fiber materials and fabrication methods, Ray optics representation and wave optics representation for step index and graded index fibers, Modes, Phase and group velocity, Power flow in step index fibers.								
	Module III.	Propagation Characteristics in Optical Fibers: $[L - 8; T - 2]$								
	-	signal attenuation in fiber, dispersion, classification and effect of dispersion in information transfer, review of fiber connectors, couplers, optical filter, isolator, circulator and attenuator.								
	Module IV.	Module IV. Design aspects of optical communication: $[L - 8; T - 1]$								
	· ·	er systems, modulation schemes, digital and analog fiber communication system, system sideration, emitter and detector design, fiber choice, connectors, various amplifiers and								
	Module V.	Module V. Optical transmitter: [L – 4; T – 1]								
	Basic concepts	Basic concepts, characteristics of semiconductor injection LASER, LED, transmitter design								
	Module VI.	Module VI. Optical Receiver: [L – 6; T – 2]								
	receiver design detection; Coh	, p-n and p-i-n photo o , receiver noise, receiver erent communication: I demodulation schemes	ver sensitiv Basic conce	ity, optical a ept, detection	amplifier and 1 principles, p	its application ractical construction of the second s	ons; Direct iderations,			

	systems, DPSK system.
	Module VII. Wavelength division multiplexing (WDM): $[L - 5; T - 1]$
	multiplexing techniques, topologies and architectures, wavelength shifting, WDM demultiplexer, optical add/drop multiplexers.
	Module VIII. Dense wavelength division multiplexing (DWDM): $[L - 5; T - 1]$
	system considerations, multiplexers and demultiplexers; Fiber amplifier for DWDM, SONET/SDH transmission, modulation formats, NRZ and RZ signaling, DPSK system modeling. Potential applications and future prospects of optical fibers, multimode intensity sensors and single mode, Interferometric sensors. Recent trends in optical communication.
	Total Contact Hours: (L=42, T=14) = 56
Text Books,	Text Books:
and/or	[1] J. M. Senior, "Optical Fiber Communications", PHI, 2nd Ed.
reference	[2] G. Keiser, "Optical Fiber Communication", McGraw Hill, 3rd Ed.
material	[3] Ghatak & Thyagarajan, "Introduction to fiber Optics", Cambridge University press.
	[4] Henry Zanger and Cynthia Zanger, Fiber Optics Communication and Other Application,
	Macmillan Publishing Company, Singapore 1991.
	Reference Books:
	[1] J.H.Franz&V.K.Jain, "Optical Communications", Narosa Publishing House.
	[2] Ghatak&Thyagarajan, "Contemporary Optics", Series Title: Optical Physics and
	Engineering, Springer
	 [3] AmnonYariv and PochiYeh, Photonics: Optical electronics for Modern Communication, 6th Ed., New York, Oxford University Press

EC9008 Optical Communication & Networks [Mapping between course outcomes (Cos) and program outcomes (POs)]

				Progra	am Outcor	nes	
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3
CO1	Students will be able to learn the intricacies of design constraints at optical frequency.	1	1	2	2	3	1
CO2	The basic training for understanding circuits and system level implementation in light-wave technology.	3	2	3	2	1	2
CO3	The students can design components and choose appropriate sources and receivers for an optical network.	2	1	3	1	2	1
CO4 Understanding the usage of OTDR in monitoring an optical communication system.		2	2	3	2	2	2
	Average		1.5	2.75	1.75	2	2

		—	ent of Electronic &		_	-				
Course	Titl	e of the course	Program Core	Total Nun	iber of cont	act hours: 56	,)	Credit		
Code			(PCR) / Electives	Lecture	Tutorial	Practical	Total	1		
			(PEL)	(L)	(T)	(P)	Hours			
EC9009	Coo	operative	PEL	3	1	0	4	4		
	Cor	nmunication								
		works								
Pre-requisit	es		Course Assessment	methods (Cor	ntinuous (CT) and end ass	essment (E	A))		
NIL			CT+EA							
Course		• CO1: App	ly the knowledge of V	Vireless Com	munication i	n design of F	Relav Netw	orks		
Outcomes			lerstand different Ar			0	•			
			formance Comparison		1 10010 1 10		•••••	e unurje		
		1	sign Cooperative Com		vstems and	analyze Perfo	rmance			
Topics Cov	ered		of Fading statistics i					e throug		
ropies cov	erea		Diversity in Wirele							
		1 .	cols, Amplify and for			1				
			ard relaying- Compre							
		Hierarchical cooper			, , ,		1	0		
		Ĩ				[L -15, T - 5]				
		SER Analysis, Co multiple relays- Ma Relay selection, En , T - 5] Topic 3: Coverag Assignment algorit	ive communication w mparison of DF and ulti-node DF protocol ergy Efficiency in Co ge expansion with o hms and Multi-hop	AF Coopera - Multi-node operative Ser Cooperation, channel, Cog	tive Gain. AF protoco nsor Networl Relay Ass gnitive Coop	Cooperative l-Distributed c. ignment prot	communica Space Tim tocols and	ation wi le Codin [2 analysi		
			tion via Cooperation	_ /		Contact Hour				
Text Books and/or refer			Ext Books: 1. K.J. Ray Liu, Ahamed K. Sadek, Weifeng Su and Andres Kwasinski, <i>Cooperative ommunications and Networking</i> , Cambridge University Press 2009. Reference Books: 1.YW. Peter Hong, Wan-Jen Huang, CC. Jay Kuo, <i>Cooperative Communications and Networking: Technologies and System Design</i> , Springer 2010.							

EC9009: Cooperative Communication Networks [Mapping between course outcomes (Cos) and program outcomes (POs)]

CO	CO Statement F		Program Outcomes							
0			PO2	PO3	PSO1	PSO2	PSO3			
CO1	CO1: Apply the knowledge of Wireless	3	2	3	3	2	2			
	Communication in design of Relay Networks									
CO2	CO2: Understand different Architectures of	3	2	3	3	2	2			
	Relay Networks and Performance analysis									
	techniques and Performance Comparisons									
CO3	CO3: Design Cooperative Communication	3	2	3	3	2	2			
	Systems and analyze Performance									

P a g e 38 | 105

	Departmen	nt of Electronics and (Communica	tion Engine	ering		
Course		Program Core	Tota	l Number of	contact hours	: 56	
Course Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9010	Network Information Theory & Coding	PEL	3	1	0	4	4
Pre-requisite Digital Com Fundamenta	es: Probability Theory, imunication	Course Assessment	methods (Co	ontinuous (C	T) and end ass	essment (E	A))
NIL		CT+EA					
Course Objectives	To understand the n information using b	cole of information the binary data streams.	ory for an eff	icient, error	-free and secur	e delivery	of
Course Outcomes Topics	character CO 2: Gain knowle CO 3: Understand information theoret CO 4: Understand t flow in a network.	the concept of Information ization of information edge about techniques in Channel Capacity a tic results as fundamen he fundamentals of Ne Relative Entropy and	for information nd Shannon tal limits on twork Inform	on compress 's Law on performance nation Theor	ion and its app Information c of communic	apacity. A ation system	ms
Covered	Introduction, D entropy, Relati- inequality, Data 2. Source Co Source Coding coding, Huffma 3. Channel Channel model Binary Erasure Differential ent entropy, Relati- Theorem, Paral 4. Network	efinition and Measure ve Entropy and Mutual a processing Inequality oding and Data Comp Theorem, Variable ler an coding, Shannon Fa	of Information Information 7, Fano's inec pression agth coding, I no Elias codi erties of Char channels, Channel ferential entre I information	on, Entropy, , Chain rules quality. Kraft inequal ing, Rate dis nnel Capacit opies, Joint a , Gaussian MA	s, Jensen inequ lity, Optimal c tortion functio y, Binary Sym and Conditiona Channel, Inforr C, Interfering	ality, log s odes, Lemj n umetric Cha al differenti nation Capa MAC, Bro	um pel Ziv unnel, al acity adcast
Text Books, and/or reference material	2. Information Education	of Information Theory on Theory Coding and Pvt. Limited. Information Theory: C	Cryptograph	Cover and J y, Third Edit	tion, Ranjan B	, Wiley ose, McGra	

EC9010: Network Information Theory & Coding

PO CO	PO #1	PO #2	PO #3	PO #4	PO #5	PO #6	PO #7	PO #8	PO #9	PO #10	PO #11	PO #12	PSO #1	PSO #2	PSO #3
CO#1	2	1	2	1	1	2	1	1	1	1	1	1	2	1	1
CO#2	3	2	2	1	1	2	1	1	1	1	1	1	2	1	1
CO#3	3	3	3	1	1	2	1	1	1	2	1	1	3	3	2
CO#4	1	2	1	1	1	3	2	1	1	1	1	1	3	3	2
CO#5	2	3	1	2	1	1	1	1	1	1	1	1	2	3	2

[Mapping of CO (Course outcome) and PO & PSO]

Correlation levels 1, 2 or 3 as defined below:

1: Slight (Low) 2: Moderate (Medium) 3: Substantial (High)

P a g e 40 | 105

Course	Title of the course	Program		Total conta	act hours: 56		Credit			
Code		Core (PCR)	Lecture	Tutorial	Practical	Total	1			
		/ Electives	(L)	(T)	(P)	Hours				
		(PEL)								
EC9011	Digital Microwave Communication	PEL	3	1	0	4	4			
Pre-requisite:			Course Ass	sessment meth	ods: (Continue	ous Assessm	ient (CA),			
	ectrmagnetic Theory and				t (MA) and end					
Transmission Lines Assignments, Quiz/class test, Mid-semester Exami 2. ECC504 Electronics Devices and Circuits II Exami										
3. Microwave		incuites in	End Seme	ster Examinat	ion					
Course	CO#1: Students will	l be able to lear	n the intricac	ies of digital 1	nicrowave lon	g haul and s	hort haul			
Outcomes	communication and	spectrum manag	gement							
	CO#2: Enriched und	-		-						
	CO#3: Ability to un	1								
Topics	Digital Microwave	•			ons, spectrum	managemen	t, standards			
Covered	and regulations; Hie	nd regulations; Hierarchy, modulation formats. [L-8]								
		Microwave network performance objectives, Synchronization in passband digital transmission, control of inter-symbol interference, equalization technique in digital microwave radio, bit stream integration								
							n integration			
	[L-10]	in digital transmission system, sources of jitter in digital transmission system, line codes [L-10]								
		_		_						
	Transmission line co antennas for digital n				cessories for di L-10]	igital microv	vave radio,			
	Digital microwave c		adio equipm	ents, antenna		ares and more	unting,			
	multiplexing equipm Designing and opera		anatama m	ultimoth foding	[L-10]	lucting and	abatmation			
	fading, reflections an microwave networks	nd obstructions,								
	Transmultiplexer, co	ommon problem	s in the work	cing of transm	ultiplexers	[L-8]				
	Terrestrial microway communication serv digital hierarchy	ices and non-ter	restrial digit	al microwave			Synchronous			
				1	Total Lecture	Hours: (L=	=42, T=14)=56			
Text Books,	Text Books:									
and/or	[1] Kizer, George M			0	01	-to-point mi	crowave			
reference material	<i>Systems</i> , John Wiley [2] P. V. Sreekanth, 2013					Press (India) Pvt Ltd.,			
	Reference Books:									
	[1] P A Rizzi, Micro	owave Engineer	ing: Passive	Circuits, 200	0, PHI					
	[2] R E Collin, Four	ndations of Mic	rowave Engi	neering, John	Wiley and Sor	ns India Pvt.	Ltd			
	[3] Kao-Cheng Hua		-	neter wave co	mmunication s	systems, John	n Wiley &			
	Sons, Inc., Hoboken	, New Jersey 20)11							

СО	Statement	Program Outcomes									
0	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3				
	Students will be able to learn the intricacies of										
CO 1	digital microwave long haul and short haul	3	2	1	2	3	1				
	communication and spectrum management										
CO 2	Enriched understanding on equipment for	2	3	2	1	2	1				
02	digital microwave radio	2	3	Z	1	2	1				
	Ability to understand the operation of digital										
CO 3	microwave terrestrial and non terrestrial	2	3	1	2	2	1				
	network										
	Average	2.33	2.67	1.33	1.67	2.33	1				

EC 9011: Digital Microwave Communication [Mapping between course outcomes (Cos) and program outcomes (POs)]

	Depar	tment of Electro	nic & Comi	nunication E	ngineering					
Course	Title of the course	Program		Total conta	act hours: 56		Credit			
Code		Core (PCR) /	Lecture	Tutorial	Practical	Total				
		Electives	(L)	(T)	(P)	Hours				
		(PEL)								
EC9012	Microwave Photonics	PEL	3	1	0	4	4			
Pre requisit		thods: (Contin	uous Assess	ment (CA),						
1. ECC403 Lines	Electrmagnetic Theory and	nd Transmission		ester assessme						
	Electronics Devices and	Circuits II	-	nents, Quiz/cla		emester Exa	mination and			
	Communication		End Sen	nester Examin	ation					
4. Microwa	ve Engineering									
Course	CO#1. Students	will be able to le	orn the intri	noise of miere	waya nhotoni	25				
Outcomes		d understanding of			-		applications			
Outcomes		lents can develop		-						
			uomity to em		o nu te photon	nes compon				
Topics										
Covered	Introduction to n component [4]	nicrowave photon	ics, optical	fiber categor	ries and prine	ciples , bas	ic fiber optic			
	Analog performan	Analog performance metrics, sources of noise in optical fiber links, distortion in fiber optic links [10]								
	Microwave photor	vics component tec	hnologies	nhotonic meth	ods for microw	vave generat	ion mm Wave			
	photonics, Photor photonics [10]	-		L .		-				
	External intensity analog optical moc power Distributed	lulation methods,	photodetecto	ors, photodeted	ctor's power co					
	Propagation effect Stimulated Brillou mixing, polarization	in Scattering, St	-		-		-			
	Microwave photo forming [10]	nics signal proces	ssing, photo	nics based RI	F signal proce	essing, phase	ed array beam			
				ſ	Fotal Contact	Hours: (L=	42, T=14)=56			
Text Books	, Text Books:									
and/or										
reference	[1] Vincent J. Uric					als of microv	vave			
material	photonics, John W [2] Stavros Iezekie					John Wiley &	& Sons, Ltd			
	Reference Books :									
	[1] Henry Zanger			otics Communi	cation and Oth	ier Applicati	on, Macmillan			
	[2] J. M. Senior, "			ns", PHI, 2nd l	Ed.					
		ptical Fiber Comn								

CO	Statement	Program Outcomes								
0	Statement		PO2	PO3	PSO1	PSO2	PSO3			
CO 1	CO 1 CO#1: Students will be able to learn the intricacies of microwave photonics.		1	2	2	3	1			
CO 2	CO#2: Enriched understanding on microwave photonics, circuits and		3	1	1	3	1			
CO 3 CO#3: The students can develop ability to characterize microwave photonics component		3	2	1	1	3	1			
	Average	2.3	2.0	1.3	1.3	3.0	1.0			

EC 9012: Microwave Photonics [Mapping between course outcomes (Cos) and program outcomes (POs)]

Page 44 | 105

	Depar	tment of Electronic	& Commun	ication Eng	ineering					
G		Program Core		Total conta	ct hours: 56					
Course Code	Title of the course	(PCR) /	Lecture	Tutorial	Practical	Total	Credit			
Code		Electives (PEL)	(L)	(T)	(P)	Hours				
EC9013	Radiating Systems for Next Gen Communication	for Next PEL 3 1 0 4								
Pre-requi		1	Course A	ssessment m	ethods: (Conti	inuous Asse	essment			
	gnetic Theory and Trar	smission Lines			sessment (MA					
	; Analog Communication		(EA)):							
	ommunication (ECC501				uss test, Mid-s	emester Ex	amination			
	pagation (ECC601) (Op			emester Exa	mination					
Course	-	letion of the course th								
Outcomes		y to characterize reso			•					
		various design paran				• •				
		stand different types		based on the r	radiation mech	hanism like	wire antenna,			
		nnas, traveling wave								
		rstand different type								
		antenna, log spiral antenna and electrically long antenna as well as electrically small antenna. CO 5: Design suitable antenna feeding mechanis								
		matching mechanism		nis						
		-		of ontonnog f	Fon difforment w	rimalaga aam	municationa			
Topics		ze and synthesize dif rief review on anten				Incless con	infuncations.			
Covered		entals; Vector potent				l wave equa	tion; Antenna			
		adiation theory and ennas, Chu's limit; Lo					2]			
		ntenna Array design d circular array - the		-	· –					
		tegral Equations [L , self and mutual imp								
		anning antennas [L g antennas, travelling		roadband ant	enna; Concep	ot of smart a	intennas.			
	Operating princi	Module VI. Microstrip antennas $[L - 6; T - 2]$ Operating principle, modes, field patterns, impedance, feeding techniques and polarization; Arrays and feed networks.								
	Huygen's princ	perture antennas [L – iple, Babinet's prir pry of diffraction and	ciple; Four		•	11				
	Antenna ranges	Module VIII.Antenna measurements [L – 6; T - 2] Antenna ranges, Impedance Measurements, Radiation Patterns, Gain Measurements, Directivity Measurements, Radiation Efficiency, Current Measurements, Polarization Measurements. Total Contact Hours: (L=42, T=14)= 56								

Text Books, and/or reference material	 Text Books: [1] C. A. Balanis, Antenna Theory : Analysis and Design, 3rd ed., John Wiley & Sons, Hoboken, New Jersey, 2005 [2] John D.Kraus, Ronald J.Marhefka "Antennas: for all Applications" 4th ed.,, Tata McGraw-Hill Inc., New Delhi, 2006.
	Reference books: [1] E C Jordan and K G Balmain, <i>Electromagnetic Waves & Radiating Systems</i> , 2 nd ed., Pearson,
	 New Delhi, 2015 [2] R. C. Johnson and H. Jasik, "Antenna Engineering handbook", 3rd ed., Mc-Graw Hill Inc., New York, 1993. [3] I. J. Bhal and P. Bhartia, "Micro-strip antennas", Artech house, Dedgham, MA, 1980.
	[4] Online Reference Material(s): 1. https://nptel.ac.in/courses/117107035/

EC9013: Radiating Systems for Next Gen Communication (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

GO	Statement -	Program Outcomes							
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3		
CO1	Ability to characterize resonance and radiation property of an antenna based on application.	2	1	2	2	3	1		
CO2	Learn various design parameters that affects an antenna and antenna array patterns.	3	2	3	2	1	2		
CO3	Understand different types of antenna based on the radiation mechanism like wire antenna, aperture antennas, traveling wave antenna.	2	1	3	1	2	1		
CO4	Understand different types of antenna based on the design mechanism like log periodic antenna, log spiral antenna and electrically long antenna as well as electrically small antenna.	3	2	3	2	2	2		
CO5	Design suitable antenna feeding mechanism as well as matching mechanism.	2	2	3	2	3	2		
CO6	Analyze and synthesize different types of antennas for different wireless	3	2	3	1	2	2		
	Average		1.67	2.83	1.67	2.17	1.67		

	Depar	tment of Electro	nic & Com	nunication E	ngineering											
Course	Title of the course	Program		Total conta	act hours: 56		Credit									
Code		Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours										
EC9014	Microwave and mm Wave Measurements	PEL	3	1	0	4	4									
Lines	e: Electrmagnetic Theory an Electronics Devices and		Mid-sem Assignr	ester assessme	thods: (Continent (MA) and east test, Mid-sation	end assessme	ent (EA)):									
Course Outcomes	 CO#1: Students will be able to learn the intricacies of measurement constraints at high frequency. CO#2:Enriched understanding on microwave and mm wave measurement techniques CO#3: Ability to characterize microwave and mm wave integrated circuits 															
Topics Covered	Review of microw microwave networ	k analysis [L-2]				• •	ter and									
		Uncertainly and confidence in Measurement, high frequency voltage measurement[L-2] Application of Smith charts in microwave networks. [L-2]														
		Introduction; slotted line technique; measurement of unknown Impedance using slotted line. [L-6]														
		Coaxial Connectors in measurement, Vector network analysis and network analyzer; construction; calibration technique – SOLT and TRL calibration; measurement procedure.[L-6]														
	Microwave and m	Microwave and mm Wave power measurement. [L-6]														
	Time domain refle	ctometry. [L-2]														
	Measurement of Q	uality factor of re	sonators. [L-	-4]												
	Attenuation measu	rement. [L-2]														
	Spectrum analyzer	measurement and	l application	s. [L-4]												
	Noise measuremen and frequency stab		accuracy, M	ismatch effect	s, Phase noise	measureme	nt techniques									
	Measurement of di	electric properties	s of material	s at RF and M	icrowave freq	uencies [L-7]									
		RFIC and MMIC measurement techniques, Probe station. Special Millimeter-wave Measurement Techniques; Non-destructive IC Package Characterization [L-7] Total Lecture Hours: (L=42, T=14)=5(
Text Books and/or reference material	 [1] David. M. Po [2] Samuel Y Li [3] R.J. Collier a 12,United Ki [4] Liu, Duixian 	ao, <i>Microwave De</i> nd A.D. Skinner, ngdom, 2007	evices and C Microwave peter-wave te	2/e, 1998 (Jol lircuits, 3/e, Pl Measurement,	nn Wiley & So HI. 3/e, IET Elec	ons). trical Measu	rement Series									
			ing: Passive	Circuits, 2000), PHI		Reference Books: [1] P A Rizzi, <i>Microwave Engineering: Passive Circuits</i> , 2000, PHI									

Page 47 | 105

[2] R E Collin, Foundations of Microwave Engineering, John Wiley and Sons India Pvt. Ltd
[3] Sorin Voinigescu, High Frequency Integrated Circuits, Cambridge University Press, UK, 2013

EC 9014: Microwave and Millimeter Wave Measurements [Mapping between course outcomes (Cos) and program outcomes (POs)]

СО	Statement	Program Outcomes							
0		PO1	PO2	PO3	PSO1	PSO2	PSO3		
CO 1 Students will be able to learn the intricacies of		2	1	2	2	3	1		
01	measurement constraints at high frequency.	2	1	2	2	5	1		
CO 2	Enriched understanding on microwave and	2	3	1	1	3	1		
02	mm wave measurement techniques	2					1		
CO 3	Ability to characterize microwave and mm	2	2	1	1	2	1		
05	wave integrated circuits		2	1	1	3			
	Average		2.0	1.3	1.3	3.0	1.0		

	Depar	tment of Electro	nic & Comr	nunication E	ngineering		
Course	Title of the course	Program		Total conta	act hours: 56		Credit
Code		Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	
EC9015	Microwave Solid State Devices	PEL	3	1	0	4	4
Lines	e: Electrmagnetic Theory a Electronics Devices and	Mid-sem Assignr	ester assessme	thods: (Continent (MA) and e ass test, Mid-s ation	end assessme	ent (EA)):	
Course CO#1: Students will be able to learn the intricacies of high frequency devices. Outcomes CO#2: Enriched understanding on microwave and mm wave solid state circuits CO#3: The students can develop ability to design circuits using compound semiconductors ar SiO2 devices					ctors and Si-		
Topics Covered	Physical properties Schottky effect, So Tunnel diodes, In TRAPATT, BARH Transferred electr devices; modes of Characteristics and [10] MESFET, HEMT comparison with M Fabrication and pa	chottky barrier dio npact ionization, RITT. [10] on devices; Diffe operation; Waveg I modeling of MC , pHEMT– devi MOSFETs.[10]	de; varactor IMPATT, rential nega uide cavity r OSFET, nanc ce physics,	diode; PIN di small-signal a tive resistance microwave and oscale MOSFE characteristic	ode; Applicati analysis and a e and two-val d mm Wave G ET, Short Char es, model and	ons. [8] model of IN ley model o funn oscillato nnel effects, d noise per	IPATT diode f Gunn effect or design. [10] BSIM models
Text Books and/or reference material	 [5] David. M. Pe [6] Samuel Y Li [7] Sorin Voinig Reference Books [1] S M Sze, <i>Phy</i> [2] B. G. Streetma NJ:Prentice Hall, 2 [3] D. A. Neamen McGraw-Hill, 200 [4] Ivan Chee-Hor 	sics of Semicondue on and S. Banerjee 2006. , Semiconductor H 3.	evices and C ency Integra ctor Devices , Solid State Physics and A ujishima, De	2/e, 1998 (Joh ircuits, 3/e, Pf ted Circuits, C , John Wiley I Electronic De Devices: Basic sign and Mod	nn Wiley & So HI. Cambridge Un New York,198 evices, 5th ed. c Principles, 3	ons). iversity Press 1 Upper Sadd rd ed. New Y	s, UK, 2013 le River, York, NY:

CO	Statement	Program Outcomes							
0			PO2	PO3	PSO1	PSO2	PSO3		
CO 1	Students will be able to learn the intricacies of high frequency devices	2	1	2	2	3	1		
CO 2	Enriched understanding on microwave and mm wave solid state circuits	2	3	1	1	3	1		
CO 3	The students can develop ability to design circuits using compound semiconductors and Si-SiO2 devices	3	2	1	1	3	1		
	Average	2.3	2.0	1.3	1.3	3.0	1.0		

EC 9015: Microwave Solid State Devices [Mapping between course outcomes (Cos) and program outcomes (POs)]

P a g e 50 | 105

		Program Core	Total N	umber of co	ontact hours:	56	
Course Code	Title of the course	(PCR) / Electives (PEL)	Lectur e (L)	Tutorial (T)	Practical (P)		
EC9016	Digital Satellite and Navigation Systems	PEL	3	1	0	4	4
	nagnetic Theory ave Engineering and Digital nication as and Wave	Course Assessmen Assignme		<u>.</u>	us (CT) and en		
Course OutcomesCO#1 To compute the satellite orbit parameters, design orbits and be able to class on Kepler's six elements. CO#2 Understand the concept of satellite launching and positioning of satellites in CO#3 Ability to understand the digital satellite communication principles and tech CO#4 To introduce students in engineering and the sciences to the methods of navigation. CO#5 Assimilatethe ability to develop new satellite navigation technology						ellites in orb and techniqu thods of sat	oits ues
Topics Covered	Basic concepts, F	considerations rela requency allocatio works and services, nent	n for sate	ellite servic	es, orbital &	spacecraft	
	Basic concepts, F comparison of net	requency allocatio works and services, nent	n for sate	ellite servic	es, orbital &	spacecraft	
	Basic concepts, F comparison of network Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita	requency allocatio works and services, nent	n for sate modulation it, and ch unch Veh	ellite servic on techniqu nange in lor icles- princi	es, orbital & es used for sa	spacecraft atellite comm al manoeuv	nunication res, orbita
	Basic concepts, F comparison of network Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic	requency allocatio works and services, nent -10] geostationary orb al perturbations. La	n for sate modulation it, and ch unch Veh on satellit	ellite servic on techniqu nange in lon icles- princi e	es, orbital & es used for sa	spacecraft atellite comm al manoeuv	nunication res, orbita
	Basic concepts, F comparison of netw Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic Satellite subsystem	requency allocatio works and services, nent -10] geostationary orb al perturbations. La les for communications ns and satellite lini t control (AOC)	n for sate modulation it, and ch unch Veh on satellit x design- [2 Subsysten	ellite servic on techniqu nange in lor icles- princi e L-8] n, TT&C,	es, orbital & es used for sa ngitude, orbita iples of Rocka power system	spacecraft atellite comm al manoeuv et propulsio	res, orbita n, powere
	Basic concepts, F comparison of network Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic Satellite subsystem Altitude and orbit transponder, Friis t Satellite RF link-[Noise, the basic RI noise temperature,	requency allocatio works and services, nent -10] geostationary orbit of perturbations. La les for communications and satellite linh t control (AOC) ransmission equation L-8] F link, satellite link	n for sate modulati it, and ch unch Veh on satellit x design- [Subsysten n, G/T rat s (up and our ure, overal	ellite servic on techniqu nange in lon icles- princi e L-8] n, TT&C, io of earth s down), opti Il system te	es, orbital & es used for sa ngitude, orbita ples of Rocka power systen tation.	spacecraft atellite comm al manoeuv et propulsio n, spacecras	res, orbita n, powere ft antenna ttellite linl
	Basic concepts, F comparison of network Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic Satellite subsystem Altitude and orbit transponder, Friis t Satellite RF link-[Noise, the basic RI noise temperature,	requency allocatio works and services, nent -10] geostationary orbit of perturbations. La les for communications and satellite linh t control (AOC) ransmission equation L-8] F link, satellite link Antenna temperatu Tropospheric and Id echniques [L-8]	n for sate modulation it, and ch unch Veh on satellit t design- [Subsysten n, G/T rat s (up and on ure, overal onospheric	ellite servic on techniqu nange in lon icles- princi e L-8] n, TT&C, io of earth s down), opti 11 system te c effect.	es, orbital & es used for sa ngitude, orbita power system tation. imization RF I	al manoeuv al manoeuv et propulsio n, spacecras	res, orbita n, powere ft antenna ttellite linl actors, rai
	 Basic concepts, F comparison of networks Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic Satellite subsystem Altitude and orbit transponder, Friis t Satellite RF link-[Noise, the basic RI noise temperature, attenuation model. Satellite Access Te FDMA, TDMA, C codes. Mathematical Mo Differential and rel 	requency allocatio works and services, nent -10] geostationary orbit al perturbations. La les for communications and satellite linh t control (AOC) ransmission equation L-8] F link, satellite link Antenna temperatu Tropospheric and Id echniques [L-8] DMA techniques, c dels for Positioning	n for sate modulati it, and ch unch Veh on satellit c design- [: Subsysten n, G/T rat s (up and o ure, overal onospheric omparisor g: oncepts of	ellite servic on techniqu nange in lon icles- princi e L-8] n, TT&C, io of earth s down), opti 11 system te c effect. n of multiple	es, orbital & es used for sa ngitude, orbita power systen tation. imization RF I imperature, pr e access techn	spacecraft atellite comm al manoeuv et propulsio n, spacecras ink, inter sa opagation fa	res, orbita n, powere ft antenna ttellite lini actors, rai
	 Basic concepts, F comparison of networks Spectrum Manager Satellite Orbits [L orbital mechanics, transfer, and orbita flight, Lauch vehic Satellite subsystem Altitude and orbit transponder, Friis t Satellite RF link-[Noise, the basic RI noise temperature, attenuation model. Satellite Access Te FDMA, TDMA, C codes. Mathematical Mo Differential and rel 	requency allocatio works and services, nent -10] geostationary orbi- al perturbations. La les for communications and satellite link t control (AOC) ransmission equation L-8] F link, satellite link Antenna temperatu Tropospheric and Id echniques [L-8] DMA techniques, control lite based navigation	n for sate modulati it, and ch unch Veh on satellit c design- [: Subsysten n, G/T rat s (up and o ure, overal onospheric omparisor g: oncepts of	ellite servic on techniqu nange in lon icles- princi e L-8] n, TT&C, io of earth s down), opti 11 system te c effect. n of multiple	es, orbital & es used for sa ngitude, orbita power systen tation. imization RF I imperature, pr e access techn	spacecraft atellite comm al manoeuv et propulsio n, spacecras ink, inter sa opagation fa	res, orbita n, powere ft antenna ttellite linl actors, rai

Text Books,	Text Books
and/or	[1]Dennis Roddy, <i>Satellite Communication</i> , 4/e, Mc Graw Hill
reference	[2]Louis J. Ippolito, Jr. <i>Satellite Communications Systems Engineering: Atmospheric Effects, Satellite Link Design and System Performance</i> , 2/e, John Wiley
material	[3]Bernhard Hofmann-Wellenhof, Herbert Lichtenegger, Elmar Wasle, <i>GNSS — Global Navigation Satellite Systems</i> , 1/e, Springer, Vienna 2008
	Reference Books [4]Recommendation ITU-R P.618-11, P Series Radio Wave Propagation. [5] Pratt and Bostian, <i>Satellite Communication</i> , 2/e, John Wiley and Sons. [6]Tri T Ha, <i>Digital Satellite Communication</i> , Mc Graw Hill

СО	Statement				n Outcome	s	
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3
CO 1	To compute the satellite orbit parameters, design orbits and be able to classify them based on Kepler's six elements.	2	1	2	2	3	1
CO 2	Understand the concept of satellite launching and positioning of satellites in orbits	2	3	1	1	3	1
CO 3	Ability to understand the digital satellite communication principles and techniques	3	2	1	1	3	1
CO 4	To introduce students in engineering and the sciences to the methods of satellite radio navigation.	2	3	2	1	2	1
CO 5	Assimilate the ability to develop new satellite navigation technology	3	2	1	2	1	1
	Average	2.3	2.0	1.3	1.3	3.0	1.0

EC9016: Digital Satellite and Navigation Systems [Mapping between course outcomes (Cos) and program outcomes (POs)]

	Departmen	nt of Electron	nics and	Communica	tion Engine	ering					
Course		Program			Total Conta	act hours: 56					
Code	Title of the course	(PCR) / El		Lecture	Tutorial	Practical	Total	Credit			
		(PEL		(L)	(T)	(P)	Hours				
EC9017	Bio-molecular Communication	PEI		3	1	0	4	4			
Pre-requisit					t methods (C	Continuous (C	Γ) and end				
Analog anInformation	d Digital communication	n	assessment (EA)) Assignments, Quiz, Mid-semester Examination and End								
	on to Biology			ster Examina				1			
Course	This course will cover	basics of mo				matical tools to	o model an	d analyze			
Objective	these systems.										
	• CO1: Identify the		of comn	nunication e	ngineering a	nd cell biolog	y in the c	ontext of			
Course	molecular communi		a and the	in communi	ation mathe	dalaar					
Course Outcomes	• CO2: Explain bio-r • CO3: Apply info						epts to 1	nolecular			
	communication.					-					
	• CO4: Analyse engin	neering of mo	lecular c	communication	on systems in	n different app	lication are	as.			
	Module I. (L-4)	tion Why w	bot and	how? Evolu	tion Applica	tion areas					
	Molecular communication: Why, what, and how? Evolution. Application areas. Module II. (L-5, T-2)										
	Nature-made biological nanomachines: Protein, DNA/RNA, Lipid membrane.										
	Module III. (L-5, T-2)										
	Molecular communication in biological systems: Scales, modes and examples of molecular communication. Biomolecular topologies that work as signal differentiators of high accuracy to arbitrary										
	communication. Biomolecular topologies that work as signal differentiators of high accuracy to arbitrary input signals around their nominal operation and relevance to natural regulatory networks.										
	Module IV. (L-7, T-3)										
	Molecular communication paradigm: Molecular communication model, general characteristics, network										
	architecture.										
Topics	Module V. (L-7, T Mathematical modelli		diffusio	n and Brown	ian motion.	Benchmarking	the comm	unication			
Covered	fidelity of biomolecul						,				
	Module VI. (L-6, T										
	Communication and molecular communication						n and estin	nation in			
	Module VII. (L-4, T-			ny or moreet		icution.					
	Design and engineeri										
	programming and self assembled systems. Realizing nanoscale communications considering both electromagnetic and biological communications to design minimally invasive, biocompatible, and										
	targeted healthcare so	0	minume	ations to ut	sign minina	illy illvasive,	biocompa	ioie, and			
	Module VIII.(L-4, T										
	Application areas: Ta										
	generation electrical and biological wearable and implantable devices, i.e. Internet of Bio-NanoThings. Total Lecture Hours: (L=42, T=14) = 56										
Text	Text Books:				i Utai L		· (1-74, 1·	-17) - 30			
Books,	[1] Tadashi Nakano			ord and Tol	kuko Haragu	uchi, <i>Molecul</i>	ar Commi	inication			
and/or reference	Cambridge Unive			Alavildia 1	Fundamentel	s of Diffusi-	n Rand	1 alamia			
material	[2] Massimiliano Pi Communication i					s oj Di jj usio	п- <i>д</i> аsea I	aoieculai			
	 <i>Communication in Nanonetworks</i>, NoW Publishers, 2014. [3] Junichi Suzuki, Tadashi Nakano and Michael John Moore, Modeling, <i>Methodologies and Tools for</i> 										
	Molecular and Nano-scale Communications: Modeling, Methodologies and Tools, Springer, 2017.										
	[4] Martin Bossert, Information- and Communication Theory in Molecular Biology, Springer, 2018.										
	References: [1] Abhishek Gupta, IITK, Molecular Communication, Course EE698U.										
	Youtube: https://y										

Page 53 | 105

				Progran	n Outcon	nes	
CO	Statement	PO1	PO2	PO3	PSO 1	PSO 2	PSO 3
CO 1	Identify the intersection of communication engineering and cell biology in the context of molecular communication.	2	2	3	3	2	2
CO 2	Explain bio-nano-machines and their communication methodology.	2	3	2	2	2	1
CO 3	Apply information theoretical and mathematical modelling concepts to molecular communication.	3	2	3	3	3	1
CO 4	Analyse engineering of molecular communication systems in different application areas.	3	2	3	3	2	1
	Average	2.5	2.25	2.75	2.75	2.25	1.25

EC9017: Bio-molecular Communication [(Mapping between course outcomes (COs) and program outcomes (POs)]

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems

PO 2: An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

	Departmen	t of Electronics and	l Communic	ation Engine	ering						
Course		Program Core	Total con	tact hours: 5	6						
Course Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit				
EC9018	Queuing Theory for Telecommunication	PEL	3	1	0	4	4				
		Course Assessme				CA), Mid-sei	nester				
P	Pre-requisites:	assessment (MA)				1 1					
	EC1001	Assignments, Qui Examination	iz/class test, r	viid-semester	Examination	and End Se	mester				
	CO1: To understand the		models and a	pply in Engi	neering						
Course Outcomes	CO2: To understand sig CO3: To develop exper			•		etworks					
·			-		WOIKS						
Topics Covered	Random variables, Bind variables, Moment Gen number, Transformation Module II. Poisson Exponential distribution distribution, Properties of independent Poisson,	erating Functions, N n of random variable Process [L – 6; T – n and memoryless] of Poisson process, N	oisson, Expo Markov's inec s. - 2] property, Con Non homoger Poisson proc	nential, Gam quality, Cheb unting proces neous Poisson ess.	yshev's ineq ss, Inter arriv , Compound	uality, Laws val and wait	of large				
	Discrete time Markov Chain, Chapman Kolmogorov Equation, Limiting probabilities, Time reversal Markov Chains, Continuous time Markov Chain, Birth Death process, Transition probability function, Computation of Transition Probability, Reward Renewal Process, Semi Markov process, Regenerative Process. Module IV. Markovian Queues $[L - 9; T - 3]$ Queuing process, system performance, Notation for Queuing Systems, Little's Formula, Analysis of M/M/1, M/M/1/K, M/M/S, M/M/S/S, Queues with unlimited service (M/M/ ∞ queues). Distribution of queuing delays in FIFO case, M/M/1 and M/M/S cases Erlang's Formula M/M/S/S, M/M/S; Queues with parallel channels and Truncation (M/M/S/K)										
	Module V. Non-Markovian Queues $[L - 9; T - 3]$ Poisson input General service Time model, Poisson input Constant Service time model. Queuing system with Bulk service. Analysis of M/G/1, M/D/1, M/G/1 system with delay distribution. Generalization of M/G/1 Theory. M/G/1 with geometrically distributed message. M/G/1 with random size batch arrival.										
	Module VI. Network of Queues [L – 4; T – 1] Traffic rate equation, Little Theorem for whole network, Burke Theorem, Jackson Theorem, Priority Queues Total Contact Hours: (L=42, T=14)= 56										
Text	Text Books:										
Books, and/or reference material	[1] Fundamentals[2] Queuing TheorySpringer	of Queuing Theory: ry and Telecommun			•	ovanni Giam	ıbene,				
age 55	Reference Books: [1] Data Networks – D. Bertsekas and R. Gallager (Prentice Hall). [2] Introduction to Queuing Networks, Theory and Practice – Smith, J. MacGregor (Springer). [3] Teletraffic Theory and Applications: Haruo Akimaru and KonosukeKawashima,Springer [4] Introduction to Probability Models: Sheldon M. Ross, Academic Press										

P a g e 55 | 105

[5] Probability & Statistics with Reliability Queuing and Computer Science Applications: Kishore
Trivedi, Wiley

EC9018: Queuing Theory for Telecommunication [Mapping between course outcomes (COs) and program outcomes (POs)]

	~	Program Outcomes							
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3		
CO1	To understand the concept of queuing models and apply in Engineering	3	3	3	3	1	2		
CO2	To understand significance of advanced queuing theory in Communication Networks	3	2	3	3	1	1		
CO3	To develop expertise to analyse and design Communication Networks	3	2	3	3	1	1		
	Average		2	3	3	1	1.33		

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems

PO 2: An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

	Departm	ent of Electronics and C	Communica	tion Engine	ering			
Course	Title of the course	Program Core	Total Nu	mber of con	tact hours: 5	6	Credit	
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours		
EC9019	Quantum Communication and Computing	PEL	3	1	0	4	4	
Pre-requisit Engineering Mechanics		Course Assessmen assessment (MA) a Assignments, Quiz Examination	and end asses	ssment (EA)):			
Course Outcomes	ourse After the completion of the course the student will be able to							
Topics Covered		Fundamental Concepts Revision of fundamental quantum computing and	concepts of	quantum me	chanics on th		10; T-4] f	
	Module II:	Quantum Communication and Information[L-10; T-3]Information Theoretic Interpretations of von Neumann EntropyInformation Theory, Entropy,Information Theory, Entropy,Channel Capacity and Quantum Minimax Decision						
]	Quantum Computing Quantum Computing and Unitary Dynamics for Qu Quantum Error Correctio Eliminating the Effects o Integrability and Computa Slowing Down the Decoh Quantum Capacity of Noi	antum Code on with Impe f Spontaneo ability in Sir erence of Q	ewords rfect Gates us Emission nulating Qua uantum Bits	in Quantum (stems Computation	12; T-4]	
		On Covariant Instruments Generalised Uncertainties	antum Measurement Theory and Statistical Physics[L-10; T-3]Covariant Instruments in Quantum Measurement Theory neralised Uncertainties for Quantum Signal Processing Open System Approach to Quantum Computers[L-10; T-3]					
				Total Lec	ture Hours: ((L=42, T=1	4)= 56	
Text Books and/or reference material	1. Osamu Hiro Measuremer	ta, A.S. Holevo, C.M. Ca <i>nt</i> , Springer, 2012 icic, <i>Quantum computatio</i> 06		m Communi	cation, Comp	uting, and		
	Reference book 1. Research Ar							

			Program Outcomes							
CO	Statement	РО 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3			
CO 1	Understand the concept of quantum mechanics in the context of quantum computing and quantum communication	2	2	2	2	2	1			
CO 2	Understand the scope of quantum communication and information	2	2	2	2	2	1			
CO 3	Understand the perspective of quantum computing	2	2	2	2	2	1			
	Average			2	2	2	1			

EC9019: Quantum Communication and Computing [Mapping between course outcomes (COs) and program outcomes (POs)]

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems

PO 2: An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

	Departi	nent of Electronics and C	Communica	tion Engine	ering				
Course	Title of the course	Program Core	Total Nu	mber of con	tact hours: 50	6	Credit		
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	-		
EC9020	Cloud Computing	PEL	PEL 3 1 0 4						
Networking	rchitecture, Computer	Course Assessmen assessment (MA) a Assignments, Quiz Examination	nd end asses z/class test, N	ssment (EA)) Mid-semester):				
Course Outcomes	 CO 1: Und CO 2: Lea 	lerstand the concept of clourn the mechanism and arch	tion of the course the student will be able to d the concept of cloud computing mechanism and architecture of cloud computing acept of cloud computing in real application						
Topics Covered	Module I: Module II:	Introduction, Understand Models, Cloud Enabling Cloud computing mech Cloud Infrastructure Mec	damental cloud computing [L-12; duction, Understanding Cloud Computing, Fundamental Concepts and els, Cloud Enabling Technology, Fundamental Cloud Security ad computing mechanisms [L-10] d Infrastructure Mechanisms, Specialized Cloud Mechanisms, Cloud agement Mechanisms, Cloud Security Mechanisms						
	Module III:	Cloud computing archi Fundamental Cloud Arch Cloud Architectures	tecture				0, T4] lized		
	Module IV:	Working with clouds Cloud Delivery Model Co Quality Metrics and SLA	ud Delivery Model Considerations, Cost Metrics and Pricing Models, S						
				Total Lect	ture Hours: (L=42, T=1	4)= 56		
Text Books and/or reference material	 Text Books: 3. Thomas Erl, Zaigham Mahmood, and Ricardo Puttini, <i>Cloud Computing: Concepts, Tecc & Architecture,</i> Pearson Education India; 1st edition, 2014 4. Toby Velte, Anthony Velte, Robert Elsenpeter, <i>Cloud Computing, A Practical Approach</i> McGraw Hill Education; 1st edition, 2017 Reference books: 2. Research Articles 								

EC9020 Cloud Computing [Mapping between course outcomes (COs) and program outcomes (POs)]

		Program Outcomes						
CO	Statement	РО 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3	
CO 1	Understand the concept of cloud computing	2	3	1	3	1	2	
CO 2	Learn the mechanism and architecture of cloud computing	2	3	1	2	2	2	
CO 3	Apply concept of cloud computing in real application	2	2	2	2	1	2	
Average		2	2.7	1.3	2.3	1.3	2	

Page 59 | 105

Course		Program Core			ct hours : 56	1				
Code	Title of the course	(PCR) /	Lecture	Tutorial	Practical	Total	Credi			
	24.11	Electives (PEL)	(L)	(T)	(P)	Hours				
	Machine Learning and									
EC9021	Deep Learning	PEL	3	1	0	4	4			
	using Python									
Pre-requisi			Course A	ssessment m	ethods: (Class	Assessme	nt (CA),			
	uter programming la	nguages like			ent (MA) and	end semes	ter			
Python, C+	+ ,Matlab etc.		examinati	< <i>//</i>						
					ass test, Mid-s Semester Exa					
Course	After the comp	etion of the course th				IIIIIatioii				
Outcomes	-	sing Python libraries				n it into tra	ining			
	and test		,P		, F		8			
		nderstand Machine L								
		terpret unsupervised			clustering alg	gorithms				
		nplement linear and r			1					
		nplement various typ lom forest	es of classifi	cation metho	bds such as SV	/M, decisio	on tree			
			learning wit	h the help of	Artificial neu	ral Networ	k			
 CO6: Implement supervised learning with the help of Artificial neural Net CO7: Learn dimensionality reduction, Deep learning and Convolutional neural Net 										
	network									
Topics		n for Machine Lear				• • • •				
Covered		Programming basics, Applications of machine learning, Supervised vs Unsupervised Learning, Python libraries for machine learning								
	Python libraries f	Python libraries for machine learning								
		Module II. Regression [L-5;T-2]								
	Linear Regression	Linear Regression, Non-linear Regression, Model evaluation methods								
	Module III Ung	Module III. Unsupervised Learning and Regenerative model[L-8;T-2]								
		Introduction to Unsupervised Learning, K-Means Clustering, Auto encoder, Restricted								
		Boltzmann Machine								
	Module IV. Sup	Module IV. Supervised Learning and Discriminative Models [L-10;T-3]								
	Introduction to St	Introduction to Supervised Learning, Perceptron, Multilayer Perceptron, MLP: Backpropagation								
		and Applications, Radial Basis Function Neural Networks (RBF), Training of RBF, Decision								
		Trees, Random Forest, Support Vector Machines (SVM), Building, training and evaluation of								
	Machine Learnin	Machine Learning Model.								
	Module V. Dime	Module V. Dimensionality Reduction[L-4;T-2]								
		Feature Selection, Principal Component Analysis								
	Madul VI D		T 1 1							
		p Learning [L-07; een Neural Network		es of Convol	utional Neuro	l Network				
		Introduction to Deep Neural Network, Architectures of Convolutional Neural Network ,Implementation of ConvNet/CNN from scratch using Python								
	,promontumon		seraton di							
Tout Deal	Tout Dealer			Total L	ecture Hours	: (L=42, T	=14)= 5			
Text Books and/or		ev-Shwartz and Shai	Ben-David	"Understan	ding Machine	Learning	From			
reference		Algorithms, "Camb								
material		J,	0	, ,_						

 Manaranjan Pradhan , U Dinesh Kumar, "<i>Machine Learning using Python</i>", First edition,2019, Wiley Gowrishankar S., Veena A, "<i>Introduction to Python Programming</i>", CRC Press Taylor & Francis Group,2019
 Abhishek Kumar Pandey, Pramod Singh Rathore, Dr. S. Balamurugan, "A Practical Approach for Machine Learning and Deep Learning Algorithms", BPB Publications, India, First Edition 2019
Reference books:
 Simon Haykin, "Neural networks and learning machines," Pearson, 3rd edition, 2009 Charu C.Aggarwal, "Neural Networks and Deep learning, "Springer, 2018

EC9021: Machine Learning and Deep Learning using Python [Mapping between course outcomes (Cos) and program outcomes (POs)]

The correlation levels are 1, 2 or 3, denoting: 1: Slight (Low) 2: Moderate (Medium) 3: Substantial (High).

CO	Statement			Program	n Outcom	es	
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3
CO1	Using Python libraries, import and wrangle data, then partition it into training and test datasets	3	2	3	1	1	3
CO2	Understand Machine Learning(ML) concepts and types of ML	3	2	2	1	1	3
CO3	Interpret unsupervised learning and learn to use clustering algorithms	2	2	2	1	1	3
CO4	Implement linear and non-linear regression	2	2	3	1	1	3
CO5	Implement various types of classification methods such as SVM, decision tree and random forest	2	2	2	1	1	3
CO6	Implement supervised learning with the help of Artificial neural Network	3	2	2	3	1	1
CO7	Learn dimensionality reduction, Deep learning and Convolutional neural network	2	2	3	2	1	2
	Average	2.42	2.0	2.42	1.0	1.42	2.57

	—	of Electronics and (-	-	_				
Course	Title of the course	Program Core			contact hour	s: 56	Credi			
Code		(PCR) / Electives	Lecture	Tutorial	Practical	Total				
		(PEL)	(L)	(T)	(P)	Hours				
EC9022	Big Data Computing	PEL	3	1	0	4	4			
Pre-requisit	es:	Course Assessmen assessment (MA) a				CA), Mid-se	emester			
Machine Lea	arning (ECE715),	Assignments, Quiz				and End Se	emester			
Database Ma (CSC502)	anagement Systems	Examination								
Course Outcomes	• CO2: Explain	and the Hadoop Fram and Analyze the Big			programming	in both Hao	loop and			
	 Spark Framewor CO 3: Demonst 	rk. t rate Spark programn	ning with dif	Foront progra	mming langu	2025				
		the most suitable mad					ì.			
		cial network graphs us			or namoring					
		ent and Evaluate the			lures using Pi	g, Hive and	l Sqoor			
Topics	Module I: Introdu									
Covered	Data storage and an									
	-	architecture; Requirement for new analytical architecture; Challenges in Big Data analytics; Need of Big Data frameworks.								
	Module II: Hadoop Requirement; Design HDFS commands; Ma	principle; Hadoop c ap reduce programmi								
	sorting, pipelining Ma	sorting, pipelining MapReduce jobs.								
	Module III: MapR K-means; PLANET; ranking; Expectation	Parallel SVM, Asso	ciation rule	mining in M	IapReduce; In	nverted ind	lex; Pag			
	Module IV: Mining Clustering of social n overlapping communi	etwork graphs; Direc	t discovery o	of communiti						
	Introduction to Hado	Module V: Hadoop Ecosystem [L-3] Introduction to Hadoop ecosystem technologies; Serialization- AVRO; Coordination- Zookeeper; Databases-HBase, Hive; Scripting language-Pig; Streaming- Flink, Storm.								
	Apache Pig - Introduc and complex types, P Hive- Hive modules, QL queries, Hive QL	ule VI: Apache Pig and Apache Hive [L-9; T-4] he Pig - Introduction, Parallel processing using Pig, Pig architecture, Grunt, Pig data model: scalar omplex types, Pig Latin: input and output, Relational operators, User defined functions; Apache - Hive modules, Data types and file formats, Hive QL data definition, Data manipulation, Hive ueries, Hive QL views: reduce query complexity, Hive scripts, Hive QL indexes: create- show- Aggregate functions; Bucketing Vs Partitioning.								
	Module VII: Importing and Handling Relational Data in Hadoop using Sqoop [L-5; T-2] Relational database management in Hadoop- Bidirectional data transfer between Hadoop and external database; Import data- transfer an entire table, import subset data, use different file format, incrementally importing new data, preserving the value; Export transfer data from Hadoop- update the data, update at the same time, export subset of columns; Hadoop ecosystem integration- import data to Hive, using partitioned Hive tables, replace special delimiters.									
					,	1	i cuutu			

	Multiplication in CUDA; CUDA memory model; Shared memory matrix multiplication; Additional CUDA API features; Writing Spark application in Scala, Python, R, Java and execution.
	Module IX: Spark SQL, GraphX, and Spark Streaming [L-3; T-1] SQL context; Importing and saving data using SQL; GraphX overview; Overview on Spark streaming including errors and recovery; Streaming source; Streaming live data with Spark.
	Total Contact Hours: (L=42, T=14) = 56
Textbooks,	Textbooks:
and/or	5. J. Lescovek, A. Rajaraman, J. Ullman, <i>Mining of Massive Datasets</i> , Stanford Press, 2011.
reference	6. T. White, Hadoop: The Definitive Guide, O'Reilly, 2015.
material	7. M. Guller, Big Data Analytics with Spark, Apress, 2015.
	8. A. Gates, D. Dai, Programming Pig Data Flow scripting with Hadoop, O'Reilly Media, 2017.
	9. E. Capriolo, D. Wampler, J. Rutherglen, <i>Programming Hive</i> , O'Reilly Media, 2012.

EC9022: Big Data Computing [Mapping the Course Outcomes (COs) to the Programme Outcomes (POs) and Programme Specific Outcomes (PSOs)]

CO	Statement			Program	n Outcom	es	
СО	Statement		PO2	PO3	PSO1	PSO2	PSO3
CO1	Understand the Hadoop Framework and Ecosystem	3	3	3	2	2	2
CO2	Explain and Analyze the Big Data using MapReduce programming in both Hadoop and Spark Framework.	3	1	2	3	1	2
CO3	Demonstrate Spark programming with different programming languages.	3	1	3	3	3	3
CO4	Identify the most suitable machine learning algorithm for handling massive data.	3	2	2	3	2	3
CO5	Mine social network graphs using MapReduce	3	1	2	3	1	2
CO6	Implement and Evaluate the data manipulation procedures using Pig, Hive and Sqoop.	3	1	3	3	3	3
	Average	3	1.5	2.5	2.83	2	2.5

	Department	t of Electronics and (Communica	tion Engine	ering		
		Program Core		Total conta	ct hours: 56		
Course Code	Title of the course	(PCR) / Electives (PEL)/OEL	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9023	Internet of Things (IoT)	PEL	3	1	0	4	4
Introduction	ronics (ECC01), n to Computing (CSC01)	Course Assessmen assessment (MA) a Assignments, Quiz Examination	nd end asses c/class test, N	ssment (EA)) Iid-semester	:		
Course Outcomes	• CO2: Analyze e	nd the concept of IoT electronic systems and ta analysis techniques	systems I IoT archited				
Topics Covered	Module I. Introduc	tion to IoT of IoT, Applications				[L-1]	
	Condition Module III. Data Co Data con MQTT, 4G, 5G Module IV. IoT Syst Introduc Arduino	al physical building b ning elements and Dat ommunication mmunication schemes HTTP, Sensor Netwo	a acquisition , Basics of N rks, Intranet, oard and Au ramming, Int on using Ard	l blocks, Dat letworking, (Internet, NF rduino prog egration of S luino board,	a processing u Communicatio FC, Bluetooth, ramming Gensors and Ad Arduino comm	Inits. [L-4; on Protocol Zigbee, W [L-8; ctuators wi nunication	nal T-2] s, 'ifi, T-2]
	of Sensor	tion to Raspberry Pi, I	Raspberry Pi	OS and Pyt	hon programn	ning, Integ	T-2]
	Raspberr	rs and Actuators with and Raspberry Pi, Inte y Pi, Data communica	egrated Sens	or Network,	Data commun	ication usi	ration ng
	Module VI. Data pro Introduct	and Raspberry Pi, Inter- ry Pi, Data communication	egrated Sens ation using R IoT, Introdu	or Network, Caspberry Pi	Data commun -integrated-co ud Computing	ication usi imputer sys [L-8; , Sensor-C	ration ng tem. T-2]
	Module VI. Data pr Introduct Introduct Module VII. IoT ap Smart H	and Raspberry Pi, Inter y Pi, Data communica ocessing tion to SDN, SDN for tion to Fog Computing	egrated Sens ation using R IoT, Introdu g, Introduction Studies Connected ve	or Network, easpberry Pi ection to Clou on to Edge C hicles, Smar	Data commun -integrated-co ad Computing omputing, Da t Grid, Industr	ication usi imputer sys [L-8; , Sensor-C ta analysis [L-8;	ration ng tem. T-2] loud,
	Module VI. Data pr Introduct Introduct Module VII. IoT ap Smart H Smart-a Module VIII. IoT ar	and Raspberry Pi, Intery Pi, Data communication to SDN, SDN for tion to Fog Computing plications and Case S formes, Smart Cities, C griculture, Tele-medic	egrated Sens ation using R IoT, Introdu g, Introductio Studies Connected ve eine, Body ac	or Network, easpberry Pi action to Clou on to Edge C hicles, Smar etivity monit	Data commun -integrated-co ad Computing omputing, Da t Grid, Industr	ication usi imputer sys [L-8; , Sensor-C ta analysis [L-8; rial IoT,	ration ng tem. T-2] loud,

Text Books,	Test Books:
and/or	1. E. A. Lee, S. A. Seshia, Introduction to Embedded Systems - a Cyber Physical Systems
reference	Approach, MIT Press; Second edition, 2019
material	2. D. Hanes, G. Salgueiro, P. Grossetete, R. Barton, J. Henry, <i>IoT fundamentals: Networking technologies, protocols, and use cases for the internet of things.</i> Pearson Education; First edition, 2017
	 Shriram K Vasudevan; Abhishek S Nagarajan; RMD Sundaram, <i>Internet of Things</i>, 2nd Edition, Wiley, New Delhi, 2020.
	4. S. Mishra, A. Mukherjee, A. Roy, <i>Introduction to IoT</i> , 1 st Ed., Cambridge University, UK, 2021.
	5. A. Bahga and V. Madisetti. <i>Internet of Things: A hands-on approach</i> . Orient Blackswan Private Limited; First edition, 2015
	4. B. A. Forouzan, Data Communications and Networking, McGraw Hill Education; 4th edition,
	2017
	Reference books:
	1. S. Monk, <i>Programming Arduino: getting started with sketches</i> . McGraw-Hill Education, 2nd edition, 2016
	2. F. Brown, Python: the complete reference, McGraw Hill Education; 4th edition, 2018
	3. E. Upton, and G. Halfacree. Raspberry Pi user guide. Wiley, 1st edition, 2012
	4. Research articles

EC9023: Internet of Things (IoT) (Elective) [Mapping between course outcomes (COs) and program outcomes (POs)]

СО	Statement	Program Outcomes								
co	PO1		PO2	PO3	PSO 1	PSO 2	PSO 3			
CO 1	Understand the concept of IoT systems	2	3	1	2	1	3			
CO 2	Analyze electronic systems and IoT architecture	3	3	2	2	1	3			
CO 3	Apply data analysis techniques in IoT	2	3	3	2	1	1			
CO 4	Analyze case studies	3	3	3	1	1	3			
	Average	2.5	3	2.25	1.75	1	2.5			

	Departr	nent of Electronics and (Communica	tion Engine	ering				
Course	Title of the course	Program Core	Total Nu	mber of con	tact hours: 5	6	Credit		
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours			
EC9024	Virtual Reality ar Augmented Reali		3	1	0	4	4		
Structures a	es: g Mathematics, Data and Algorithms, als of Image Processing After the co • CO 1: Exp • CO 2: App • CO 3: Lean	Course Assessment assessment (MA) a Assignments, Quiz Examination ompletion of the course the lain basic concepts of comput rn programming using mod	and end asses z/class test, M e student wil aputer graphi er graphics/A	ssment (EA) Mid-semeste I be able to cs/ AR/ VR AR to build a): r Examination and process th	n and End S ne 2D/3D m	emester		
Topics Covered	Module I:	elop AR/VR application Introduction to Augment future of AR, Applicatio Coordinate Systems.	•		•		nations,		
	Module II:	Introduction to Augment	duction to Augmented Reality - Part 2: Projections, Image formation ir ble camera, camera calibration, camera calibration techniques, camera						
	Module III:	Classification of Trackin Tracking, Optical Tracking	se Estimation and Tracking: Pose Estimation; Pose Tracking in AR, assification of Tracking, Stationary Tracking Systems, Mobile Sensor-Backing, Optical Tracking, Hybrid Tracking, Marker-Based Tracking and ninished Reality, Marker less Tracking and AR. [L-8; T mputer Vision for AR: Image Processing, Computer Vision-Definition a ope, Object Detection and Tracking, Spatial Mapping, 3D Reconstruction door Tracking, OCR and Text Recognition for AR. [L-9; 7]						
	Module IV:	Scope, Object Detection							
	Module V:	3D Graphics in AR: Basi C# Developers, 3D Mode Libraries, Graphics Libra Application Performance,	el Importers/ ary Depende	loaders, 3D	Modeling Sof , Graphics De	ftware, Graj	ohics on AR		
				Total Lec	ture Hours: ((L=42, T=1	4)= 56		
Text Books and/or reference material	 Chetankur Publication Schmalstie 	nar G Shetty, <i>Augmented I</i> ns 2020. eg and Hollerer, <i>Augmente</i> India, October 2016.			-				
	Reference bool 3. Research A								

		Program Outcomes							
СО	Statement	РО 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Explain basic concepts of computer graphics/ AR/ VR	2	3	1	3	1	2		
CO 2	Apply the concepts of computer graphics/AR to build and process the 2D/3D models	2	3	1	2	2	2		
CO 3	Learn programming using modern tools to create and process 2D/3D models	2	2	2	2	1	2		
CO 4	Develop basic AR/VR application	2	2	2	2	1	2		
	Average	2	2.5	1.5	2.25	1.25	2		

EC9024: Virtual Reality and Augmented Reality [Mapping between course outcomes (COs) and program outcomes (POs)]

		of Electronics and C		-	-					
Course	Title of the course	Program Core	Total Nu	Credit						
Code		(PCR) / Electives (PEL)	Lecture Tutorial (L) (T)		Practical (P)	Total Hours				
EC9025	Network Functions Virtualization (NFV) and Software Defined Networks (SDN)	PEL	3	1	0	4	4			
Pre-requisit		Course Assessmen assessment (MA) a			,	CA), Mid-s	emester			
Computer Ne Engineering	etwork; Communication	Assignments, Quiz Examination				and End S	emester			
Course Outcomes	 CO 2: Apply vi CO 3: Recogniz 	and the concept of NF artualization concept in ze and interpret the b and analyze a complete	n modern ne basic buildin	tworking g blocks of S		7				
Topics Covered	Module I: Introdu Virtual Machine, virt centers, VM connecti	tual networks, hypervi	isor, managi		[L-5; T-2] sources, virtu	alizing	data			
	NFV: concepts and an approaches to virtuali flow, open stack, etc.									
	Module III:Software Defined Networks[L-10; T-3]SDN: background and motivation; review of networking; SDN: application, control, infrastructure layer; SDN data plane, SDN control plane and SDN application plane									
	Centralized control:	e IV: SDN Controllers [L-6; T-3] ized control: commercial versus open-source controllers; network virtualization; the open day DL) project; SDN use case examples.								
	Connecting it all toge	Module V:Virtualized Networks[L-7; T-2]Connecting it all together; building and managing virtualized network; service chaining in SDN;SDN and NFV working together.								
	Module VI:Security and Visibility[L-4; T-1]Storage virtualization; preventing data leakage; encryption in virtual network; overlay networks; network management tools; monitoring traffic between virtual switches.									
TD (1 1				Total L	ecture Hours	: (L=40, T	=14) = 54			
Textbooks, and/or reference material	10. J. Doherty, SDN 11. W. Stallings, Fo	 Textbooks: 10. J. Doherty, SDN and NFV simplified, Pearson Education, U.S., 2016. 11. W. Stallings, Foundations of Modern Networking: SDN, NFV, QoE, IoT (Internet of things) and Cloud, Pearson Education, 2015. 								
	 Reference books: 3. R. Chayapathi, S. F. Hassan, P. Shah., <i>Network functions virtualization with a touch of SDN</i>, Pearson Education, U.S., 2016. 									

		Program Outcomes							
СО	Statement	PO1	PO2	PO3	PSO 1	PSO 2	PSO 3		
CO 1	Understand the concept of NFV and SDN	3	3	3	3	2	2		
CO 2	Apply virtualization concept in modern networking	3	1	2	2	1	2		
CO 3	Recognize and interpret the basic building blocks of SDN and NFV	3	2	3	3	3	3		
CO 4	Design and analyze a complete network with SDN and NFV	3	2	3	2	3	3		
	Average	3	2	2.75	2.5	2.25	2.5		

EC9025: Network Functions virtualization (NFV) and Software Defined Networks (SDNs) [Mapping between course outcomes (Cos) and program outcomes (POs)]

POs:

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems **PO 2:** An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSOs:

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

	Departi	of Electronics and C	Communication Engineering					
Course	Title of the course		Program Core	Total Nu	mber of con	tact hours:		Credit
Code			(PCR) / Electives	Lecture	Tutorial	Practical		
			(PEL)	(L)	(T)	(P)	Hours	
EC9027	Multiphysics Anal and Modeling	ysis	PEL	3	1	0	4	4
Pre-requisite	es:		Course Assessmen				t (CA), Mid-s	emester
			assessment (MA) a					
	onics (ECC01),		Assignments, Quiz	z/class test, N	Aid-semeste	r Examinati	ion and End S	emester
	Mechanics (XEC01)	1	Examination		1111.4.			
Course Outcomes			etion of the course the nd characteristics of r					
Outcomes			antitative analysis tec			systems		
			nd modeling of multi			systems		
			te complex designs of			nd case stud	lies	
Topics Covered	Module I:	-	roduction to physica	1 1	<u> </u>		[L-1]	
Covered	Module II:	Stat Lin	aracteristics of Physicic, dynamic and quasiearity, nonlinerity, hy racteristics, response	i static chara vsteresis, tim	cteristics of e domain an	physical el d frequency	y domain	
	Module III:	Loa repr	ding effects in two port network [L6; T-2] ling effects in physical systems, Loading effect modelling, Two port esentation of physical elements and systems, Lumped parameter repr ransducer, Amplifiers, Filters.					
	Module IV:	Sou sour met	For analysis and mod arces of signal errors, a rces of noise, wide-ba hods of error measure ribution, correlation, a	Systematic a and noise, na ements, statis	rrow-band n stical averag	oise, Error es, standaro	modelling, St l deviation, G	atistical aussian
	Module V:	Bor prin circ	tem Representation, ad graph representation aciple, Lagrange equat uits, electromechanic amics, Time-varying	esentation of e s, Nonlinear	lton's			
	Module VI:	Cor relia	iability analysis of p acept of reliability, ma ability, reliability anal emes for improving re	athematical 1 lysis of phys	nodelling of ical element	s and physi		
					<u>Total</u> L	<u>ecture H</u> o	urs: (L=42, T	<u>=14)= 56</u>
Text Books and/or reference material	1. S. H. Cranda 2017		C. Karnopp, Dynami	v				
	2011	Mecl Dyna	hatronics, Dynamics o mics for Engineers, V	•		d Piezoelec	tric Systems, S	Springer,

Page 70 | 105

		Program Outcomes								
CO	Statement	PO1	PO2	PO3	PSO 1	PSO2	PSO 3			
CO 1	Understand characteristics of multiphysics systems	1	3	1	3	1	1			
CO 2	Apply quantitative analysis techniques to multiphysics systems	3	3	3	3	1	2			
CO 3	Understand modeling of multiphysics systems	2	3	3	3	1	2			
CO 4	Investigate complex designs of multiphysics systems and case studies	3	3	3	3	1	2			
	Average	2.25	3	2.5	3	1	1.75			

EC9027: Multiphysics Analysis and Modeling [Mapping between course outcomes (Cos) and program outcomes (POs)]

POs:

PO 1: An ability to independently carry out research /investigation and development work to solve practical problems **PO 2:** An ability to write and present a substantial technical report/document

PO 3: Students should be able to demonstrate a degree of mastery over the area as per the specialization of the program. The mastery should be at a level higher than the requirements in the appropriate bachelor program

PSOs:

PSO 1: Understanding mathematical modelling of communication systems and networks

PSO 2: Enhancing the knowledge of RF front end circuit design and radio propagation phenomena

PSO 3: Equip with modern computational and hardware tools for designing communication systems

		Department of El	ectronics & C	.ommunicau	on Engineering	5			
~		Program Core							
Course Code	Title of the course	(PCR) / Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit		
EC9028	C9028 Mixed PEL Design			1	0	4	4		
	Design[EC101	2], 3], <u>DSP[ECC603]</u>	semester as	sessment (MA ts, Quiz/class	ods: (Continuou A) and end asses test, Mid-semes	ssment (EA)):			
Course Outcomes	 CO1: H CO2: H CO3: C CO4: A CO5: H 	completion of the c Explain the operatio Design Analog Circu Create the Layout of Analyze a Comparat Interpret the use of S Compare Data conve	ourse, the stud n of various H uits using gm/ f a CMOS Miz for. Switched Capa	lent will be ab ligh performan ID techniques ked Signal Systematorics	nce OTAs/Opar stem. in Sampled dat	a Systems			
Topics Covered	Overview Telescopic Module II Gm over D Various de and Two st Module III Slew rate	 Module I. Introduction [L - 7; T - 2] Overview of Mixed-Signal Design flow. Design of high performance Fully Differential Opamps Telescopic cascode, Folded cascode, two-stage, Rail-to-Rail, Gain boosted OTAs/Opamps, Comparison Module II. gm over I_D Design Process [L - 4; T - 2] Gm over ID technique: Transconductor efficiency in subthreshold, moderate and strong inversions Various design plots: gm/I_D, gm/gds, f_T etc., and their use in Analog Design. Design of a CS Amplifier and Two stage Opamp using gm/I_D technique. Module III. Opamp performance Metrics: [L - 4; T - 1] Slew rate & Settling time, CMRR, PSRR, Linearity, Distortion : Gain Compression, THD, IIP3 calculation. Offset Cancellation techniques. 							
	Introduction layout, Fing	odule IV. Layout Techniques $[L - 3; T - 2]$ roduction to CMOS process, CMOS Layers, Design rule basics, DRC, LVS, Passive and Transist out, Fingering, Interdigitization. Matching components: Common centroid, Use of Dummy. Matchi or, error propagation.							
	Basic philo effect of o	Module V. Switched Capacitor Circuits $[L - 5; T - 1]$ Basic philosophy of Switched capacitor circuits, design of switched-capacitor amplifiers and integrato effect of opamp finite gain, bandwidth and offset, circuit techniques for reducing effects of opar imperfections, switches and charge injection and clock feed-through effects.							
	Operation of	Module VI. Sample and Hold $[L - 4; T - 1]$ Operation of sample and holds circuits and theirs non-idealities. Comparators: OPAMP based, Str Arm Regenerative Latch, Latch dynamics, Offset reduction.							
	Error, SINA	als of data converter		n to data conve					
		AD, ENOB, SFDR, mode converters, g, folding flash, SA	hybrid and se	egmented con	verters. Nyquis	st rate A/D co	onverters (Flas		

	frequency detector, Loop filters, Charge Pump PLLs, non-ideal effects in PLLs.
	Total Lecture Hours: (L=42, T=14) =56
Text	Textbooks:
Books,	1. Behzad Razavi, "Design of Analog CMOS Integrated Circuits", McGraw Hill, 2nd Ed. 2017
and/or	2. Tony Chan Carusone; David Johns; Kenneth Martin, "Analog Integrated Circuit Design", Wiley,
Reference	2nd Ed. 2013.
materials	3. Behzad Razavi, "Principles of Data Conversion System Design", Wiley-IEEE Press, 1994
	4. Adel Sedra, Kenneth Smith Tony Chan Carusone, Vincent Gaudet, "Microelectronic Circuits",
	Oxford ; 8th Ed.; 2020
	Reference Books/Materials:
	1. R.Gregorian, "Introduction to CMOS Opamps and comparators", Wiley, 1999
	2. Rudy J. Van De Plassche, "CMOS Integrated Analog-to-Digital and Digital-to-Analog Converters",
	Springer, 2nd Ed. 2003.
	3. Nagendra Krishnapura, IIT Madras, "Analog Systems Design"
	https://www.youtube.com/watch?v=4PxwecUfcHs&list=PLtTAxS17nYhJnIp5_P8sm7iAQIN
	11XmOe
	https://www.youtube.com/watch?v=eLTpf_5di2o&list=PLtTAxS17nYhLs4rJGpK2aBhBgCV
	tavGNh
	4. Ali Hajimiri, Caltech, "New Analog Circuit Design",
	https://www.youtube.com/watch?v=403CnTftB4M&list=PLc7Gz02Znph-c2-
	ssFpRrzYwbzplXfXUT

EC9028: Mixed Signal IC Design [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]

СО	Statement	Program Outcomes							
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3		
CO1	Explain the operation of various High performance OTAs/Opamps.	2	1	2	3	1	1		
CO2	Design Analog Circuits using gm/ID techniques.	2	3	1	3	2	2		
CO3	Create the Layout of a CMOS Mixed Signal System.	3	2	1	2	2	2		
CO4	Analyze a Comparator.	3	1	1	3	2	1		
CO5	Interpret the use of Switched Capacitor Circuits in Sampled data Systems	3	1	1	2	1	2		
CO6	Compare Data converter architectures based on Area/Power/Speed	2	1	3	3	1	1		
	Average		1.5	1.5	2.66	1.5	1.5		

Page 73 | 105

		Program		Total conta	ct hours : 56							
Course Code	Title of the course	Core (PCR) / Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit					
EC9029	Architectural Design of Integrated Circuits	PEL	3	1	0	4	4					
Pre-requisi		~ ~			ods: (Continuo							
Dış	gital IC Design, D	SP			(MA) and end test, Mid-semes							
				ter Examinatio		ster Examina	tion and					
Course	After the comp	letion of the c										
Outcomes	• CO1: Map a	ny algorithm t	o VLSI Archi	tecture.								
					mum one based	l on applicati	on					
		ze and employ be CORDIC b	-									
			•		teps to meet the	e timing cons	straints					
Topics	Module IX. In			<u></u>		e uning eons						
Covered	VLSI Design fl											
	Implementation strategies of Digital VLSI Design, One bit incrementer, four bit incrementer, N-											
	bit incrementer, ones' complement, two's complement, sum of N –natural numbers, prioritization greatest common divisor (GCD).											
	greatest common divisor (GCD).											
	Module X. Mapping Algorithms to Architectures $[L - 6, L - 2]$ Mapping algorithms into Architectures: Signal flow graph, data dependences, datapath synthesis, control structures, critical path and worst case timing analysis, concept of hierarchical system design;											
	design;	s, critical path	h and worst c	ase timing an	alysis, concept							
	design;	s, critical path Adder, Subtra res: Single bit	h and worst c actor Architec addition, Car	ase timing an etures: [L – 4 ry – Ripple ad	alysis, concept 4, L – 2] der, Carry – Sk	of hierarchi	cal syster rry-Look-					
	design; Module XI. A Adder architectu	s, critical path Adder, Subtra res: Single bit ry –Select add Iultiplier Arc on, Array mul	h and worst c addition, Carri ler, Carry – Inc hitectures [L ltiplication, sig	ase timing an ctures: $[L - 4$ ry – Ripple ad crement adder – 5, L – 2] gned multi-ope	alysis, concept 4, L – 2] der, Carry – Sk , Tree adder. Su erand addition,	of hierarchi sip adder, Ca ubtractor arch	cal syster rry-Look- nitectures.					
	design; Module XI. A Adder architectu ahead adder, Car Module XII. M Tree multiplicati	s, critical path Adder, Subtra res: Single bit ry –Select add fultiplier Arc on, Array mul ronous shift an ORDIC Arch d, rotation and n, implementa	h and worst c addition, Carl ler, Carry – Ind hitectures [L hiplication, signd add multipl itecture [L – – vectoring mon tions: word-se	ase timing an etures: $[L - 4$ ry – Ripple ad crement adder – 5, L – 2] gned multi-opt ier, Booth alg 5, L – 1] ode, convergenerial and pipel	alysis, concept 4, L – 2] der, Carry – Sk , Tree adder. Su erand addition, orithm. ace, precision a ined, New tech	of hierarchi ip adder, Cau ibtractor arch squaring, sh nd range, sca	cal syster rry-Look- nitectures. ift and ad					
	design; Module XI. A Adder architectu ahead adder, Car Module XII. M Tree multiplicati multiplier, synch Module XIII.C CORDIC method and compensatio	Adder, Subtra res: Single bit ry –Select add Iultiplier Arc on, Array mul ronous shift at ORDIC Arch d, rotation and n, implementa ng (MAR), Bin Timing Ana nic timing anal puts, sequenti	h and worst c addition, Carri ler, Carry – Ind hitectures [L ltiplication, signd add multipl itecture [L – $-$ l vectoring mo- titions: word-se hary to Bipola lysis [L – 6, L lysis, System (al machine, cl	ase timing an etures: $[L - 4$ ry – Ripple ad crement adder – 5, L – 2] gned multi-opdier, Booth algo 5, L – 1] ode, convergent erial and pipel r Recoding (B L - 2] Considerations	alysis, concept 4, L – 2] der, Carry – Sk , Tree adder. Su erand addition, orithm. ace, precision a ined, New tech BR). s - edge triggere	of hierarchi cip adder, Cau libtractor arch squaring, sh nd range, sca niques – Mic	cal syster rry-Look- nitectures. ift and ad aling facto ero rotatio v, handlin					
	design; Module XI. A Adder architectu ahead adder, Car Module XII. M Tree multiplicati multiplier, synch Module XIII.C CORDIC method and compensation to Angel Recodin Module XIV. Static and Dynama asynchronous in	s, critical path Adder, Subtra res: Single bit ry –Select add fultiplier Arc on, Array mul ronous shift an ORDIC Arch d, rotation and n, implementa ng (MAR), Bin Timing Ana nic timing anal puts, sequenti- gh, Re-timinga	h and worst c addition, Carl ler, Carry – Ind hitectures [L hiplication, sign ad add multipl itecture [L – 4 l vectoring mo- tions: word-se hary to Bipola lysis, System (C al machine, cl s. al Design of D	ase timing an etures: $[L - 4$ ry - Ripple ad crement adder - 5, L - 2] gned multi-optier, Booth alg 5, L - 1] ode, convergenerial and pipel r Recoding (B L - 2] Considerations lock cycle tim	alysis, concept 4, $L - 2$] der, Carry – Sk , Tree adder. Su erand addition, orithm. ace, precision a ined, New tech BR). 5 - edge triggerent he, Violation – L - 4, L - 2]	of hierarchi cip adder, Cau ubtractor arch squaring, sh nd range, sca niques – Mic ed, clock skew maximum p	cal syster rry-Look- nitectures. ift and ad- aling facto cro rotatio					

	system design, ASIC (application specific integrated circuits) and ASISP (application specific instruction set processors) design.
	Total Lecture Hours (L=42, T=14)=56
Text	Text Books:
Books,	5. M. D. Ercegovac and T. Lang, "Digital Arithmetic", Morgan Koffman, 2003
and/or	6. K. W. Ulrich, "Advanced Arithmetic for the Digital Computer", Springer, 2002
Reference	
materials	Reference Books/Materials:
	5. B. Parhami, "Computer Arithmetic: Algorithms and Hardware Designs", Oxford, 2009

EC 9029: Architectural Design of ICs [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]

CO	Statement	Program Outcomes							
CO	Statement		PO2	PO3	PSO1	PSO2	PSO3		
CO1	Map any algorithm to VLSI Architecture.	2	1	2	3	1	1		
CO2	Compare Adder architectures and select the optimum one based on application	2	3	1	3	2	2		
CO3	Analyze and employ Multiplier architectures	2	3	1	3	2	2		
CO4	Describe CORDIC architecture with any applications.	3	1	1	3	2	1		
CO5	Illustrate the timing issues and adopt necessary steps to meet the timing constraints.	3	1	1	2	1	2		
	Average	2.4	1.8	1.2	2.8	1.6	1.6		

		Departm	ent of Electronics and	l Communic	ation Engine	eering		
Course			Program Core		Total conta	ct hours: 57		
Code	Title	of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9030	RF IC D	esign	PEL	3	1	0	4	4
Pro-roou	isitas / C	o-requisites:	Course Assessment	methods: (C	Continuous As	ssessment (CA), Mid-ser	nester
Analog IC	Design (l		assessment (MA) an					
Electromag	gnetic	theory and (ECC 403)	Assignments, Qui	iz/class test, l	Mid-semester Examination		and End S	emester
Course			he course is to give the	student fun	damontal kno	wledge on Re	dio Freque	nev (PF)
Objective	int		design. The course of					
Course Outcomes	Af		gh the course, student v	vill be able to)			
	CO	-	various architectures o				eceivers.	
		•	and design basic RF bu	•				
	CO) 3: Define balling IIP3	asic RF measurements	parameters s	uch as S-para	ameters, sensit	ivity, noise	figure,
	CO		te the design technique	s of VCO, L	NA as well a	s other front-e	nd circuits	
Covered/ Syllabus	cir Me RF fre Y	cuit analysis tec odule-II: Semic diodes, MOS tr quency behavio Parameters – S	RF Design, passive of hniques at radio freque conductor radio freque ransistor, determination ur of basic amplifier.R Parameters – Unders transistors, matching	encies. ency component of model part F Transistor tanding RF	nents [L – 8 rameters, par Materials – T Transistor D	; T – 3] asitics of MOS The Transistor ata Sheets; BS	transistors Equivalent	s and high Circuit -
			e and non-linearity. [] representation of non-li		modulation p	products and in	ntercept po	ints
	Re	odule-IV: Filter sonator and filte filters a coupled	r Design [L – 4; T – 1] er configurations, realiz l line filter.] zation of filte	r for specific	transfer funct	ion, imple	mentation
	Sta top LN	Module V: RF Transistor Amplifier $[L - 8; T - 3]$ Stability consideration, constant, gain and noise figure circles. Low Noise Amplifiers: SNR, LNA topologies, power constrained CMOS LNA design, low-current CMOS inverter LNAs, low-voltage LNA topologies, differential LNA design methodology, process variation in tuned LNAs, impact of temperature variation in tuned LNAs, low-noise bias networks for LNAs, MOSFET layout of LNA.						
	Ba	sic design conc	fixers $[L - 5; T - 1]$ cepts, single end diode mixers, conversion los	-	le balanced a	and double ba	llanced dic	de mixer
	Ba me	sic Principles,	Oscillators [L – 6; T - Phase Noise, negative quency scaling of C	e resistance				-
	-							

P a g e 76 | 105

	Class A, AB, B, C, D, E and F amplifiers, modulation of power amplifiers, linearity consideration, Layout in CMOS. Total Contact Hours: (L=43, T=14) = 57
	10tar Contact Hours: (L=43, 1=14) = 57
	Text Books: [1] Behzad Razavi, RF Microelectronics Prentice Hall of India, 2001 [2] Cam Nguyen, Radio Frequency Integrated Circuit Engineering, John Wiley and Sons, New York 2015 [3] Sorin Voinigescu, High Frequency Integrated Circuits, Cambridge Univeity Press,UK, 2013
Text Books, and/or Reference material	Reference Books: [1] Thomas H. Lee, The Design of CMOS Radio Frequency Integrated Circuits, Cambridge University Press.
Internal	 [2] R Ludwig and P Bretchko, <i>RF Circuit Design: Theory and Application</i>, Pearson Education, New Delhi [3] Bosco Leung, "<i>VLSI for Wireless Communication</i>", Springer (2011). [4]Ivan Chee-Hong Lai, Minoru Fujishima, <i>Design and Modeling of Millimeter-wave CMOS Circuits for Wireless Transceivers</i>, Springer Netherlands,2008

EC9030: RF IC Design (Elective) [Mapping between course outcomes (COs) and program outcomes (POs)]

	O Statement			Program	n Outcon	nes	
CO			PO 2	PO 3	PSO 1	PSO 2	PSO 3
CO 1	Analyze various architectures of today's digital radio transmitters and receivers	2	1	2	2	1	1
CO 2	Analyze and design basic RF building- blocks in CMOS technology	3	1	3	3	3	1
CO 3	Define basic RF measurements parameters such as S-parameters, sensitivity, noise figure, IIP3	3	2	3	2	2	1
CO 4	Define basic RF measurements parameters such as S-parameters, sensitivity, noise figure, IIP3	3	2	3	2	2	1
CO 5	CO#4:Assimilat the design techniques VCO, LNA as well as other front end circuits	2	1	2	3	3	2
	Average			2.50	2.67	2.50	1.33

	Departme	nt of Electronics and	Communica	tion Engine	ering		
Course		Program Core		Total conta	ct hours: 56		
Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9031	SoC Design	PEL	3	1	0	4	4
language (dware description Verilog or VHDL) from	Course Assessment assessment (MA) an Assignments, Quiz/o	nd end assess	ment (EA)):		•	
VLSI Desi Course Objective Course	based SoCs from I FPGA hardware us	Examination produce students who high level functional sping standard hardware pletion of this course, s	pecifications description a	to design, in and software	nplementation programming	and testin languages	ig on real
Outcomes After going through the course, student wil be able to	• CO1: Knowledg • 0 4 • 0 4 • 0 4 • 0 4 • 1 • CO2: Intellecture • 4 • CO3: Practical	ge and understanding of Arm processor architect Capture the design of A anguage Low-level software des levelopment	f: tures and Arn rm-based So ign for Arm- se between d lementation r nding high-le	n-based SoC Cs in a stand based SoCs a ifferent techr esults (e.g., s vel design ar	s ard hardware and high-level niques for digi speed, area, po ad capture.	description application tal system	n design
Topics Covered/ Syllabus	Introduction to de power issues. Module II. Ro Characteristics of limitations, inter- coding schemes (Module III. Sys Emerging SoC tr for testability (DI standard for SoC Module IV. Im Different low pow of low-voltage C other related met optimization.	portance of Power an wer design methodolog MOS circuits, multi-th hodologies, coding fo	Contempora Contempora rosstalk min citance and in presence c tform based and reusabilit anism (TAM d Low Powe ies, physics of reshold CMC r low power	M) era, inclue ry SoC Desi imization, de its effect on if crosstalk, in Design [L – y, multiproce b), concepts of er SoC Desig of power dissons OS (MTCMO	gn [L – 2, T - elay in long w wire delay, nterconnect in - 2, T -0] essor SoC plat of core based t m Methodolo ipation in CM PS), variable th	0] ire and per crosstalk a ductance. tform desig est and IEI gy [L – 2, IOS, design hreshold C	formance woidance gn, design EE P1500 T -0] and test MOS and
	Introduction to P	2M based SoC: [L – 2 , rogrammable SoCs; Wesign Productivity Gap	hy the SoC D	-			•

Page 78 | 105

What Is Inside an SoC?, Example Arm-based SoC, Advantages of SoCs, Limitations of SoCs, SoC v Microcontroller v Processor, SoC Design Flow, SoC Example: NVIDIA Tegra 2, SoC Example: Apple SoC Families.

Module VI. The Arm Cortex-M0 Processor Architecture: Part 1[L – 3, T -1]

Building a System on a Chip, Arm Holdings, What Is Arm Architecture?, Example Design of an Arm-based SoC, Arm Processor Families, Arm Cortex-M Series Family, Cortex-M0 Processor, Arm Processor v Arm Architectures, Cortex-M0 Overview, Cortex-M0 Block Diagram, Cortex-M0 Three-stage Pipeline, Cortex-M0 Block Diagram, Cortex-M0 Registers, Cortex-M0 LR, Cortex-M0 PSRs, Cortex-M0 Memory Map, Cortex-M0 Executable Memory Space, Cortex-M0 Device Memory Space, Cortex-M0 Private Peripheral Bus, Cortex-M0 Reserved Memory Space, Cortex-M0 Executable Memory Map Example, Cortex-M0 Endianness

Module VII. The ARM Cortex-M0 Processor Architecture part-2 [L - 3, T -1]

Building a System on a Chip, Thumb Instruction Set, Thumb-2 Instruction Set, Cortex-M0 Instruction Set, Cortex-M0: Generic Format of Instructions, Cortex-M0 Instruction Set, Register Access: The Move Instruction, Memory Access: The LOAD Instruction, Memory Access: LOAD, Memory Access: The STORE Instruction, Memory Access: STORE, Multiple Data Access, Stack Access: PUSH and POP, Arithmetic ADD, Arithmetic SUB, MUL, Arithmetic CMP, Logic Operation, Arithmetic Shift Operation, Logical Shift Operation, Rotate Operation, Reverse Ordering Operation, Extend Operation, Program Flow Control, Suffixes for Conditional Branch (B <cond>), Conditional Branch Example, Memory Barrier Instructions, Exception-Related Instructions, Other Instructions, Sleep Mode Related Instructions, Low-Power Requirements, Cortex-M0 Low Power Features, Cortex-M0 Sleep Mode, Sleep-on-Exit Feature, How to Enable Sleep Features, Processor Wakeup Conditions, Wakeup Interrupt Controller, Enter and Exit Deep Sleep Mode, Developing Low-Power Applications

Module VIII. The AMBA3 AHB Lite Bus Architecture [L – 3, T -1]

Building a System on a Chip, What Is a Bus?, Bus Terminology, Bus Operation in General, A Typical Bus Operation Example, Communication Architecture Standards, Arm AMBA System Bus, Arm AMBA Bus Families, AMBA 3 AHB-Lite Bus, AHB-Lite Bus Block Diagram, AHB-Lite Master Interface, AHB-Lite Slave Interface, Address Decoder, Slave Multiplexor, Hardware Implementation, AHB-Lite Operation Principles, AHB-Lite Bus Timing, Basic Read Transfer, Basic Write Transfer, Read Transfer with Wait State.

Module IX. ARM AHB Bus Peripherals: [L – 2, T -1]

Design and Implementation of an AHB VGA Peripheral: Building a System on a Chip, VGA Overview, How VGA Signals Work, VGA Timing, AHB VGA Peripheral, Additional Design Requirement, AHB VGA Peripheral Hardware Architecture, VGA Interface, VGA Image Buffer, Text Console, AHB Interface, Memory Space.

Module X. Design and Implementation of an AHB UART peripheral [L – 2, T -1]

Building a System on a Chip (SoC), Serial Communication, Types of Serial Communication, Parallel Communication, Serial v Parallel Communication, UART Overview, UART Protocol, Character-Encoding Scheme, ASCII Encoded Characters, AHB UART Peripheral, Baud Rate Generator, UART Transmitter, UART Receiver, First In First Out (FIFO), Why Do We Need an FIFO in UART?, First In First Out (FIFO), FIFO Implementation, Memory Space

Module XI. Design and Implementation of an AHB timer, a GPIO peripheral, and a 7-segment display peripheral [L - 2, T - 1]

Building a System on a Chip (SoC), Timer Overview, Standard Architecture of Hardware Timers, Timer Operation Modes, Timer Operation Mode, Timer Operation Modes, Hardware Module Overview, AHB Timer, Timer Registers, Hardware Module Overview, GPIO Overview, AHB GPIO, GPIO Registers, Hardware Module Overview, 7-Segment Display Overview, AHB 7-Segment Display, 7-Segment Display Registers, Memory Space.

Module XII. Design and Implementation of Interrupt Mechanism [L – 2, T -1]

Building a System on a Chip (SoC), Polling v Interrupts, Exception and Interruption, Interrupt Preemption, Cortex-M0 Block Diagram, Armv6-M Exception Model, Cortex-M0 Interrupt Controller, NVIC Registers, NVIC Registers, Building a System on a Chip (SoC), The Interrupt Mechanism Process, Interrupt Implementation for Timer, Interrupt Implementation for UART, Connect Interrupts to Processor, Enable Interrupts in Software, Entering an Exception Handler, Exiting an Exception Handler.

Module XIII. Software Programming of ARM SoC: [L – 2, T -1]

Programming an SoC Using C Language; Building a System on a Chip (SoC), C and Assembly Language Review, Typical Program-Generation Flow, Program-Generation Flow with Arm Tools, Program Image, Program Image in Global Memory, Program Data Types, Data Qualifiers in C Language, How Is Data Stored in RAM, Example of Data Storage, Define Interrupt Vector in C, Define Stack and Heap, Accessing Peripherals in C, Calling a C Function from Assembly, Calling an Assembly Function from C, Embedded Assembly

Module XIV. ARM CMSIS and Software Drivers [L – 2, T -1]

Building a System on a Chip (SoC), What Is CMSIS?, What Is Standardized in CMSIS?, CMSIS Components, Access NVIC Using CMSIS, Access Special Registers Using CMSIS, Execute Special Instructions Using CMSIS, Access System Using CMSIS, Benefits of CMSIS, Device Driver, AHB Peripheral Drivers, Using Pointer to Access Peripherals, Define Data Structure for Peripherals, Functions Reuse Between Multiple Units, Define AHB Peripherals, Examples of Simple Functions

Module XV. Application Programming Interface (API) and Final Application: The SNAKE Game [L - 3, T -1]

Building a System on a Chip (SoC), API Overview, Develop a Simple API, Hardware-Dependent Functions, Call-Back Functions, Retargeting, Retargeting Examples, Example of API Functions, Game Application: Snake, More Game Applications, Cortex-M0 Low-Power Features Review, Cortex-M0 Sleep Mode, System Control Register, Sleep-on-Exit, Polling v Interrupts, Developing Low-Power Applications.

Module XVI. ARM DS-5 Development Studio [L -3, T -1]

Arm DS-5 Development Studio Overview, ARM DS-5 Code, ARM DS-5 Build, ARM DS-5 Debug, Debug Hardware, Virtual Debug Interface – VSTREAM, ARM DS-5 Analyzer – Streamline, ARM DS-5 Analyzer – Energy Probe, ARM DS-5 Simulation, ARM DS-5 Device Configuration Database

Module XVII. ARM v7-A/R ISA [L - 2, T -1]

Why do u need to know Assembler?, ARM assembler file syntax, Single/ Double register data transfer, Addressing Memory, Pre- and Post -Indexed Addressing, Multiple Register Data Transfer, Data Processing Instructions, Shift/Rotate Operations, Instructions for loading constants, Multiply/Divide, Bit Manipulation Instructions, Byte Reversal, Flow control, Branch instructions, Interworking, Compare and Branch if zero, Conditional Instructions, If Then, Coprocessor instructions, PSR access, DSP instructions overview, Saturated Maths and CLZ, Saturation, SIMD

Module XVIII. ARM Cortex-A9 Processor [L – 2, T -1]

Cortex- A9, Cortex-A9 MP Core, Cortex-A9 MPE Configuration, Cortex-A9 Media Processing Engine, Register Renaming, Virtual Flags Registers, Small Loop Mode, Program Flow Prediction, Performance Monitoring Unit (PMU), Cortex A9 supports ARMv7-A Architecture, caches, Data Cache, Memory Management Unit, ARM v7 Architecture Effects.

Module XIX. AMBA AXI4 Bus Architecture [L – 2, T -1]

What is a Bus, Bus Types, Bus Terminology, Bus Operation, Communication Architecture Standards, ARM AMBA System Bus, AMBA 3 AXI Interface, AMBA 4 Specifications, AXI Components and Topology, Transcation Channels, Basic Signals, Clock and Reset, Channel Timing Example, Relationship between the Channels.

	Total Contact Hours: (L=42, T=14)= 56
Text Books, and/or	Text Books: [1] Steve B. Furber, ARM System-on-Chip Architecture. [2] William Hohl, ARM Assembly Language: Fundamentals and Techniques. [3] Joseph Yiu, The Definitive Guide to the ARM Cortex-M0.
Reference material	Reference Books/materials: [1] Cortex-A Series Programmer's Guide for ARMv7-A by Arm [2] http://infocenter.arm.com/help/topic/com.arm.doc.den0013d/index.html [3] Louise H Crockett, Ross A Elliot, Martin A Enderwitz, The Zynq Book Tutorials for Zybo and ZedBoard

EC9031: SoC Design (Elective)

[Mapping between course outcomes (Cos) and program outcomes (POs)]

60	Statement		Program Outcomes						
CO	Statement	PO1	PO2	PO3	PSO 1	PSO 2	PSO 3		
CO 1	Knowledge and understanding of: Arm processor architectures and Arm-based SoCs Capture the design of Arm-based SoCs in a standard hardware description language, Low-level software design for Arm-based SoCs and high-level application development	2	3	2	3	2	3		
CO 2	Intellectual: Ability to use and choose between different techniques for digital system design and capture; Ability to evaluate implementation results (e.g. speed, area, power) and correlate them with the corresponding high level design and capture;	3	3	3	3	2	3		
CO 3	Practical: Ability to use a commercial tool to develop Armbased SoCs	3	3	3	3	3	3		
	Average		3	2.66	2.5	2.33	3		

	Departmer	nt of Electronics and	Communica	tion Engine	ering							
Course		Program Core	Total	contact hour	rs: 70 (L-42 +	P-28)						
Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit					
EC9032*	FPGA based Design	PEL	3	0	2	5	4					
	tes/Co-requisites: uits and Systems	Course Assessment Assessment (MA:2: Continuous Assessi	5%) and End	-Term Asses	sment (EA:60	%))						
Course	•CO1: Learn logic	synthesis techniques	– two level a	and multilevel	l synthesis.							
Outcomes	• CO2: Be able to	 CO1: Learn logic synthesis techniques – two level and multilevel synthesis. CO2: Be able to design systems using FPGAs and CPLDs. 										
		ential machine design										
	-	sign systems for low p	•									
Topics		rs: Lecture – 42; Pra	-									
Covered	of two-level synthe Module-II: (L – 10 Programmable Log Logic (PAL), PAI implementation, Ty Module-III: (L – 1 Programmable Gate Arrays; Look up ta level synthesis tech Generalized FPGA simulation – introd Module-IV: (L – 0 Sequential Circuit I table, State assignt	mentals: Two level sy sis, introduction to mu)) ic Devices: Programm L vs. PROM, Fan- /pical PAL chips; Con 0) e Arrays: Gate Array c /bles (LUT) Configura niques – Factoring and Architecture; Introduc uction to HDL, synthe	alti-level syn nable Logic A in expansion pplex Progra concept, Mas able logic bl f Functional o ction to CAD sis, post syn fachines, Mo ext-state and	thesis. Array (PLA) and feature, A mmable Logi k programma ocks (CLB), decompositio Tools for FP thesis simulat ore and Meal output expr	architecture; F rchitecture fo c Devices (CF oble and Field logic design to n, Shannon's I GA based desi ion, interfacir y Machines; S essions, state	Programma r sequenti PLD). Programm using LUT Expansion ign, design ng external State diagra minimizati	ble Array al circuit able Gate 's; Multi- Theorem; entry and devices.					
	Module-V: $(L - 02)$ Advanced features Analog interface.	of embedded system. Module-V: (L – 02) Advanced features of modern FPGAs: Block RAMs, Embedded processor, Communication ports Analog interface. Module-VI: (L – 06)										
	- Logic State Analy	re Debugging platforn /zer and its use; Conce lator, Break-points and	pt of Hardwa	re emulation	-simulation v	vs. Emulation	on, FPGA					
Page 82	adder/Subtractor, d user constraint file decoder, keyboard design – sequence	18) CAD tools, Design ecoder, encoder, multi e, interfacing input (sv /display interface; des e generators, timing	plexer, demu witch) and c signing mem	ultiplexer; Int output (LED) ory elements	erfacing exter devices, BC s and arrays;	nal devices D to sever sequential	- setting -segment machine					

	machine); A simple CPU design, constructing a basic embedded system – interfacing on-chip CPU, memory and I/O ports.
	Module-VIII: $(P - 10)$
	Design analysis: Static timing analysis, Power analysis, Resource utilization, noise, clock network,
	DRC, debugging methods.
	Total Contact Hours: (L=42, P=28) = 70
Text Books,	Text Books:
and/or	1. S. Brown and Z. Vranesic, "Fundamentals of Digital Logic with Verilog Design," McGraw
Reference	Hill Education Special India Edition (SIE), 2017.
Materials	
	Reference Books:
	1. J. Bhasker, "A Verilog HDL Primer", B.S. Publications, Hyderabad in arrangement with Star
	Galaxy Publishing, USA, 1999.

	EC9032: FPGA based Design* (Elective) [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]							
				Progra	m Outcon	nes		
СО	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3	
CO 1	Learn logic synthesis techniques – two level and multilevel synthesis.	2	1	2	2	1	1	
CO 2	Be able to design systems using FPGAs and CPLDs.	3	1	3	3	3	1	
CO 3	Learn sequential machine design using FPGAs.	3	2	3	3	3	1	
CO 4	Learn to design systems for low power operation.	3	2	3	2	2	1	
	Average	2.75	1.5	2.75	2.5	2.25	1	

	Departi	ment of Electronics and C	Communica	tion Engine	ering			
Course	Title of the course	Program Core	Total Nu	Credit				
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours		
EC9033	Embedded Syster	ns PEL	3	1	0	4	4	
Introduction	es: ronics (ECC01), n to Computing (CSC0 uits and Systems	01) Course Assessment assessment (MA) a Assignments, Quiz Examination	nd end asses	ssment (EA)):	·		
(ECC503)	ssors and Microcontrol							
Course Outcomes	 CO 1: Und CO 2: Inte CO 3: Des 	empletion of the course the lerstand use of Microproce rface I/O devices with Mic ign software controlled har estigate application specific	ssor in Micr roprocessor rdware syste	ocontrollers in Microcon ms			ıter	
Topics Covered	Module I:	Intel 8051 Microcontro Architecture of Intel 805 oscillators, Digital I/O P limitations of Intel 8051	1 Microcont ins, Digital I	/O ports, 80			ıl	
	Module II:	Architecture of ATmega Hardware components o pins, PWM signals, PWI	Cmega Microcontrollers and Arduino [L-4;] chitecture of ATmega Microcontrollers using functional blocks, ardware components of Arduino boards, ADC, Analog input pins, Digital I/O ns, PWM signals, PWM pins, Serial communication pins, Arduino shields, mitations of ATmega Microcontrollers and Arduino.					
	Module III:	ARM processor, Hardwa pins in Raspberry Pi boa	Aspberry Pi Micro-Computer [L-4] RM processor, Hardware components of Raspberry Pi Micro-computer, GPIO ns in Raspberry Pi board, PWM signals, Raspberry Pi OS, In-built data communication devices, Limitations of Raspberry Pi Micro-Computer.					
	Module IV:	Sensors, Resistive sensor Motors, Signal condition storage devices, Compat	O devices for Micro controllers and Microcomputers [L-5; T-2] ensors, Resistive sensors, Capacitive sensors, Inductive sensors, Actuators fotors, Signal conditioning circuits, Amplifiers, Filters, Display elements, torage devices, Compatibility of several transducers with Intel 8051 dicrocontroller, ATmega Microcontrollers and Arduino, Raspberry Pi Mic computer mbedded System Programming using Keil [L- eil editor and compiler, Keil Programming for Intel 8051 Microcontroller, rogram uploading to 8051 Microcontroller, I/O programming, Interfacing nalog and Digital sensors and actuators with Intel 8051 Microcontroller, Ir ogramming in 8051, Keypad and Display element interfacing with 8051.					
	Module V:	Keil editor and compiler, Program uploading to 80. Analog and Digital senso						
	Module VI:	Embedded System Prog Arduino editor and comp Program uploading to Ar Analog and Digital senso Data transmission in Ard Display element interfaci	iler, Arduino duino board ors and actua uino, Interru	o Programmi , I/O program tors with Are pt programm	ng, nming, Interfa duino, Serial c	cing communica	tion and	

P a g e 84 | 105

	Module VII:	Embedded System Programming using Python[L-7; T-3]Raspberry Pi OS, Python programming, Interfacing Analog and Digital sensorsand actuators with Raspberry Pi, I/O programming in Raspberry Pi, Serialcommunication and Data transmission in Raspberry Pi, Interrupt programming,Keypad and Display element interfacing with Raspberry Pi.
	Module VIII:	Case studies [L-4; T-3] Application specific embedded system design using 8051 Microcontroller, Arduino, Raspberry Pi, Password lock device using Embedded system, Smart home using embedded system, Motor controller using Embedded system
		Total Lecture Hours: (L=42, T=14)= 56
Text Books, and/or reference material	 Wiley; Stud 8. E. A. Lee, S <i>Approach</i>, 9. M. A. Mazi 	, F. Vahid, Embedded System Design: A Unified Hardware / Software Introduction, dent edition, 2006 S. A. Seshia, Introduction to Embedded Systems - a Cyber Physical Systems PHI Learning Pvt Ltd, MIT Press; Second edition, 2019 idi, The 8051 Microcontroller and Embedded Systems: Using Assembly and C, ucation India; 2nd edition, 2007
	 T. W. Schu Prentice Ha S. Monk, P 2nd edition J. Yiu, <i>The</i> edition, 201 S. Monk, R Shroff/O'Re D. Molloy, 	Principles of measurement systems. Pearson Education India; 3rd edition, 2002 htz, C and the 8051, Vol.1: Hardware, Modular Programming & Multitasking, all; 2nd edition, 1997 Programming Arduino: Getting Started with Sketches, Second Edition, McGraw-Hill, , 2016 Definitive Guide to ARM® Cortex®-M3 and Cortex®-M4 Processors, Newnes; 3rd aspberry Pi Cookbook: Software and Hardware Problems and Solutions, eilly; Second edition, 2016 Exploring Raspberry Pi: Interfacing to the Real World with Embedded Linux, edition, 2016

EC9033: Embedded Systems [Mapping between course outcomes (COs) and program outcomes (POs)]

		Program Outcomes							
CO	Statement		PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Understand use of Microprocessor in Microcontrollers and Microcomputer	2	3	3	2	1	2		
CO 2	Interface I/O devices with Microprocessor in Microcontrollers and Microcomputer	3	3	3	2	1	3		
CO 3	Design software controlled hardware systems	3	3	3	2	1	3		
CO 4	Investigate application specific embedded systems	2	2	2	2	1	2		
Average			2.75	2.75	2	1	2.5		

P a g e 85 | 105

	Departme	nt of Electronics and	Communica	ation Engine	ering						
Course		Program Core		Total conta	ct hours: 56						
Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit				
EC9034	MEMS & Microsystems	PEL	3	1	0	4	4				
Pre-requisi	Technology	Course Assessment	mathada; (C	ontinuous A	accompant (CA) Mid sor	aastar				
	Elle EC9086ctronics	assessment (MA) ar			ssessment (CP	(), Miu-sei	liester				
(ECC01),	Engineering Mechanics (XEC01)	Assignments, Quiz/ Examination			Examination a	nd End Ser	nester				
Course Outcomes	 After the completion of the course the student will be able to CO 1: Understand characteristics of MEMS system CO 2: Understand fundamental building blocks of general MEMS systems CO 3: Apply qualitative and quantitative analysis techniques in general MEMS systems CO 4: Understand fabrication technology of MEMS system CO 5: Investigate application specific MEMS systems 										
Topics Covered		uction to MEMS & N y of MEMS technology s					MS				
	Electr	Module II: Electromechanical transduction techniques [L-5; T-2] Electrostatic transduction, Electromagnetic transduction, Piezoelectric transduction, Piezoresistive transduction									
	Stati Dyna	racteristics of MEMS c characteristics, linear amic characteristics, Re acteristics of MEMS de	ity, nonlinea esponse time		ity, Resolution						
	Conc	ysis and Modelling of ept of Energy, Co-ene el, Lumped model, Fin	rgy, Energy	methods, Lag		• 6; T-2] ns, Physics	based				
	Source	Module V: Effect of noise [L-2; T-1] Sources of different types of noise, Thermal noise, Environmental noise, Noise modelling techniques, Statistical methods of noise modelling									
	Trans	Module VI: Integration and packaging [L-6; T-3] Transducers in MEMS, MEMS sensors, MEMS actuators, Integration of MEMS transducers with signal conditioning /driver circuits, Signal amplifiers, Signal filters									
	MEM	Module VII: MEMS device fabrication processes [L-10; T-2] MEMS materials, Bulk micromachining, Silicon anisotropic etching, Surface micromachining,									
	Effec	aling effect, Reliability of inertia in MEMS of bility, Mathematical modes.	devices, Scal	ing effect of	MEMS device						
		studies in MEMS				L-4; T-1]					

	Application specific MEMS devices, MEMS blood pressure sensors, MEMS microphone, MEMS accelerometer, MEMS gyro
	Total Lecture Hours: (L=42, T=14)= 56
Text Books, and/or reference material	 Text Books: 1. S. D. Senturia, <i>Microsystem Design</i>, Springer; 1st edition, 2004 2. K.J. Vinoy, S. Gopalakrishnan, K.N. Bhat, V.K. Aatre, G.K. Ananthasuresh, <i>Micro and Smart Systems</i>, Wiley India Pvt Ltd, 2010
	Reference books: 1. Research Articles

EC9034: MEMS & Microsystems Technology (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

			Program Outcomes						
CO	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Understand characteristics of MEMS system	2	3	2	3	1	1		
CO 2	Understand fundamental building blocks of general MEMS systems	3	3	2	3	1	2		
CO 3	Apply qualitative and quantitative analysis techniques in general MEMS systems	3	3	3	3	1	1		
CO 4	Understand fabrication technology of MEMS system	2	3	2	3	1	2		
CO 5	Investigate application specific MEMS systems	3	3	2	3	1	2		
	Average			2.2	3	1	1.6		

	Departmen	t of Electronics an	d Communic	ation Engin	eering			
Course		Program Core		Total conta	ct hours: 56			
Course Code	Title of the course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit	
EC9035	Nanoelectronics	PEL	3	1	0	4	4	
Pre-requisit Microelectro Semiconduct [PHC331, E0 Course Outcomes	nics and tor Device Physics C1011] CO 1:Demor CO 2:Demor characterizati	quire a fundament	and end asse iz/class test, l g of fundamen ng of nanoted	ssment (EA) Mid-semeste ntal of nanoc chnology co): r Examination levices fabrica ncepts for de	and End S ation techni vice fabric	emester ques. ation and	
Topics Covered	CO 4:To acc various nanos Module I. Int	uire knowledge of	technology []	L -8; T - 2]				
	-dimensional ele conductor, Trans Coupled nanoscal Module III. Na Nanotechnology: Techniques, Nan- Surfaces; Instrum Scanning Tunneli	ptical properties of ctron gas (density smission probabilit le structures, and Su momaterials, depo Deposition techniq omaterials, Nanopa nentation for nanos ing Microscope and ectronic devices ba	of states), C y calculation perlattices. sition and ch ues for Nanos rticles, Nanos scale electron scanning nea	arrier scatte n, Electron aracterizati cale Devices wires, Nanon nics: The A r field optica	ring, the resi tunnelling, F on techniques s, Nanolithogr magnetic Mate tomic Force al microscope.	stance of Resonant t s [L – 11; ' aphy, Self- erials, Nan Microscop	a ballistic unnelling, Γ - 4] Assembly ostructure	
Text Books	Shrink-down app Devices, Downso Tunneling Device on carbon nanotu well and Quan	odule IV. Electronic devices based on nanostructures $[L - 13; T - 3]$ rink-down approaches: Electronic devices Based on Nanostructures: Advance Heterostruct vices, Downscaling of the MOSFET. Nanoscale FET Transistors, the Ballistic FET, Resonaneling Devices and Circuits, Single Electron Transistor and Related Devices. Devices bacarbon nanotubes, Spintronic Devices; Optoelectronic Devices using Nanostructures: Quantll and Quantum Dot LASERS, Quantum Cascade LASER, Quantum well-infratorotodetector, Superlattice LASER. Total Contact Hours: (L=42, T=14):						
and/or referent							lectronic	
	Press, 19 2. Y. Taur Press, 19	Press, 1988.						

		Program Outcomes							
СО	Statement	PO1	PO2	PO3	PSO 1	PSO 2	PSO 3		
CO 1	Demonstrate understanding of fundamental of nanodevices fabrication techniques	2	1	2	2	1	1		
CO 2	Demonstrate understanding of nanotechnology concepts for device fabrication and characterization.	3	1	3	3	3	1		
CO 3	To quire fundamental understanding for electronics and optical properties of nanomaterials.	3	2	3	3	3	1		
CO 4	To acquire knowledge of basic nanodevice principles and fabrication approaches for various nanoscale devices.	3	2	3	2	2	1		
	Average	2.75	1.5	2.75	2.5	2.25	1		

EC 9035: Nanoelectronics (Elective) [Mapping between course outcomes (COs) and program outcomes (POs)]

Page 89 | 105

		Department	of Electronic &	Communication	Engineering		
Course	Title of	Program Core (PCR) /	(Le	Total contac	ct hours: 70 tical/Sessional – 2	(8)	
Code	the course	Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9036*	ASIC Design using Verilog*	PEL	3	0	2	5	4
Pre-requis		tems [ECC402]	assessment (N	(A) and end asses	Continuous Assess sment (EA)): Iid-semester Exan		
			Examination	Quiz/eiass test, iv	nd-semester Exam		nu semester
Course Outcome s	 CO 1: 1 CO 2: 4 CO 3: 1 CO 4: 4 CO 5: 0 	Employ Verilog t Write test benche Compare betwee	sign flow using gn combination to model a digita es to verify the o n blocking and	HDL. al and sequentia al system. lesign. non-blocking sta	l digital systems. tement and their	uses.	
		•		to synthesizable	e design. : Total Contact H		
Topics Covered	Module I. Overview o design flow Module-II. Top-down a a simulation Module-III Lexical con Introduction Module-IV Module defi Module-V. Modeling us off delays, r	Brief introdu f Digital Design v , Verilog HDL, T Hierarchical and bottom-up des h, design block, st Basic Conce wentions, data ty n synthesis of differ Modules an inition, port decla Gate-Level sing basic Verilog min, max, and typ Dataflow N	action to VLSI of vith Verilog HDI rends in HDLs. Modelling Con- sign methodolog imulus block. pts [L - 3] pes, system tasl erent Verilog con- d Ports [L - 3] ration, connection Modelling [L - gate primitives, ical delays. Iodelling [L - 3	using CAD tools L: Evolution of C. acepts [L – 3] y, differences bet cs, compiler direct nstructs. ag ports, hierarchic 2, P-2] description of and , P-2]		HDLs, typica I module instan nodelling Log ng. pe gates, rise,	nces, parts of ic Synthesis:
	 Module-VII. Behavioural Modelling [L – 3, P-2] Structured procedures, initial and always, blocking and nonblocking statements, delay control, generate statement, event control, conditional statements, multiway branching, loops, sequential and parallel blocks. Module-VIII. Tasks and Functions [L – 4] Differences between tasks and functions, declaration, invocation, automatic tasks and functions. 						
Dage Q0	Module-IX. Useful Modelling Techniques [L – 4. P-2] Procedural continuous assignments, overriding parameters, conditional compilation and execution, useful system tasks.						

P a g e 90 | 105

	Module-X. Flip-Flop and Counter Design: [L – 4, P-6]
	Synchronous and asynchronous flip flop design with set and reset, design of basic counters.
	Module-XI.FSM & Processor Design: [L – 6, P-10]FSM modelling, Data path and Controller design, Modelling Memory, Pipelining, Design of a Processor.Introduction to Reconfigurable computing, FPGAs, the Altera /Xilinx flow.
	Module-XII. Essential SystemVerilog for UVM: [L – 4, P-4] Overview of basic System Verilog, UVM verification environment: introduction to UVM methodology and universal Verification Components (UVC) structure, stimulus modelling, creating a simple environment, DUT, TLM, functional coverage modelling, register modelling in UVM.
	Total Contact Hours: (L=42, P/S=28) = 70
Text	Text Books:
Books,	
and/or	1. Samir Palnitkar, Verilog HDL, , Second Edition, Pearson Education, 2004
reference material	2. J. Bhaskar, Verilog HDL Synthesis, BS publications, 2001.
material	References:
	1. S. Brown and Z. Vranesic, Fundamentals of Digital Logic with Verilog Design, McGraw Hill 3rd Ed. 2013.
	2. G. De Micheli. Synthesis and optimization of digital circuits, McGraw Hill, India Edition, 2003
	3. Indranil Sengupta, IIT Kharagpur, NPTEL Course (2017)
	https://www.youtube.com/watch?v=NCrlyaXMAn8&list=PLRsFfXmDi9IYCNlvNjrsD8bLMmNE0Ux
	BH

EC9036: ASIC Design using Verilog/VHDL* (Elective) [Mapping between course outcomes (COs) and program outcomes (POs)]

СО	Statement	Program Outcomes							
co	Statement	PO 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Explain VLSI design flow using HDL.	1	1	3	2	2	1		
CO 2	Analyze and design combinational and sequential digital systems.	2	1	3	2	2	2		
CO 3	Employ Verilog to model a digital system.	3	2	3	3	3	1		
CO 4	Write test benches to verify the design.	3	2	3	3	3	1		
CO 5	Compare between blocking and non- blocking statement and their uses.	2	1	3	3	2	2		
CO 6	Create a System from simulation to synthesizable design	3	1	3	3	3	1		
	Average		1.33	3	2.66	2.5	1.33		

	Departm	ent of Electronics a	nd Communica	tion Enginee	ering		
Course	Title of the	Program Core	Total	Number of co	ontact hours: 5	56	
Code	course	(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9037 Circ	v Power cuits and tems	PEL	3	1	0	4	4
Pre-requisites:			nent methods: (C assessment (MA				mester
EC1013: Digital IC	Design.	Assignments, Q	uiz/class test, M I	id-semester l Examination	Examination a	nd End Sei	mester
Course Objectives		course deals with issu amentals of power di Students will be it.	issipation,				
Course Outcomes	CO#2: Under typic CO#3: Apply CO#4: Learn	n to design and optin rstand sources of po- al circuits different techniques to the different source the device level as we	ower dissipation to minimize dyn s of leakage in N	and be able namic dissipa MOS transist	to estimate er tion.	nergy dissi	pation in
Syllabus/Topics CoveredTotal Contact hours: Lecture –Module-I: $(L - 05: T - 02)$ Introduction: Need for Low powe CMOS inverter and other gates; w Circuit optimization for performa Module – II: $(L - 06; T - 02)$ CMOS layout and Fabrication: T process flow, Imperfections in fab details – parasitic elements and th Module – III: $(L - 06; T - 02)$ Power dissipation mechanisms i power dissipation – switching I Concept of signal activity, signal difference, estimation of probabilModule – IV: $(L - 08, T - 03)$ Dynamic dissipation managem Scaling; Single-level Voltage for approaches, circuit level – Tra architectures, Algorithm level tran path and its management; Multi converters, Power up/down seq Frequency Scaling (DVFS), DVFModule-V: $(L - 06: T - 02)$			VLSI chips, MC by CMOS for Loc ce. pical CMOS cir ication steps, De ir estimation, im CMOS circuits ss, short circuit robability and ac y and activity in ent –Supply vo caling (SVS), a formations; Stat evel Voltage Sc encing; Dynami	S Transistor w Power? CN cuit layout, I ssign rules an portance of d : Static and dissipation, tivity, Signal complex logi Stage scalin Speed vs d Architecture ic Voltage Sc aling (MVS) ic Voltage S	structure and AOS Logic dea C fabrication d their import levice scaling. Dynamic diss concept of s activity comp ic circuits; g approache issipation, Sp level – Para caling Design I), MVS issues Scaling; Dyna	device mod sign metho overview, ance; MOS sipation, D witching a putation – I set Static beed mana allel and p Procedure, s – Layout mic Volta	dology, CMOS device ynamic activity; Boolean Voltage gement pipeline Critical t, Level ge and s: What

P a g e 92 | 105

	Optimization, Clock gating, State Encoding of FSM's.
	Module-VI: $(L - 06: T - 02)$ MOS Transistor revisited: Review of quantum theory of solids, concept of quantum mechanical tunneling, Leakage mechanisms in MOS transistor – diode leakage, sub-threshold current, sub-threshold swing; short channel effects – Gate tunneling, reducing gate tunneling – high-k technology, DIBL and GIDL effects; Recent advances in MOS transistor design – SOI technology, FinFET, Gate All Around (GAA) FET.
	Module-VII: $(L - 03; L - 01)$ Static Power Optimization Techniques: Comparison of static and dynamic loss in modern chips; Stand-by and Run-time leakage; Stand-by leakage reduction techniques, Transistor stacking, VT CMOS approach, Power gating, MT CMOS technology, Power gating issues, DVFS with Power gating; Run-time leakage reduction, Dynamic V _{DD} scaling, Dual V _t approach, V _t hopping.
	Module-VIII: $(L - 02)$ Battery operated system design: Battery construction and working principle, Battery capacity and energy density, comparison of different storage cell technologies; Battery charging and discharging profiles and their effects on battery capacity and life; Design of multi-battery system installations. Total Contact Hours: $(L=42, T=14) = 56$
	Text Books:
	 Ajit Pal, Low Power VLSI Circuits and Systems, Springer, 2015. Kaushik Roy and Sharat C Prasad, Low Power CMOS VLSI circuit Design, John Wiley and Sons, 2000. References:
Text / Ref. Books	 Anantha P Chandrakasan and Robert W Brodersen, <i>Low Power Digital CMOS Design</i>, Kluwer Academic Publishers, Holland, 1995. Gary B Yeap K, <i>Practical Low Power Digital VLSI Design</i>, Kluwer Academic Publishers, 1998. Kuo J B and Lou J H, <i>Low Voltage CMOS VLSI Circuits</i>, John Wiley and Sons, Singapore, 1999.

EC9037: Low Power Circuits and Systems (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

				Program Outcomes							
CO	Statement		PO 2	PO 3	PSO 1	PSO 2	PSO 3				
CO 1	Acquire knowledge of the fundamentals and applications of Low-power circuits	2	1	2	2	1	1				
CO 2 Identify various leakage/ switching power sources in a MOSFET and a digital circuits.		3	1	3	3	3	1				
CO 3	CO 3 Analyze the various issues to power dissipation and techniques to minimize/optimize		2	3	3	3	1				
CO 4	Learn various leakage/ switching power reduction mechanisms at device level and circuit level.	3	2	3	2	2	1				
CO 5	CO 5 Design and implementation of a power-aware circuits and systems		1	2	3	3	2				
CO 6	Evaluate the performance of low power circuits and systems	2	1	2	3	3	2				
	Average	2.50	1.33	2.50	2.67	2.50	1.33				

Page 93 | 105

		Department of E	lectronics and C	communicat	ion Enginee	ring		
			Program		Total conta	ct hours: 56		
Course Code	Course Code Title o		Core (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit
EC9038	Testing Verifica Circuit	ation of VLSI	PEL	3	1	0	4	4
Pre-requisites Digital Circuits		ems (ECC402)	Course Assess (EA))		× ·			
		<u>, </u>	Assignments, Semester Exam		Гest, Mid-ser	nester Examir	nation and	End
Course Objecti	ves	To expose the design.	students, the basi		and verifica	tion technique	es for the c	ligital IC
Course Outcomes After the comp CO1: Exten CO2: Gener CO2: Gener CO3: Demo CO3: Demo CO4: Discu CO4: Discu CO5: Use m Syllabus/Topics Module XVII. Covered Module XVIII. Boolean differen pattern generation Module XIX.P Module XIX.P			letion of the cour d knowledge of the ate test vectors to nstrate the concepts about Built-in-3 addern tools for te Introduction [I ad their modeling, lel, deductive and Test generation ce, D-algorithm, 1 n; aliasing and its LA testing [L – 4 t model, test generation	test a circui of of Memory Self Test and sting and ve -4; T - 1] Fault equive concurrent n for combi Podem, rand s effect on fa	nt of fault me t efficiently c y testing tech l its applicati rification. alence and do techniques; c national circ om etc. Exha ult coverage.	odeling in VL covering maxi niques. on in modern ominance; fau critical path tra cuits [L – 4; T ustive, randor	mum fault digital des lt collapsir acing.	s. ign. ıg, Fault
		Permanent, inter Module XXI.D	 K. Memory testing [L – 4; T - 1] intermittent and pattern-sensitive faults; test generation. KI.Delay faults and hazards [L – 6; T - 2] in generation techniques, ATPG and its different types. 					
Module XXII. Ad-hoc and stru Module XXIII LBIST and MB level (data path			Test pattern ge ctures techniques	neration fo	r sequential	circuits [L – (6; T - 2]	
			EXXIII. Built-in Self-Test techniques $[L - 8; T - 4]$ and MBIST. Verification: logic level (combinational and sequential circuits), RTL- ata path and control path). Verification of embedded systems. Use of formal les: decision diagrams, logic-based approaches.					
			 ASIC/IP Verification [L – 6; T - 2] dom testing, Error detection and correction codes. 					
					Total Co	ntact Hours:	(L=42, T	=14) =56
Text / Ref. Boo	oks		Shnell and V. D. $A^{2^{nd}}$ edition, 2004.		omputer arch	itecture and o	rganizatio	n",

P a g e 94 | 105

Refere	ence books:
[1]	A. Krstic and K-T Cheng, "Delay Fault Testing for VLSI Circuits", Kluwer
	Academic Publishers, 3rd edition, 2003.
[2]	N. K. Jha and S. Gupta, "Testing of Digital Systems", Cambridge University Press,
	2nd Edition, 2003.
[3]	M. Abramovici, M. A. Breuer and A. D. Friedman, "Digital Systems Testing and
	Testable Design", Wiley-IEEE Press, 3rd Edition, 1994.
[4]	P. K. Lala, "Fault Tolerant and Fault Testable", Prentice-Hall, 4th Edition, 1986.

EC9038: Testing and Verification of VLSI Circuits (Elective) [Mapping between course outcomes (Cos) and program outcomes (POs)]

CO	CO Statement –			Program Outcomes			
			PO 2	PO 3	PSO 1	PSO 2	PSO 3
CO 1	Extend knowledge of the requirement of fault modeling in VLSI circuits.	1	1	1	2	1	1
CO 2	Generate test vectors to test a circuit efficiently covering maximum faults.		2	3	2	1	1
CO 3	Introduce students to the concepts Memory testing techniques.	2	2	2	3	2	1
CO 4	Understanding Built-in-Self Test and its application in modern digital design	2	2	3	2	2	1
CO 5 Use modern tools for testing and verification.		2	2	3	3	2	2
	Average			2.4	2.4	1.6	1.2

				ication Eng					
Course		Program Core			ct hours : 56		~		
Code	Title of the course	e (PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit		
EC9039	Advanced Computer	PEL	3	1	0	4	4		
Digital Ci	Computer Architecture sites/Co-requisites: rouits & Systems [ECC suits & Systems Labora After successfu • CO 1: • CO 2: • CO 3: • CO 4: • CO 6: Module I. History of comp their benefits of II, instruction set Module II. Fundamental corprinciples and tr level trade-off, p Module III. Module III. Binary arithmetic point arithmetic. Module IV. Pipelining: issue exceptions, state Module V. SI SIMD processing Access Execute of memory, memoriorganization and memory processing	2402] atory [ECS452] al completion of the con- Acquire idea about of Understand the fund Illustrate the operati Analyze control and Design and implement Evaluate the perform Introduction and B uters, introduction to comfortably crossing t architecture III, arch Fundamental Concep ncepts in computer a ade-off, elements of a roperty of ISA vs. mice rithmetic Operations c, ALU Design, multip rocessor Design [L – croarchitecture, multi- es in pipelining, data maintenance, state re IMD, GPUs, VLEW g: array and vector pr (DAE), Systolic Array Memory Hierarchy hy, physical memory vy controller, memory l operation, high perforing	Course As (CA), Mid (EA)): Assignme and End S ourse, the stu computer arc lamental com- ons of memo data flow of entation of m mance of a co- basics [L – 4 computer ar them, instru- itecture exant ts and ISA [urchitecture: an ISA, RISC croarchitecture: an ISA, RISC croarchitecture: s [L – 5; T – plier design, of 8; T - 2] -cycle micro and control covery; Out- and DAE [I rocessors, SI y, and Cache y and virtual y manageme ormance cach	ssessment m l-semester as ints, Quiz/cla emester Exa ident will be hitecture and cepts of ISA ory unit. F a computer ultiprocesso omputer syste ; T - 1] chitecture, le totion set arc nples, examp L - 6; T - 2 Von Neuma C vs. CISC, tre. 3] divider desig architecture, dependence of-Order exe L - 5; T - 1] MD operation s [L - 7; T - 1]	ethods: (Con seessment (M ass test, Mid- mination able to: d organization	tinuous Asses A) and end a semester Exa n. formation, ab nstruction set nd data flow ISA vs. micro on, multiplica ammed micro oranch predic ssues in OoO ISAs, VLIW mory techno rance: prefeto	ssment ssessment mination stract layer architectur leas. model, IS. oarchitectur tion, floatin parchitectur tion, floatin parchitectur tion, precis execution.		
		Module VII. Multiprocessor $[L - 7; T - 3]$ Multiprocessor types, multiprocessing and issues in multiprocessor, limits of parallel speedup difficulty in parallel programming, heterogeneous systems, input/output subsystem, interfaces, I/0 operations, interconnection networks: bus based and NoC based architectures.							

P a g e 96 | 105

	Total Contact Hours: (L=42, T=14)=56
Text Books, and/or reference	Text Books: 1. Patterson and Hennessy, "Computer Organization and Design: The Hardware/Software Interface", 4th Edition, Morgan Kaufmann/ Elsevier, 2009.
material	Reference Books: 1. Andrew Tanenbaum, "Structured Computer Organization"6th Edition, Pearson, 2016.
	 Andrew Fahrenbaum, "Structured Computer Organization our Edition, Fearson, 2010. Patt and Patel, "Introduction to Computing Systems: From Bits and Gates to C and Beyond", Morgan Kaufman, Elsevier, 2th Edition, McGraw-Hill Education 2003.
	3. Harvey Cragon, "Computer Architecture and Implementation", Cambridge University Press, 2000.
	1. C. Hamacher, Z. Vranesic, S. Zaky, "Computer Organization", McGraw Hill Education; 5th Edition, 2011.

EC9039: Advanced Computer Architecture [Mapping between course outcomes (COs) and program outcomes (POs)]

СО	Statement	Program Outcomes						
co	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3	
CO1	Acquire idea about computer architecture and organization.	1	1	2	2	3	2	
CO2	Understand the fundamental concepts of ISA	1	1	2	2	3	1	
CO3	Illustrate the operations of memory unit	1	1	2	3	3	3	
CO4	Analyze control and data flow of a computer	2	1	2	3	3	1	
CO5	Design and implementation of multiprocessors.	1	1	2	3	3	2	
CO6 Evaluate the performance of a computer system.		1	1	2	3	3	1	
	Average	1.17	1.17	1	2	2.67	3	

		Program		Total conta	ct hours: 56				
Course Code	Title of the course	Core (PCR) / Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credi		
EC9040	DSP Architectures in VLSI	PEL	3	1	0	4	4		
Signals & S	es/Co-requisites: ystems, DSP, Digit SCC603, ECC404]	al Design	Mid-term as	sessment (MA)	s: (Continuous 2 and End term a ent(s), Quiz(zes	issessment (H	EA)):		
Course Objectives	processing. The algorithms frequ	esigned to give a central theme of t tently encountered ign techniques to	the course is to 1 in DSP system	design efficien ns. It focuses o	t VLSI architec n algorithm tran	tures for con sformation a	puting nd		
Course Outcomes	 State VLSI d Describe VLSI Implement/Si Analyze DSF 	 Describe VLSI algorithms and architectures for DSP. Implement/Simulate basic architectures for DSP using Matlab/CAD tools. Analyze DSP architectures and evaluate their performance. Discuss various issues that need to be addressed when implementing DSP algorithms in real 							
Covered	 Module I. Introduction to Digital Signal Processing [L – 4; T - 2] Review of DSP fundamentals: Discrete Systems: Representation of Systems, Properties of DSP systems: Difference equation and its relationship with system function, Impulse response and frequency response Module II. Digital Signal Processing Algorithms [L – 4; T - 2] Introduction for DSP algorithms: VLSI Design flow, Mapping algorithms into Architectures: Graphica representation of DSP algorithms – signal flow graph (SFG), data flow graph (DFG), critical path dependence graph (DG). Data path synthesis, control structures, Optimization at Logic Level and architectural Design, Loop bound and iteration bound, Algorithms for computing iteration bound Iteration bound of Multirate data-flow graphs. – Retiming. 								
	Module III. Introduction to DSP systems $[L - 2; T - 1]$ DSP Systems, Parallel and pipeline of signal processing application: Architecture for real-time systems, latency and throughput related issues, clocking strategy, power-aware structures, array architectures; Pipelining processing of Digital filter, Parallel processing, Parallel and pipelining for Low power design, Optimization with reference to speed, area and power, asynchronous and low power system design, ASIC (application-specific integrated circuits) and ASISP (application-specific instruction-set processors) design.								
	Module IV.Systolic Array Architecture [L – 3; T - 2]Methodology of systolic array architecture, FIR based Systolic Array, Selection of Scheduling Vector, Matrix multiplication of systolic array.								
	Module V.Signal processing Architectures [L – 7; T - 2]Convolution technique, Retiming concept, Folding/Unfolding Transformation, Fast convolution, Cook- Toom algorithm, modified Cook-Toom algorithm. CORDIC architecture.								
	_		U						

P a g e 98 | 105

	Scaling and round-off noise, scaling operation, round-off noise, state variable description of digital filters, scaling and round-off noise computation, round-off noise in pipelined IIR filters.
	Module VII. Low Power Design $[L - 5; T - 2]$
	Theoretical background, Scaling v/s power consumption, power analysis, Power estimation approach, Power reduction techniques.
	Total Contact Hours: (L=42, T=14)= 56
Text	Text Books:
Books, and/or Reference	1. Keshab K. Parhi, "VLSI Digital Signal Processing Systems, Design and Implementation", Wiley-Interscience, 1999.
materials	Reference Books:
	1. Uwe Meyer-Baese, "Digital Signal Processing with Field Programmable Gate Arrays", Springer, Third Edition, 2007.
	NPTEL/SWAYAM/Other Video Lectures: 1. Prof. N. Chandrachoodan, IITM, (2019) <u>Mapping Signal Processing Architectures in VLSI</u>

EC9040: DSP Architectures in VLSI [Mapping between course outcomes (COs) and program outcomes (POs)]

CO	Statement	Program Outcomes								
CO	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3			
CO1	State VLSI design methodology for signal processing systems.	2	1	2	3	1	1			
CO2	Describe VLSI algorithms and architectures for DSP.	2	3	1	3	2	2			
CO3	Implement/Simulate basic architectures for DSP using Matlab/CAD tools.	3	2	1	2	2	1			
CO4	Analyze DSP architectures and evaluate their performance.	3	1	1	3	2	1			
CO5	Discuss various issues that need to be addressed when implementing DSP algorithms in real hardware.	3	1	1	2	1	2			
	Average		1.50	1.50	2.67	1.50	1.33			

	Depart	ment of Electronics	& Commun	nication Eng	gineering				
G		Program Core	Total conta	ct hours : 56					
Course Code	Fitle of the course	(PCR) / Elective (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours	Credit		
Po EC9041 Ma De	3	1	0	4	4				
Pre-requisites/Co-requisites: Analog IC Design[EC1012, <u>EC722</u>], Signals & Systems[<u>EC503</u>]			Course Assessment Methods: Continuous Assessment (CA-15/100), Mid-Term (MT- 25/100) and End-Term assessment (ET-60/100)) Assignments, Quiz/class tests, Mid-term Exam and End- term						
CourseThe course is to develop understanding of why power management circuits are needed in a system. It primarily deals with different components of a power management system with for dc-dc converters. It aims to design a chip level dc-dc converter from the given specifications.							with focus on		
Course Outcomes	 CO1: Define CO2: Descri CO3: Emplo CO4: Design CO5: Compare 	 After the completion of the course the student will be able to: CO1: Define different types of DC-DC converters. CO2: Describe the concept of power management ICs. CO3: Employ Miller compensation to obtain better time response. CO4: Design a compensator for Buck converter. CO5: Compare between Buck and Boost Converter. CO6: Evaluate the performance of a Switched Capacitor DC-DC Converter. 							
Topics Covered	DC Converters, I Line and Load R Droop Compens Brokaw Bandgap Module II. L Bandgap Voltag regulator, pass tr current limiting, Module III. Sw Basic Concept o PWM Control 7 Techniques for	Power Management - Linear versus Switch egulation, Line and L sation; Current Rego o Circuit. inear Regulators [L e Reference, Low D ansistor, error amplifi power supply rejection vitching Regulator [f a Switching Regulator Fechniques, Losses DC-DC Converters;	ction [L – 4; T - 0] anagement -Voltage regulators, Need of DC-DC Converters, Types of DC- ersus Switching Regulator, Performance Parameters - Efficiency, Accuracy, b, Line and Load Transient, PSRR; Point-of-Load Regulator, Kelvin Sensing, Current Regulators and their Applications; Bandgap Voltage Reference,						

P a g e 100 | 105

	Introduction to the Buck-Boost Converter, Introduction to Switched-Capacitor DC-DC Converters, Applications of SC DC-DC Converters in Open-Loop, Output Regulation in SC DC-DC Converters using Feedback Control. Module VII. Advanced Topics [L – 6; T - 2] Digitally controlled dc-dc converters, digitally controlled LDOs, adaptive compensation, dynamic voltage scaling (DVS), Single-Inductor Multiple-Outputs (SIMO) Converters, dc-dc converters for LED lighting, Li-ion battery charging circuits.
	Total Lecture Hours: (L=42, T=14)=56
Text Books, and/or reference material	 Text Books: Switch-Mode Power Supplies: SPICE Simulations and Practical Designs by Christophe P. Basso, McGraw-Hill Professional, 2008. Design of Analog CMOS Integrated Circuits by Behzad Razavi, McGraw-Hill, 2017
	Reference books:
	 Power Management Techniques for Integrated Circuit Design By Ke-Horng Chen, Wiley- Blackwell, 2016.
	 Fundamentals of Power Electronics, 2nd edition by Robert W. Erickson, Dragan Maksimovic, Springer, 2001.

EC9041: Power Management IC Design [Mapping between Course Outcomes (COs) and Program Outcomes (POs)]

CO	Statement	Program Outcomes							
СО	Statement	PO1	PO2	PO3	PSO1	PSO2	PSO3		
CO1	Define different types of DC-DC converters	2	2	2	2	3	2		
CO2	Explain techniques of Stabilizing a Regulator.	2	1	2	2	3	1		
CO3	Employ Miller compensation to realize good phase margin	1	2	1	2	3	3		
CO4	Design a compensator for Buck converter.	2	1	2	3	3	1		
CO5	Compare between Buck and Boost Converter	1	1	2	3	3	2		
CO6	Evaluate the performance of a Switched Capacitor DC-DC Converter	1	2	3	3	3	1		
	Average	1.5	1.5	2	2.5	3	1.67		

	Department	of Electronics and C	Communicat	ion Engine	ering				
Course	Title of the course	Program Core	Total Nu	Credit					
Code		(PCR) / Electives (PEL)	Lecture (L)	Tutorial (T)	Practical (P)	Total Hours			
EC9042	Cyber Physical Electronic System Design	PEL	3	1	0	4	4		
Pre-requisites	s:	Course Assessmen				CA), Mid-s	emester		
Basic Electror	nics (ECC01)	assessment (MA) a Assignments, Quiz				and End S	emester		
	Aechanics (XEC01)	Examination		na semester	Examination		emester		
Course Outcomes	 CO 1: Understat CO 2: Understat CO 3: Apply qu CO 4: Learn fur 	 CO 2: Understand basic building blocks of electronic systems CO 3: Apply quantitative analysis techniques to electronic systems CO 4: Learn fundamentals of cyber-physical electronic systems 							
Topics CoveredModule I.Introduction to cyber physical electronic system[L-1]CoveredConcept of Cyber Physical Electronic Systems (CPES), Applications of CF									
	 Sensor Piezore conditi commu motors Module III. Physic Micro- sensin Closed Module IV. Physica Intranet Industri systems Module VI. Data S Requir Module VII. Case 	rement of data securit	Capacitive se IS sensors, M Processing tors, Motors near servo ac ns puters, Emb oltage sensin ded control a rk tooth, Zigber on Protocols, ndustrial IoT ies, Data end	nsors, Induct AEMS Acce unit, Data pr , BLDC, Ste tuators, Mec edded syster ng, Actuation strategies, E e, WiFi, 4G, HART, MQ	lerometers, M esentation, Da pper Motors, chanisms ns, Vibration n systems, Op mbedded PID [1 5G, Industria (TT, HTTP, C [1 tegies. [1	Piezoelectri IEMS Gyrc ata storage, Servo moto [L- sensing, Fo ben-loop sy controller. L-10; T-1] Il Ethernet, Cyber physi L-1] L-6; T-3]	o, Signal and Data ors, AC 10; T-5] orce stem,		
		physical structural he	•	ing systems	, Industry 4.0.				
Text Books,	Text Books:			Total L	ecture Hours	s: (L=42, 1	<u>(=14)= 56</u>		
and/or reference material	 J. Bentley, <i>Prince</i> E. A. Lee, S. A. <i>Approach</i>, MIT B. A. Forouzan, 2017 Reference books: 	ciples of measurement Seshia, Introduction Press; Second edition Data Communication	to Embedded n, 2019 1s and Netwo	l Systems - a orking, McG	e Cyber Physic raw Hill Educ	cal Systems			
Page 102	2. Research Articles	try 4.0 the industrial i	internet of th	ings, Apres	s; 1st edition,	2017			

P a g e 102 | 105

EC9042: Cyber Physical Electronic System Design [Mapping between course outcomes (Cos) and program outcomes (POs)]

		Program Outcomes							
СО	Statement	РО 1	PO 2	PO 3	PSO 1	PSO 2	PSO 3		
CO 1	Understand application based electronic systems	2	3	1	3	1	1		
CO 2	Understand basic building blocks of electronic systems	2	3	1	3	1	1		
CO 3	Apply quantitative analysis techniques to electronic systems	2	3	1	3	1	1		
CO 4	Understand fundamentals of cyber-physical electronic systems	3	2	2	1	1	3		
CO 5	Investigate complex designs of cyber physical embedded systems through case studies	3	2	3	1	1	3		
	Average	2.4	2.6	1.6	2.2	1	1.8		

		of Electronics and C					Credit	
Course	Title of the course	Program Core	Total Number of contact hours: 56					
Code		(PCR) / Electives (PEL)	Lecture	Tutorial	Practical	Total		
EC9043	Smart Materials	PEL	(L) 3	(T) 1	(P) 0	Hours 4	4	
	based Devices							
Pre-requisi	tes:	Course Assessmen assessment (MA) a				(CA), Mid-s	emester	
	onics (ECC01), Mechanics (XEC01)	Assignments, Quiz Examination	z/class test, N	Aid-semeste	r Examinatio	on and End S	emester	
Course Outcomes	 After the comple CO 1: Understa CO 2: Apply qu CO 3: Understa CO 4: Learn der 	etion of the course the nd concept of Smart I antitative analysis tec nd basic building bloo sign techniques of Sm te application specific	Materials bas chniques to S cks of Smart nart Material	sed Electron Smart Materi Materials based Elect	ials based El ased Electro ctronic syster	nic systems ns	ices	
Topics Covered	Smart M	ction to Smart Mate laterials, Smart Mater s based Electronic De	ials based E			[L-1] cations of Sn	nart	
	Static, d Devices Module III: Analy Energy,	eteristics of Smart M ynamic and quasi stat sis and Modelling of Co-energy, Energy m s and modelling of Sn	ic characteri Smart Mat aethods, Han	stics of Sma erials based nilton's princ	rt Materials I Electronic ciple, Lagrar	Devices [L- ige's Equatio	onic 12; T-5]	
		Module IV: Piezoelectric Devices Piezoelectric sensors, actuators, transformers, motors, resonators						
	Shape M	Module V: Shape Memory Alloy devices Shape Memory effect, Shape Memory Alloy elements, Shape Memory elements as actuators, Shape Memory Alloy element as sensor						
		Module VI: Electroactive polymer devices Electroactive polymers, Electroactive polymer actuators					T-1]	
	Concept Devices Module VIII: Case Piezoele	Module VIII: Case studies Piezoelectric transducers for ultrasound generation, SMA actuator drives						
	exoskele	eton		Total I	ecture Hou	rs: (L=42, T	'=14)= 5	
Text Books and/or reference material	 12. V. K.Varadan, F. Development M. 13. J. Bentley, Prince 14. S. H. Crandall, I. 2017 Reference books: 4. D. J. Leo, Engin 	K.J.Vinoy, S.Gopalaka ethodologies, Wiley, ciples of measuremen D. C. Karnopp, Dynar eeering Analysis of Sr echatronics, Dynamic	2006 t systems. Pe nics of Mecl nart Materia	art Material earson Educa nanical and I I Systems, Jo	Systems and ation India; 3 Electromech ohn Wiley &	<i>I MEMS: De</i> Brd edition, 2 <i>anical</i> , Medu z Sons Inc, 2	sign and 002 eech Pub 007	

6. D. K. Gehmlich, S. B. Hammond, <i>Electromechanical system</i> , McGraw-Hill, 1967
7. D. Hutton, Fundamentals of Finite Element Analysis, McGraw Hill, 2003
8. Research articles

EC9043: Smart Materials based Devices [Mapping between course outcomes (Cos) and program outcomes (POs)]

			Program Outcomes							
CO	Statement	РО 1	PO 2	РО 3	PSO 1	PSO 2	PSO 3			
CO 1	Understand concept of Smart Materials based Electronic Devices	3	3	3	1	1	1			
CO 2	Apply quantitative analysis techniques to Smart Materials based Electronic Devices	2	3	2	3	1	2			
CO 3	Understand basic building blocks of Smart Materials based Electronic systems	3	3	3	3	1	1			
CO 4	Learn design techniques of Smart Materials based Electronic systems	3	3	2	3	2	3			
CO 5	Investigate application specific Smart Materials based Electronic systems	2	3	2	2	1	2			
	Average	2.6	3	2.4	2.4	1.2	1.8			